

**PH300S280-\***

**EVALUATION DATA**

**型式データ**

DWG No. C113-53-01			
承認	承認	査閲	担当
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5/Sep/97	3/Sep/97	3/Sep/97	3/Sep/97

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## 使用記号 Terminology used

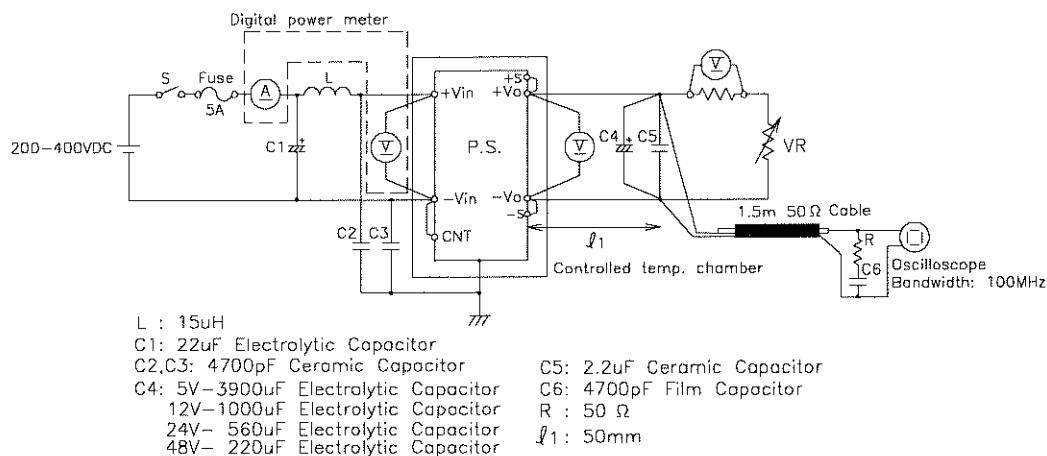
## 定義 Definition

Vin	.....	入力電圧	Input Voltage
Vout	.....	出力電圧	Output Voltage
Vcnt	.....	CNT電圧	CNT(ON/OFF Control) Voltage
Iin	.....	入力電流	Input Current
Iout	.....	出力電流	Output Current
Tp	.....	ベースプレート温度	Base-Plate Temperature

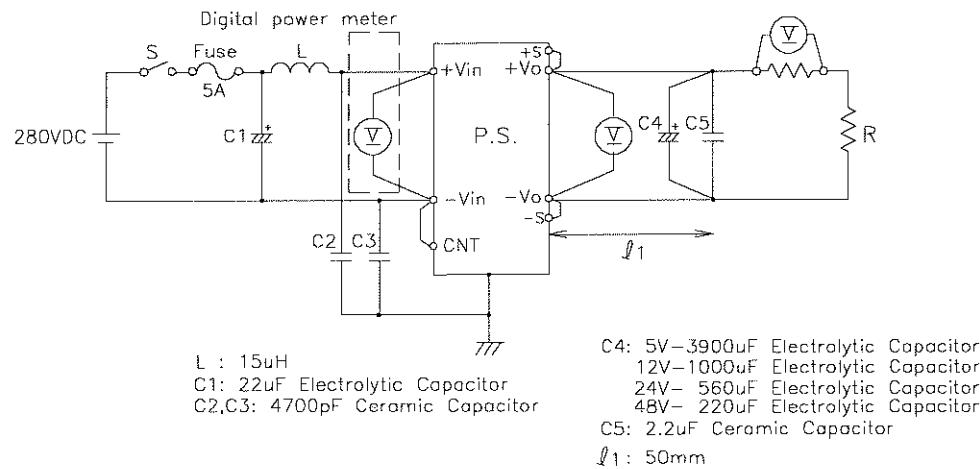
## 1. 1

**測定回路**  
**Circuit used for determination**

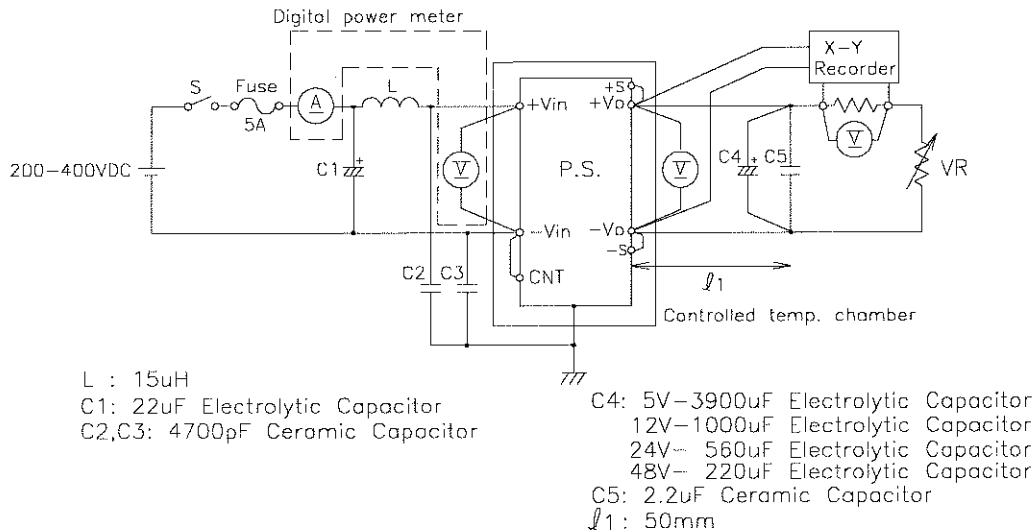
## (1) 静特性 Steady state data



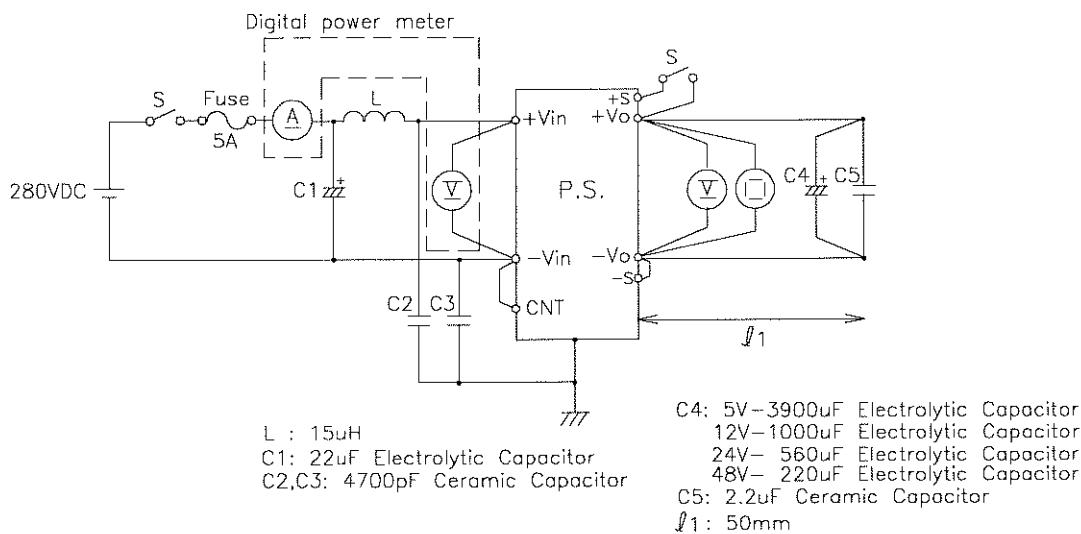
## (2) 通電ドリフト特性 Warm up voltage drift characteristics



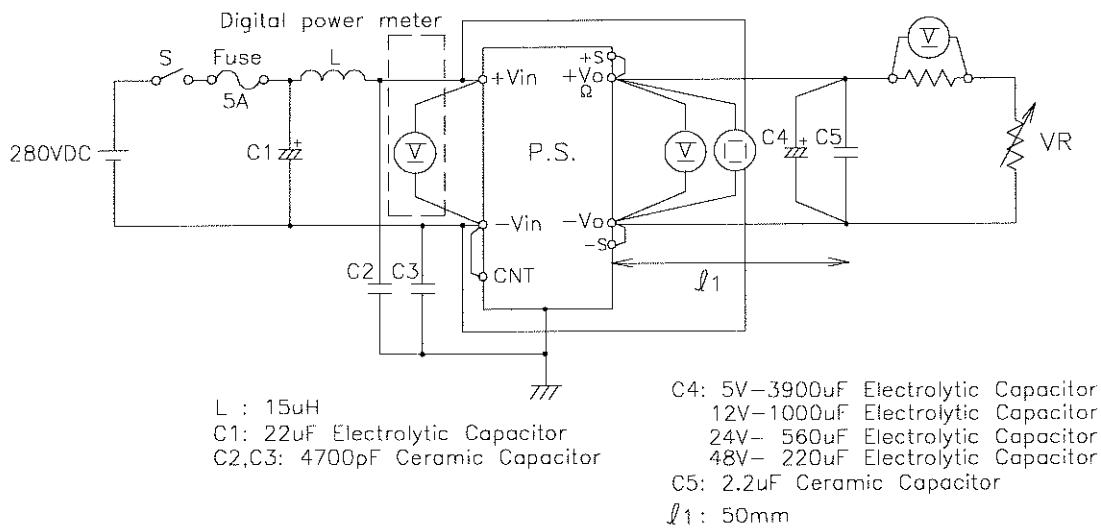
## (3) 過電流保護特性 Over current protection (O.C.P.) characteristics



## (4) 過電圧保護特性 Over voltage protection (O.V.P.) characteristics



## (5) 出力立ち上がり特性 Output rise characteristics



## (6) 出力立ち下がり特性 Output fall characteristics

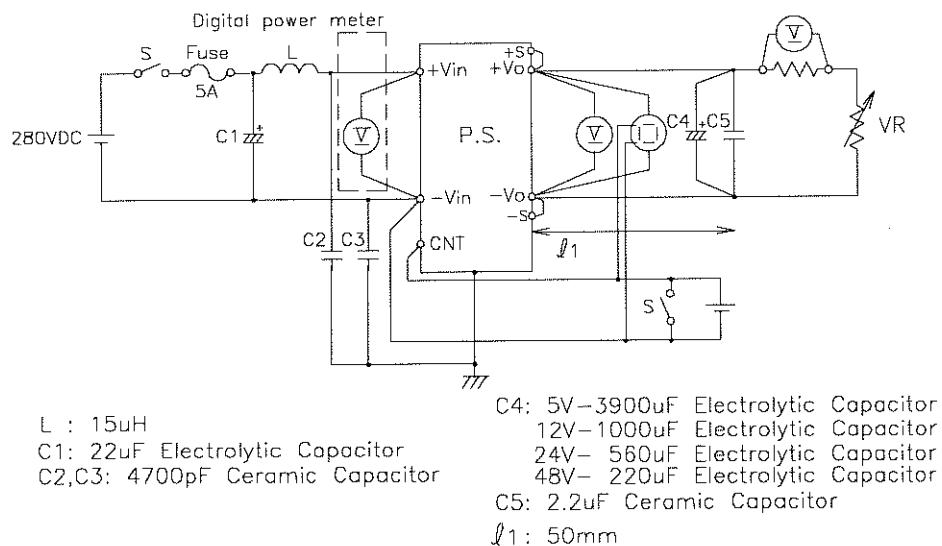
出力立ち上がり特性と同じ

Same as output rise characteristics

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## (7) 出力立ち上がり特性 (ON/OFF コントロール時)

Output rise characteristics with ON/OFF CONTROL



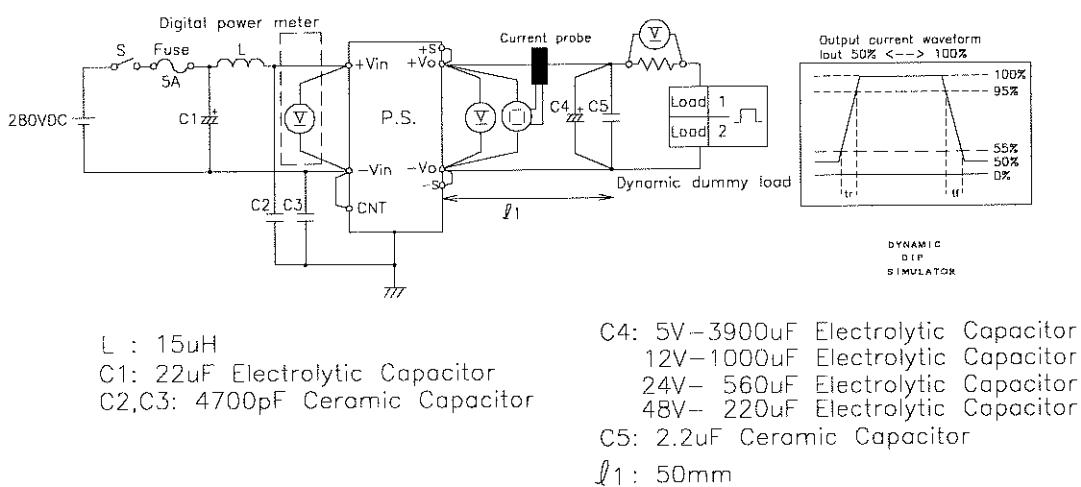
## (8) 出力立ち下がり特性 (ON/OFF コントロール時)

Output fall characteristics with ON/OFF CONTROL

出力立ち下がり特性 (ON/OFF コントロール時) と同じ

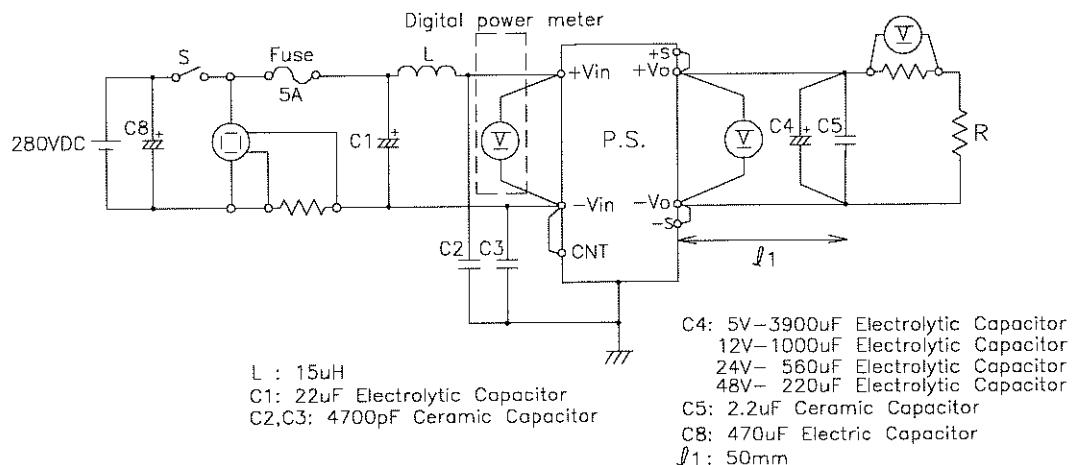
Same as output rise characteristics with ON/OFF CONTROL

## (9) 過渡応答 (負荷急変) 特性 Dynamic load response characteristics



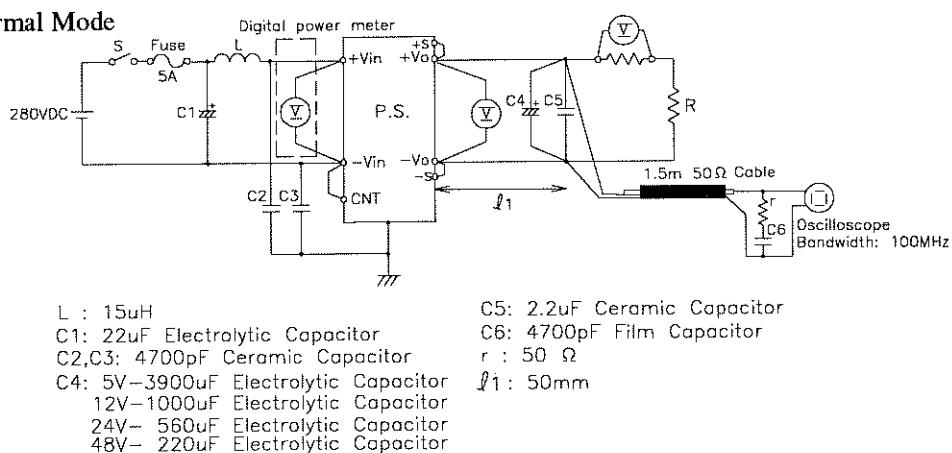
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## (10) 入力サージ電流（突入電流）特性 Inrush current characteristics

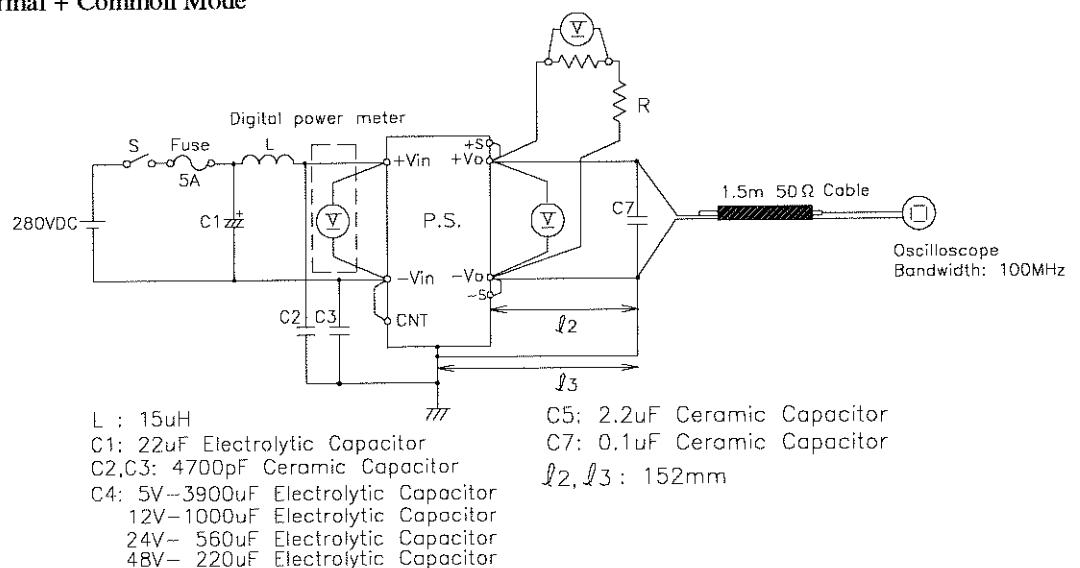


## (11) 出力リップル、ノイズ波形 Output ripple and noise waveform

## (a) Normal Mode



## (b) Normal + Common Mode

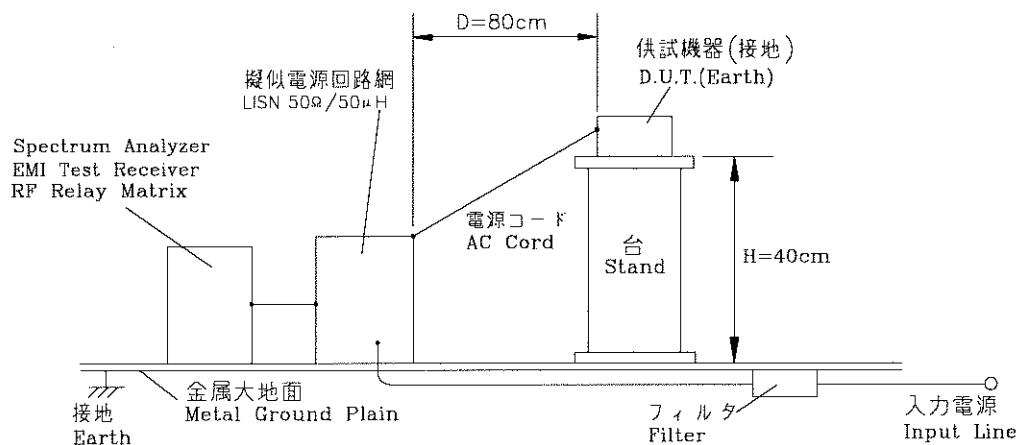


## (12) E M I 特性

Electro-Magnetic Interference characteristics

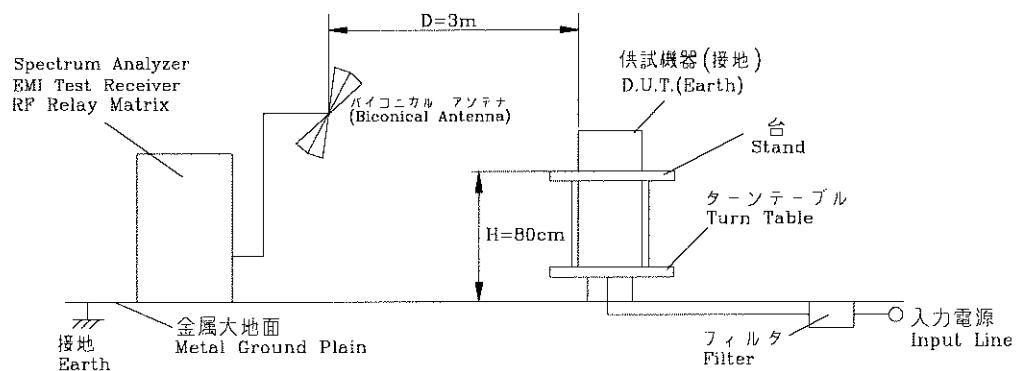
## (a) 雜音端子電圧 (帰還ノイズ)

Conducted Emission Noise



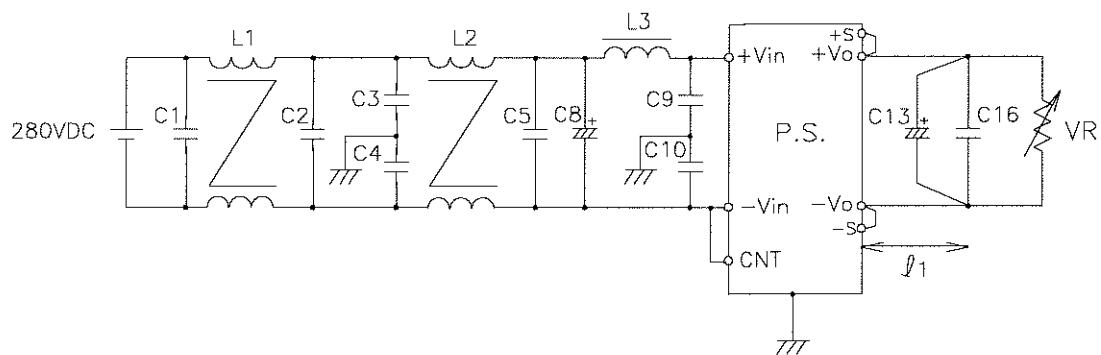
## (b) 雜音電界強度 (輻射ノイズ)

Radiated Emission Noise

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## (1) VCCI class A 対応アプリケーションシステム

VCCI class A application system



L1 : 1mH

L2 : 3mH

L3 : 15uH

C1,C2,C5 : 0.68uF Film Capacitor

C3,C4,C9,C10 : 4700pF Ceramic Capacitor

C8 : 22uF Electrolytic Capacitor

C13 : 5V-3900uF Electrolytic Capacitor

12V-1000uF Electrolytic Capacitor

24V- 560uF Electrolytic Capacitor

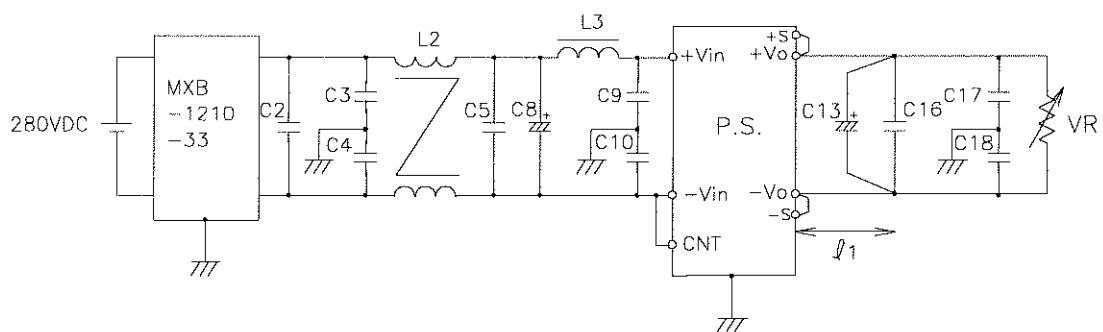
48V- 220uF Electrolytic Capacitor

C16 : 2.2uF Ceramic Capacitor

 $\ell_1$ : 50mm

## (2) VCCI class B 対応アプリケーションシステム

VCCI class B application system



L2 : 10mH

L3 : 15uH

C2,C5 : 1uF Film Capacitor

C3,C4,C9,C10 : 4700pF Ceramic Capacitor

C8 : 22uF Electrolytic Capacitor

C13 : 5V-3900uF Electrolytic Capacitor

12V-1000uF Electrolytic Capacitor

24V- 560uF Electrolytic Capacitor

48V- 220uF Electrolytic Capacitor

C16 : 2.2uF Ceramic Capacitor

C17 : 0.1uF Film Capacitor (For 24V only)

C18 : 0.1uF Film Capacitor (For 24V,48V only)

 $\ell_1$ : 50mm

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## 1.2 使用測定機器 List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	OSCILLO SCOPE	HITACHI DENSHI	V-1100A
2	DIGITAL STORAGE OSCILLOSCOPE	TEKTRONIX	TDS540B
3	DIGITAL MULTIMETER	ADVANTEST	R6341A
4	DIGITAL POWER METER	YOKOGAWA ELECT.	WT110
5	CURRENT PROBE/AMPLIFIER	TEKTRONIX	A6303/AM503
6	DYNAMIC DUMMY LOAD	TAKASAGO	FK-1000L
7	AC POWER SUPPLY	KIKUSUI	PCR4000L
8	X-Y RECORDER	GRAPHTEC	WX4309
9	CONTROLLED TEMP. CHANBER	TABAI ESPEC	SH-240
10	SPECTRUM ANALYZER	ROHDE & SCHWARZ	FSA
11	EMI TEST RECEIVER	ROHDE & SCHWARZ	ESHS10
12	EMI TEST RECEIVER	ROHDE & SCHWARZ	ESVS10
13	RF RELAY MATRIX	ROHDE & SCHWARZ	PSU
14	LISN	KYORITU DENSHI	KNW-242
15	ANTENNA(BICONICAL ANTENNA)	SCHWARZBECK	BBA9106

## 2. 特性データ

## 2.1 静特性 Steady state data

(1) 入力、負荷、温度変動 Regulation - line and load, temperature drift

5V

## 1. Regulation - line and load

condition Tp : 25°C

Iout \ Vin	200VDC	280VDC	400VDC	line regulation	
0%	5.007V	5.007V	5.007V	0mV	0.00%
50%	5.004V	5.004V	5.006V	2mV	0.04%
100%	5.004V	5.006V	5.007V	3mV	0.06%
load regulation	3mV	3mV	1mV		
	0.06%	0.06%	0.02%		

## 2. Temperature drift

conditions Vin : 280VDC

Iout : 100%

Tp	-20°C	25°C	100°C	temperature stability	
Vout	4.999V	5.006V	5.002V	7mV	0.14%

12V

## 1. Regulation - line and load

condition Tp : 25°C

Iout \ Vin	200VDC	280VDC	400VDC	line regulation	
0%	12.030V	12.030V	12.031V	1mV	0.008%
50%	12.022V	12.022V	12.022V	0mV	0.000%
100%	12.018V	12.020V	12.020V	2mV	0.017%
load regulation	12mV	10mV	11mV		
	0.100%	0.083%	0.092%		

## 2. Temperature drift

conditions Vin : 280VDC

Iout : 100%

Tp	-20°C	25°C	90°C	100°C	temperature stability	
Vout	12.008V	12.023V	12.011V	12.006V *1	17mV	0.142%

\*1) Iout : 83%



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## 2. 特性データ

## 2.1 静特性 Steady state data

(1) 入力、負荷、温度変動 Regulation - line and load, temperature drift

24V

## 1. Regulation - line and load

condition Tp : 25°C

Iout \ Vin	200VDC	280VDC	400VDC	line regulation	
0%	24.090V	24.093V	24.093V	3mV	0.013%
50%	24.066V	24.065V	24.066V	1mV	0.008%
100%	24.061V	24.062V	24.064V	3mV	0.013%
load regulation	29mV	31mV	29mV		
	0.121%	0.129%	0.121%		

## 2. Temperature drift

conditions Vin : 280VDC

Iout : 100%

Tp	-20°C	25°C	90°C	100°C	temperature stability	
Vout	24.104V	24.100V	24.031V	24.018V *2	86mV	0.358%

\*2) Iout : 83%

48V

## 1. Regulation - line and load

condition Tp : 25°C

Iout \ Vin	200VDC	280VDC	400VDC	line regulation	
0%	48.070V	48.080V	48.090V	20mV	0.042%
50%	48.050V	48.060V	48.060V	10mV	0.021%
100%	48.040V	48.050V	48.050V	10mV	0.021%
load regulation	30mV	30mV	40mV		
	0.063%	0.063%	0.083%		

## 2. Temperature drift

conditions Vin : 280VDC

Iout : 100%

Tp	-20°C	25°C	90°C	100°C	temperature stability	
Vout	47.92V	47.94V	47.89V	47.88V *3	60mV	0.125%

\*3) Iout : 83%

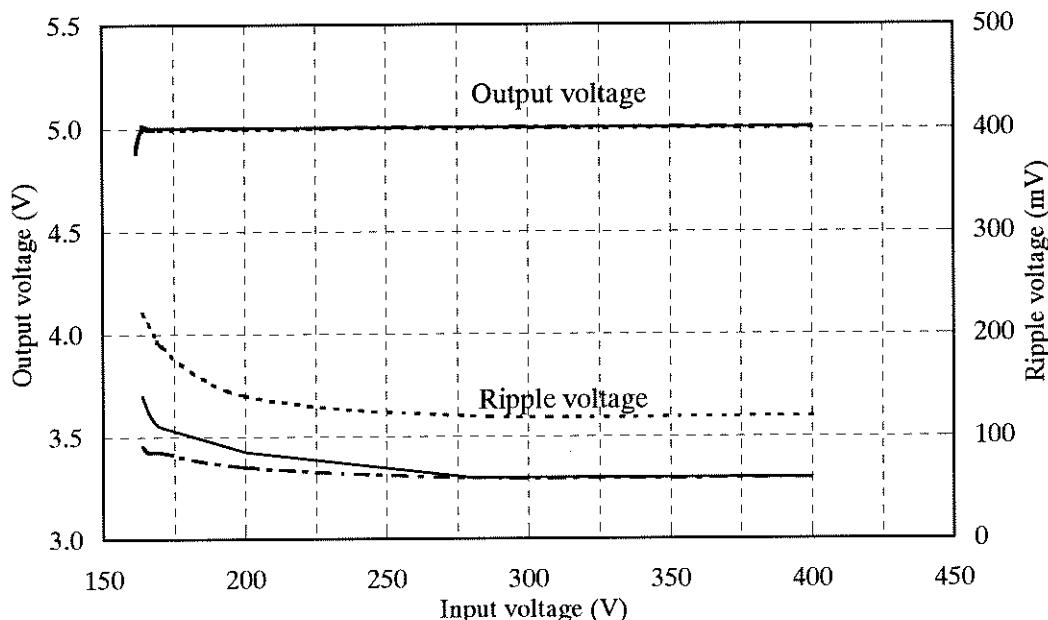


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2.1 (2) 出力電圧、リップル電圧対入力電圧  
 Output voltage and ripple voltage v.s. input voltage

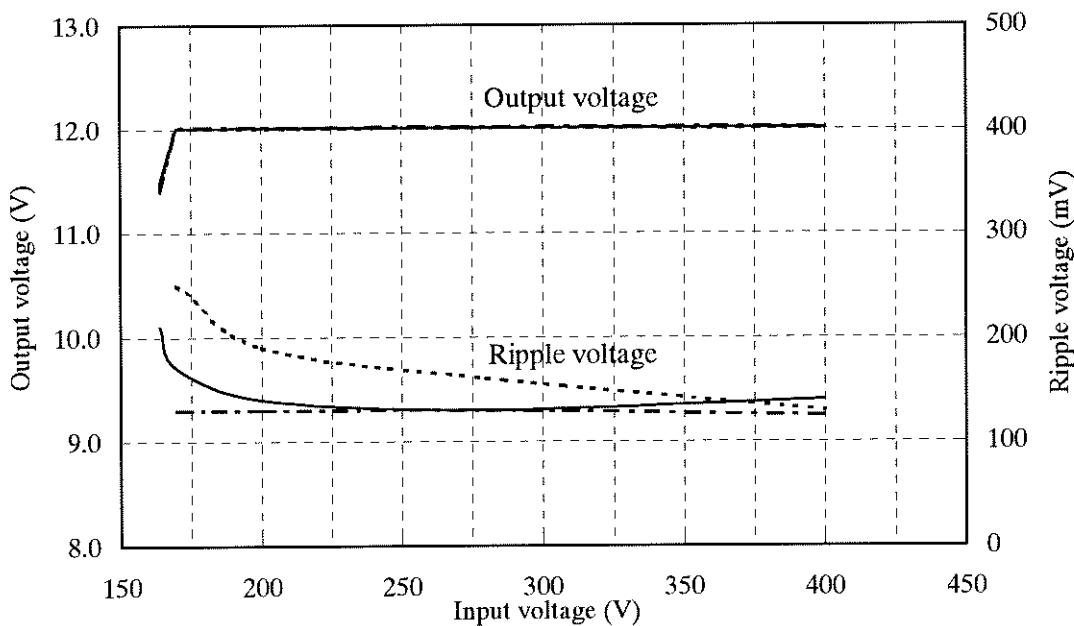
5V

Conditions Iout : 100 %  
 Tp : -20 °C .....  
 : 25 °C - - - -  
 : 100 °C ———



12V

Conditions Iout : 100 %  
 Tp : -20 °C .....  
 : 25 °C - - - -  
 : 90 °C ——— \*4



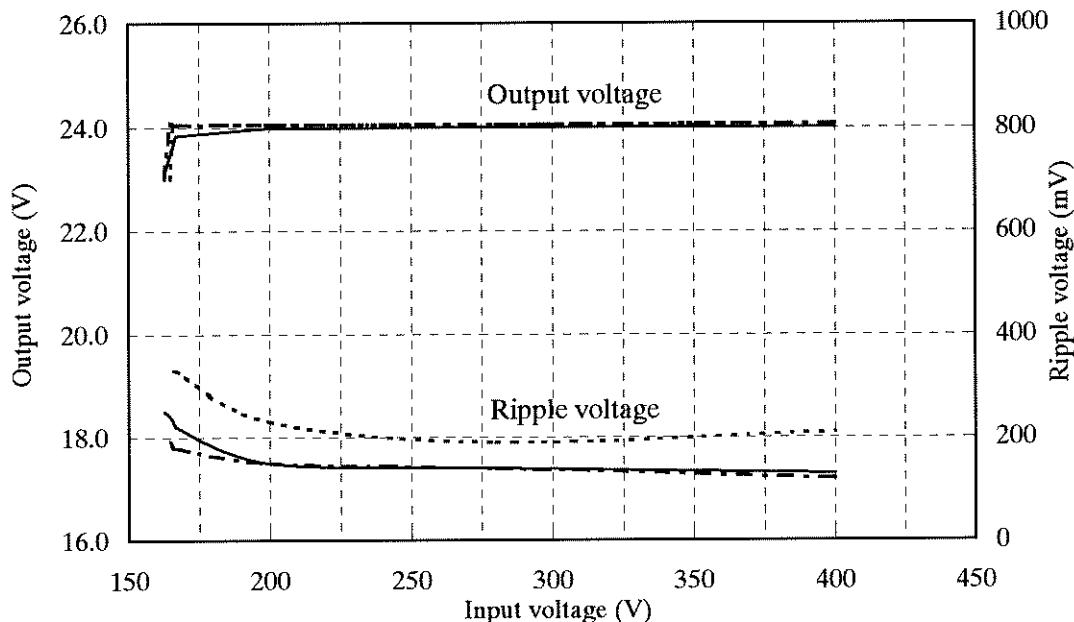
\*4) Tp : 100°C, Iout : 83% においても同等の特性を示します。  
 Same characteristics at Tp : 100°C, Iout : 83%.

2.1 (2) 出力電圧、リップル電圧対入力電圧  
 Output voltage and ripple voltage v.s. input voltage

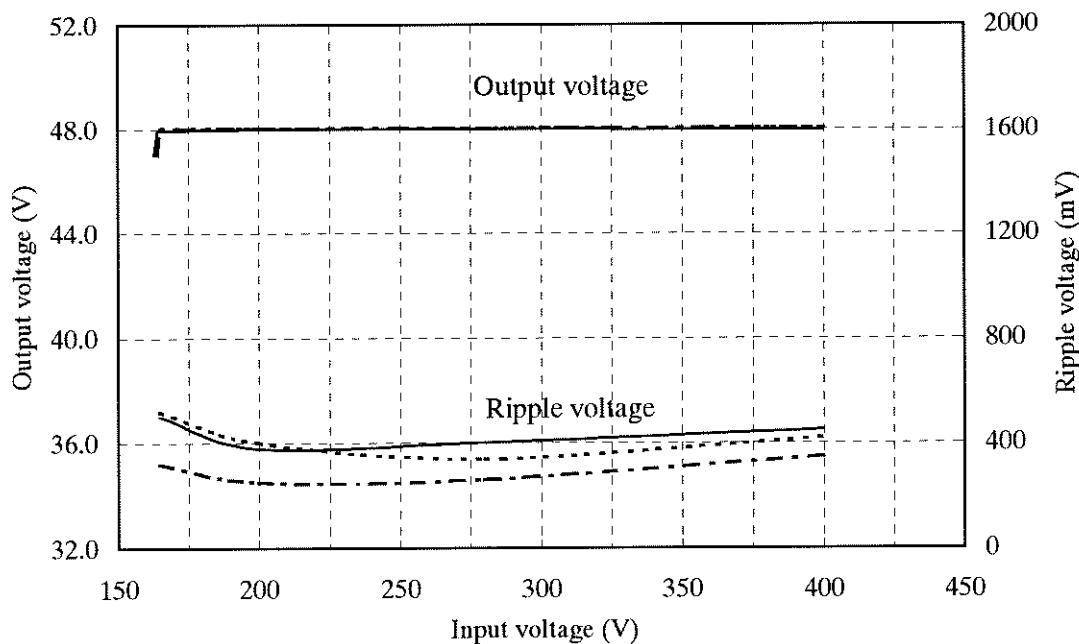
Conditions Iout : 100 %

T<sub>p</sub> : -20 °C .....  
 : 25 °C .....  
 : 90 °C ———\*5

24V



48V



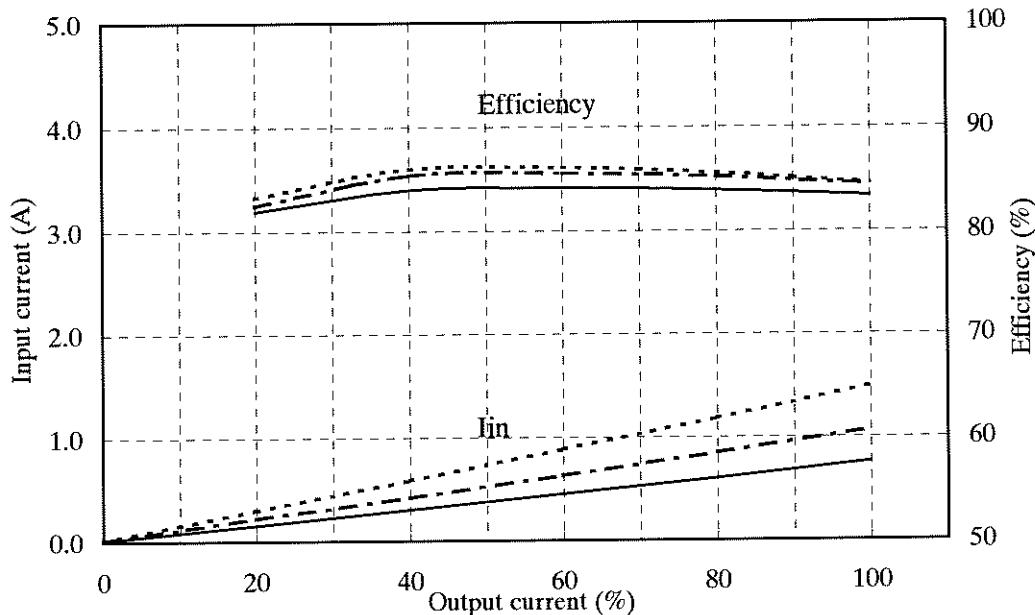
\*5) T<sub>p</sub> : 100°C, Iout : 83% においても同等の特性を示します。  
 Same characteristics at T<sub>p</sub> : 100°C, Iout : 83%.

## 2.1 (3) 効率、入力電流対出力電流

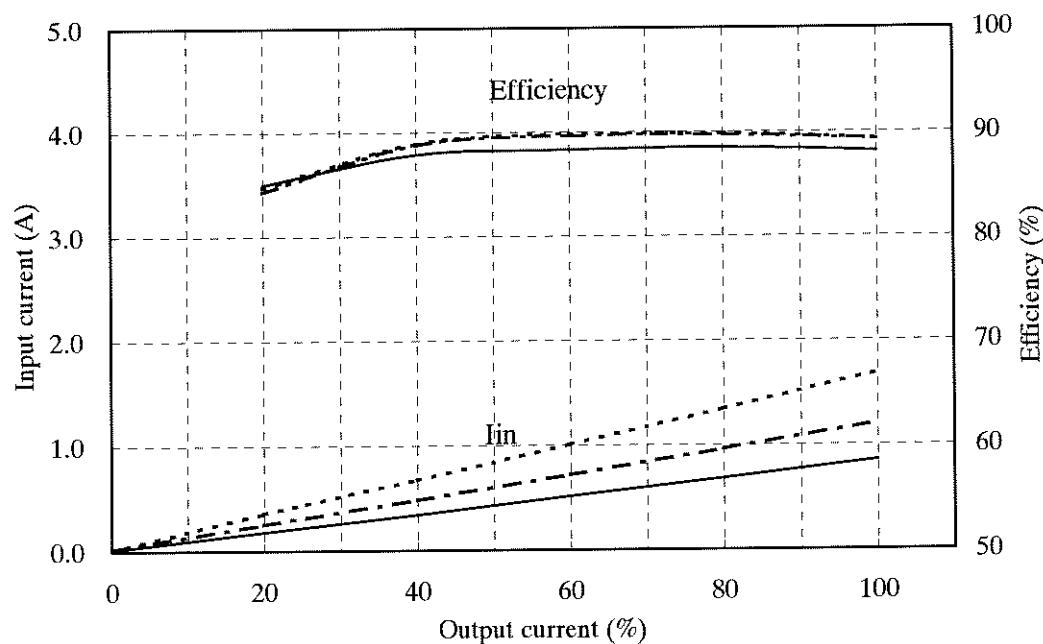
· Efficiency and input current v.s. output current

Conditions Vin : 200 VDC .....  
 ..... 280 VDC - - -  
 ..... 400 VDC ———  
 Tp : 25 °C

5V



12V

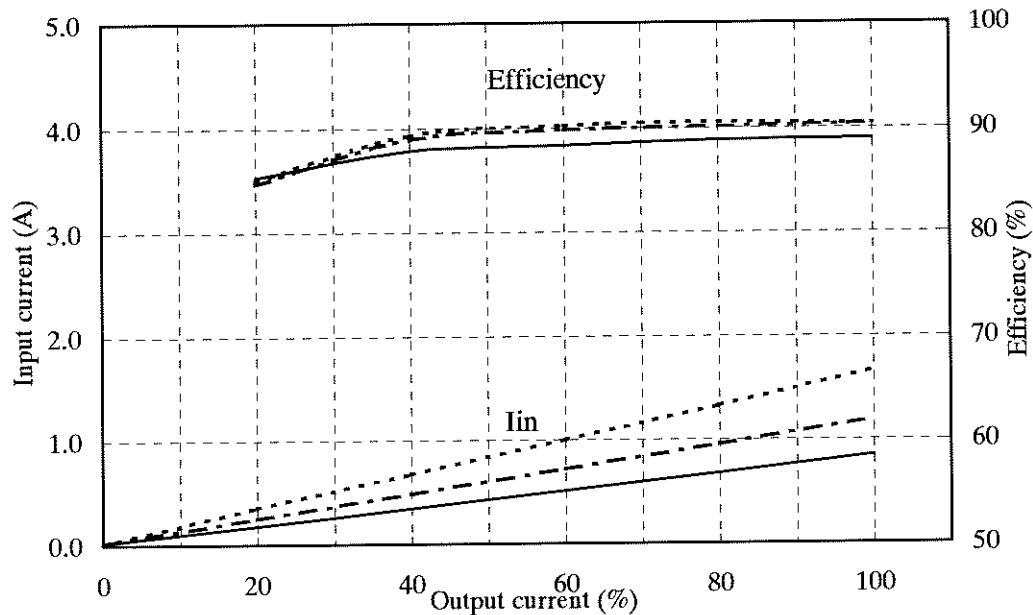


## 2.1 (3) 効率、入力電流対出力電流

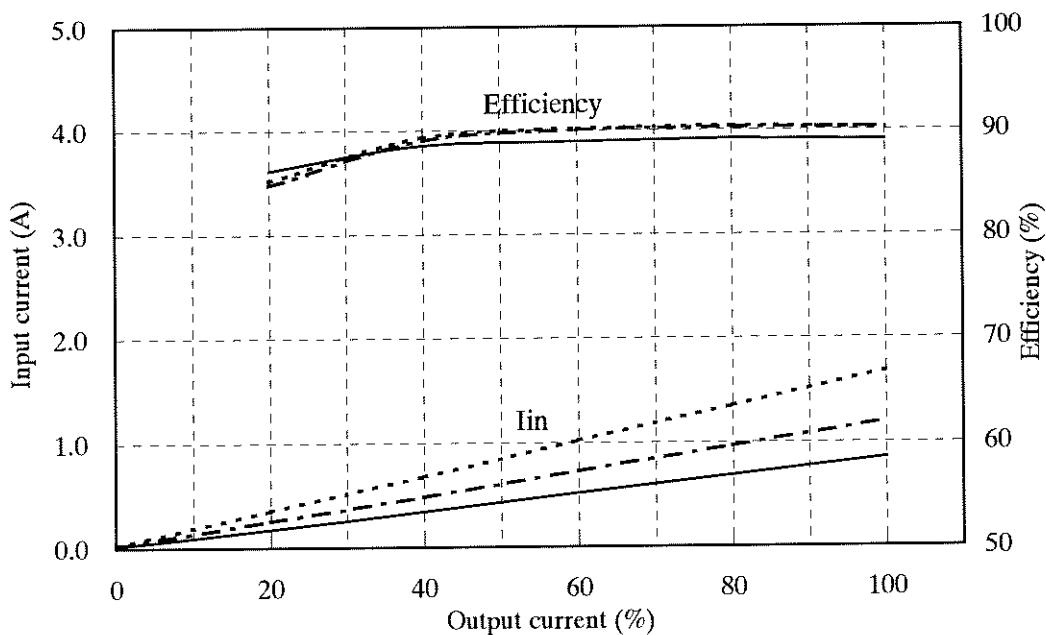
Efficiency and input current v.s. output current

Conditions Vin : 200 VDC .....  
 ..... : 280 VDC - - -  
 ..... : 400 VDC ———  
 Tp : 25 °C

24V



48V



## 2.1 (4) 効率対入力電圧

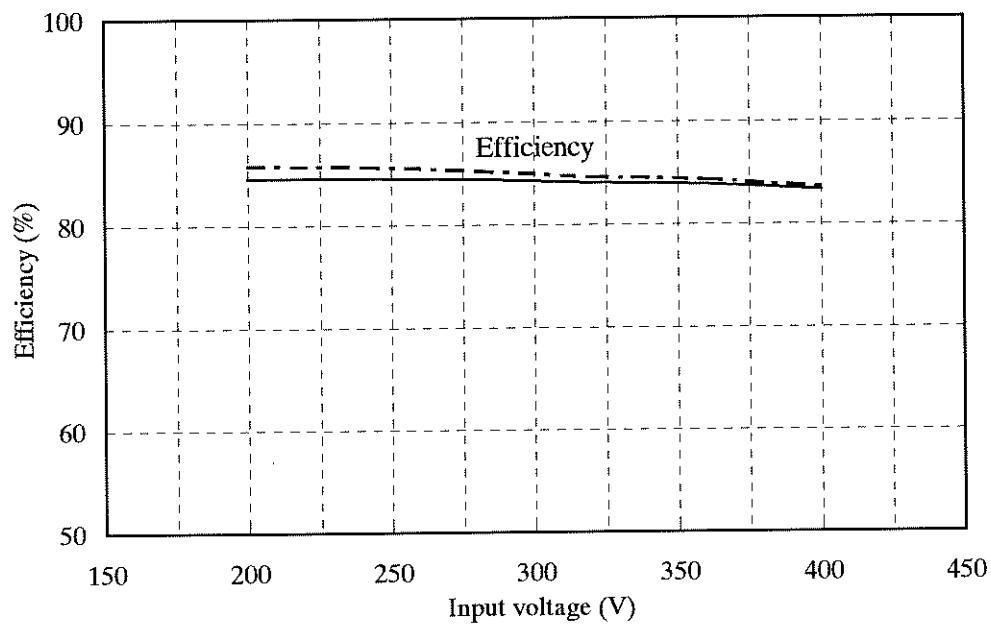
Efficiency v.s. input voltage

Conditions Tp : 25 °C

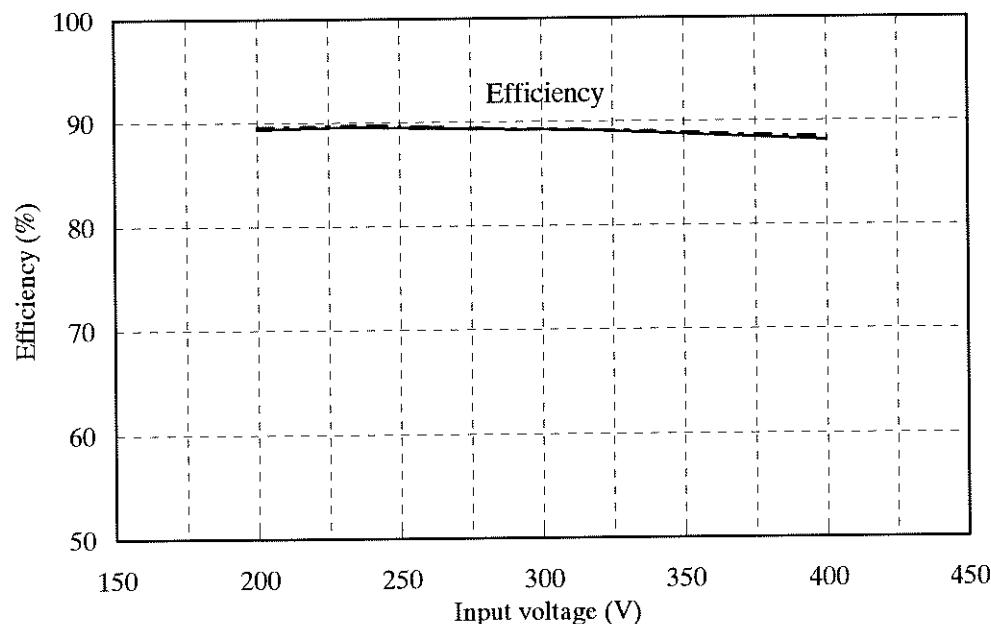
Iout : 50 % - - -

100 % ———

5V



12V



## 2.1 (4) 効率対入力電圧

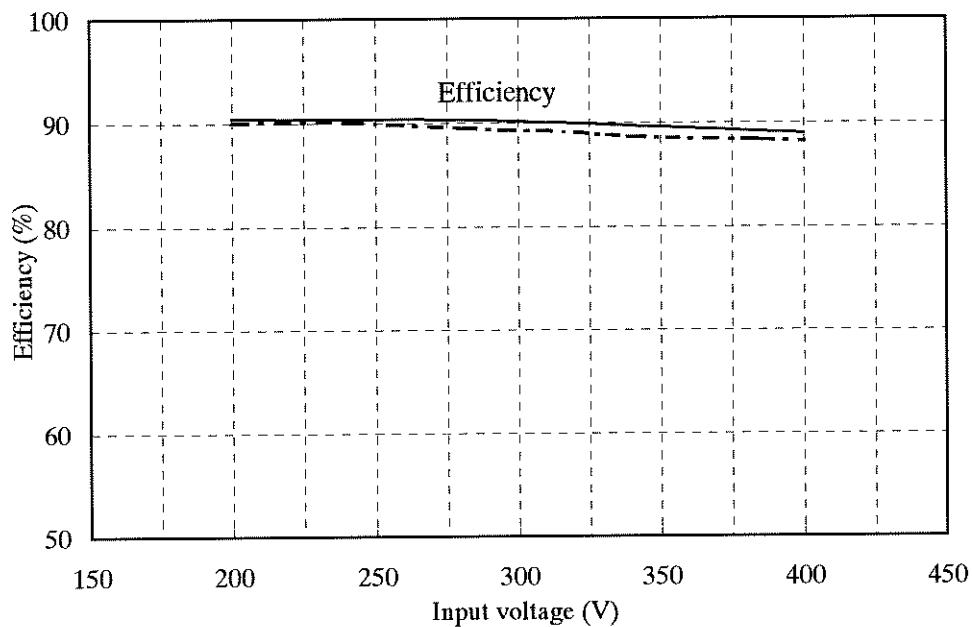
Efficiency v.s. input voltage

Conditions Tp : 25 °C

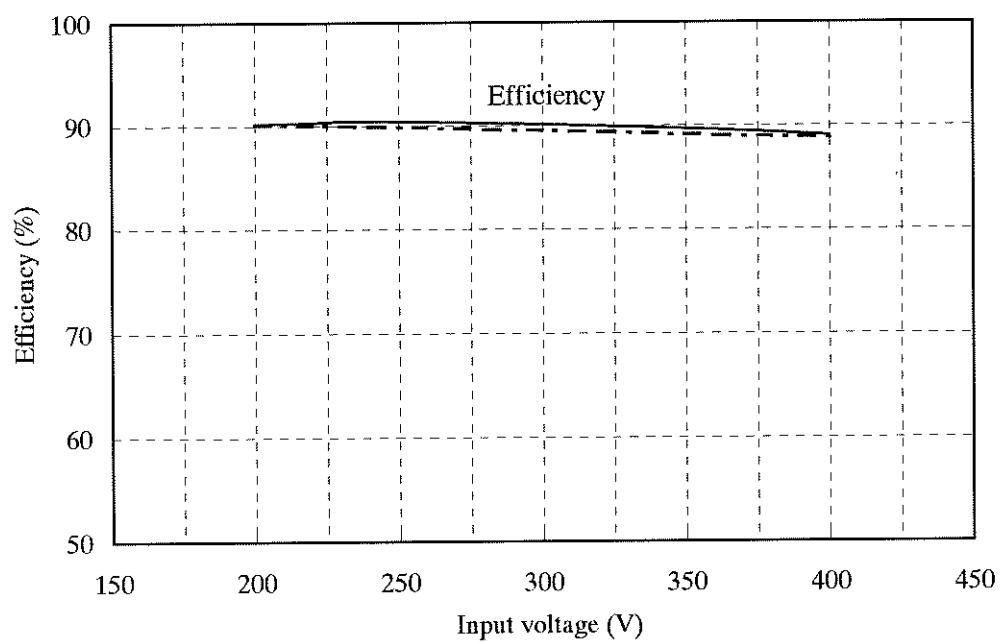
Iout : 50 %

100 %

24V



48V



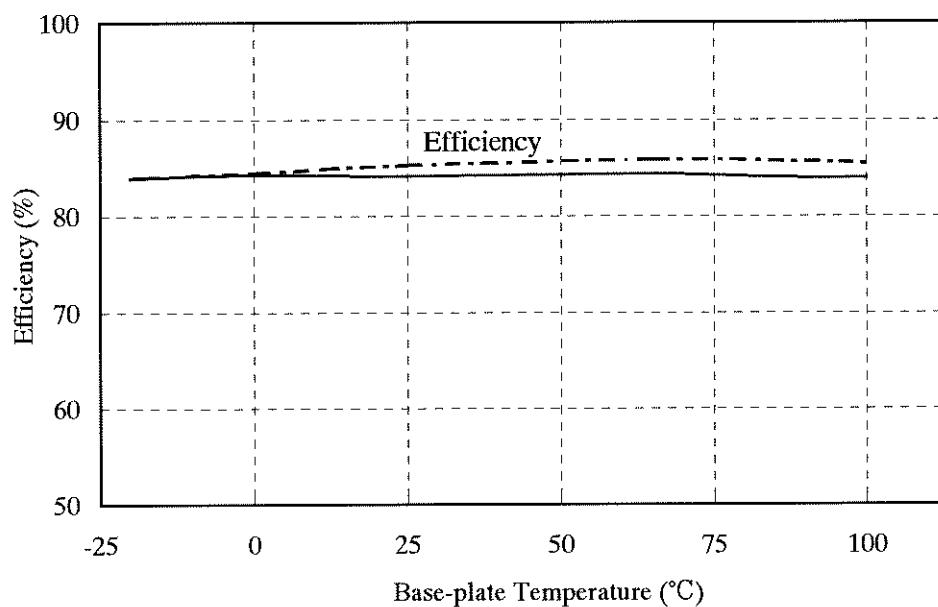
## 2.1 (5) 効率対ベースプレート温度

Efficiency v.s. base-plate temperature

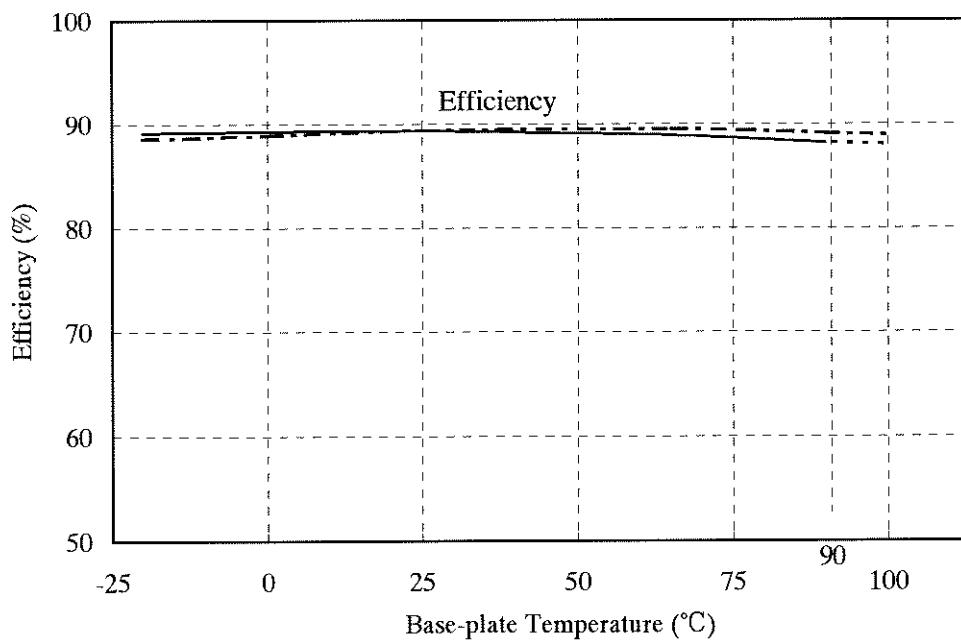
Conditions Vin : 280 VDC

Iout : 50 % - - -  
 100 % —————  
 83 % ·····

5V



12V

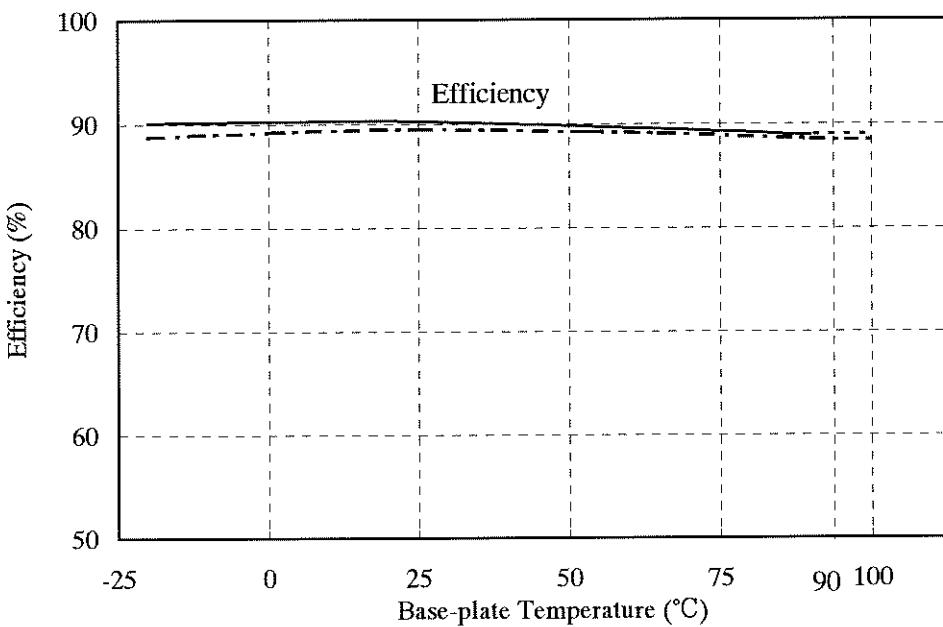


2.1 (5) 効率対ベースプレート温度  
Efficiency v.s. base-plate temperature

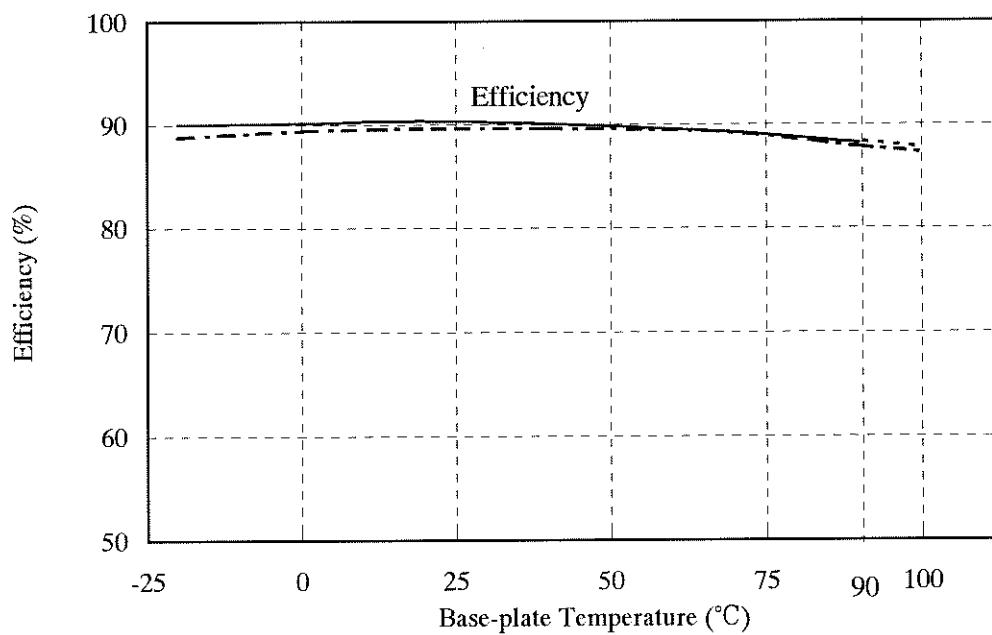
Conditions Vin : 280 VDC

Iout : 50 %	-----
100 %	———
83 %	-·---

24V



48V



## 2.2 通電ドリフト特性

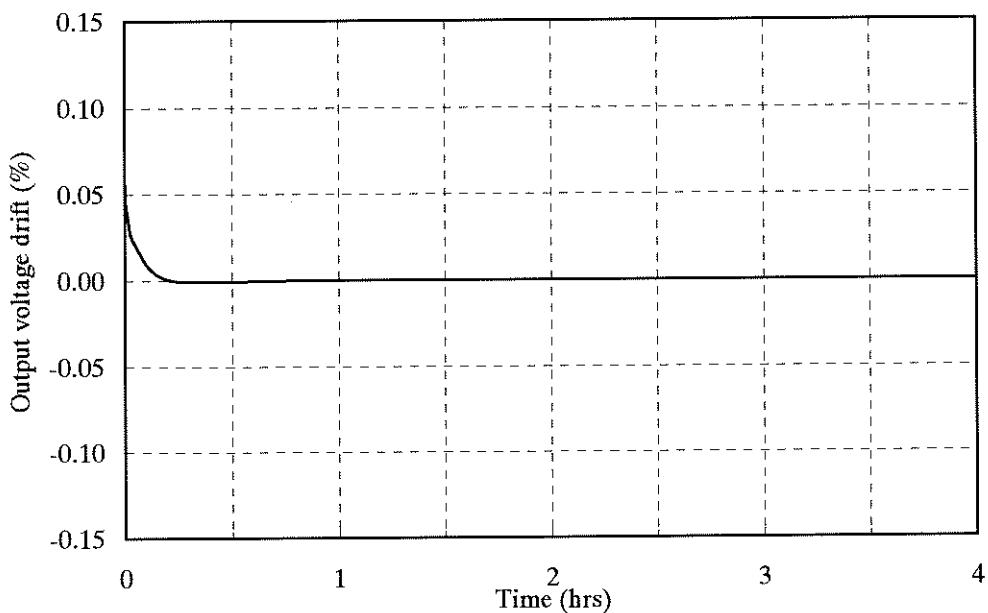
Warm up voltage drift characteristics

Conditions Vin : 280 VDC

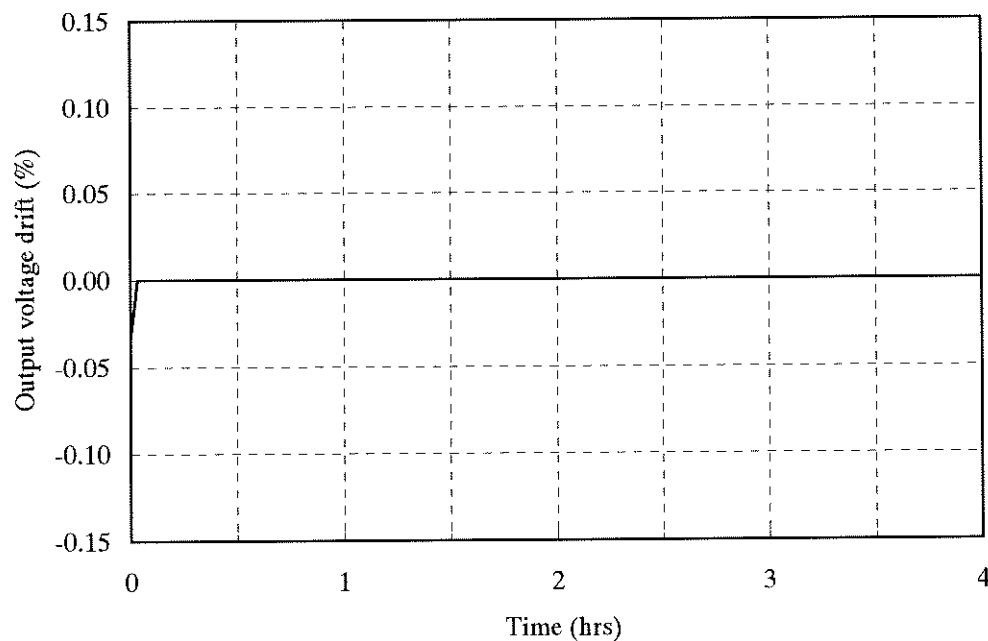
Iout : 100 %

Tp : 25 °C

5V



12V



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## 2.2 通電ドリフト特性

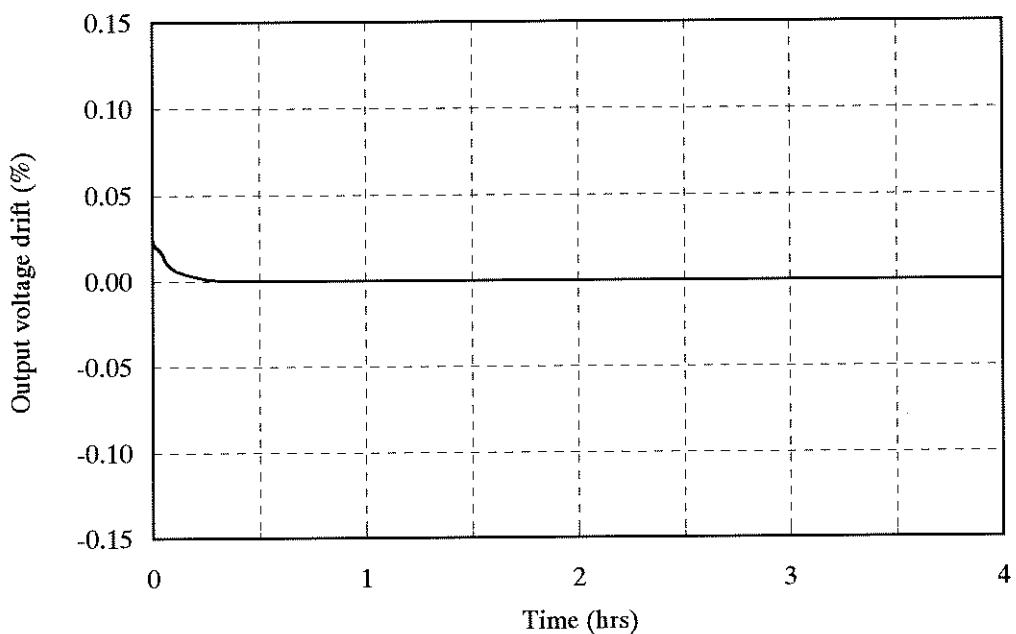
Warm up voltage drift characteristics

Conditions Vin : 280 VDC

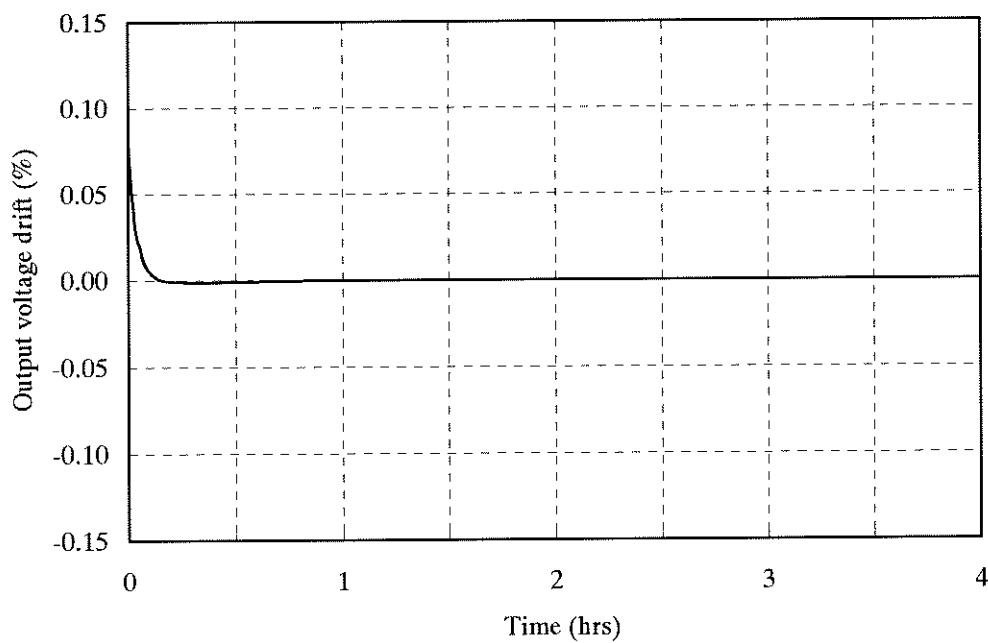
Io : 100 %

Tp : 25 °C

24V



48V



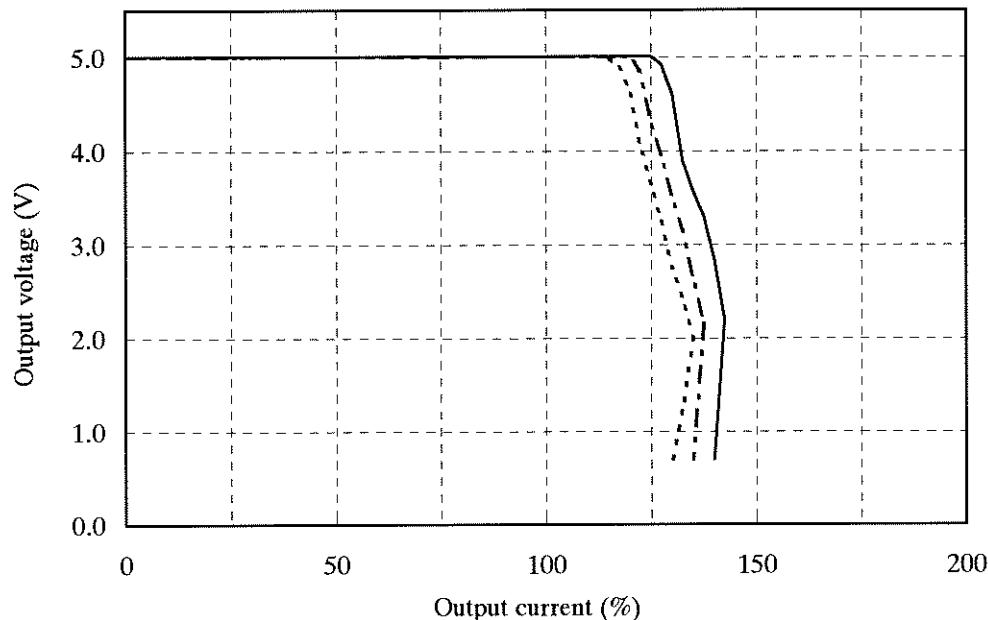
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## 2.3 過電流保護特性

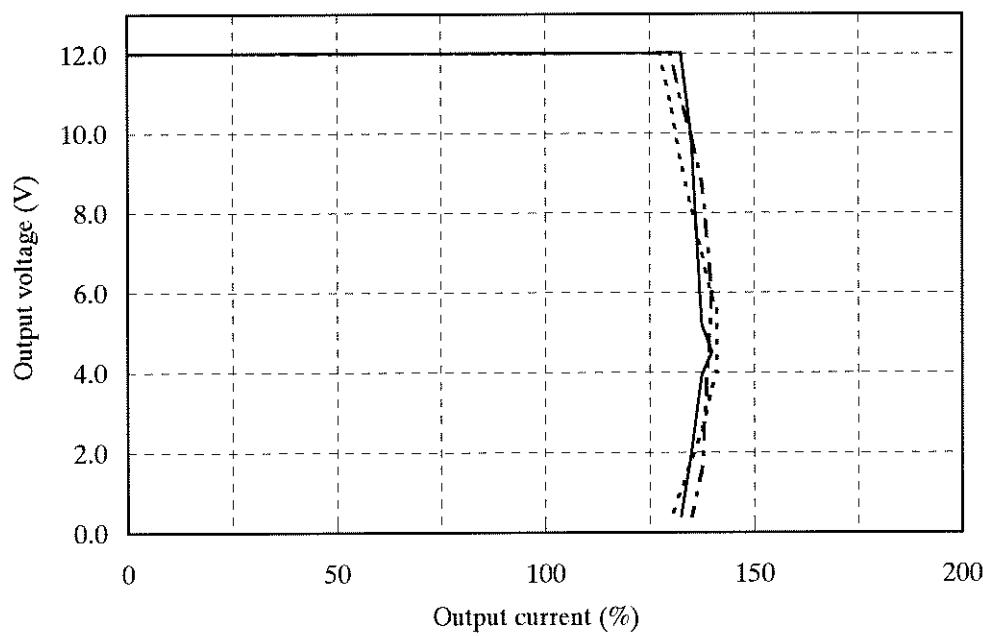
Over current protection (OCP) characteristics

Conditions Vin : 200 VDC .....  
 : 280 VDC - - - - -  
 : 400 VDC —————  
 Tp : 25 °C

5V



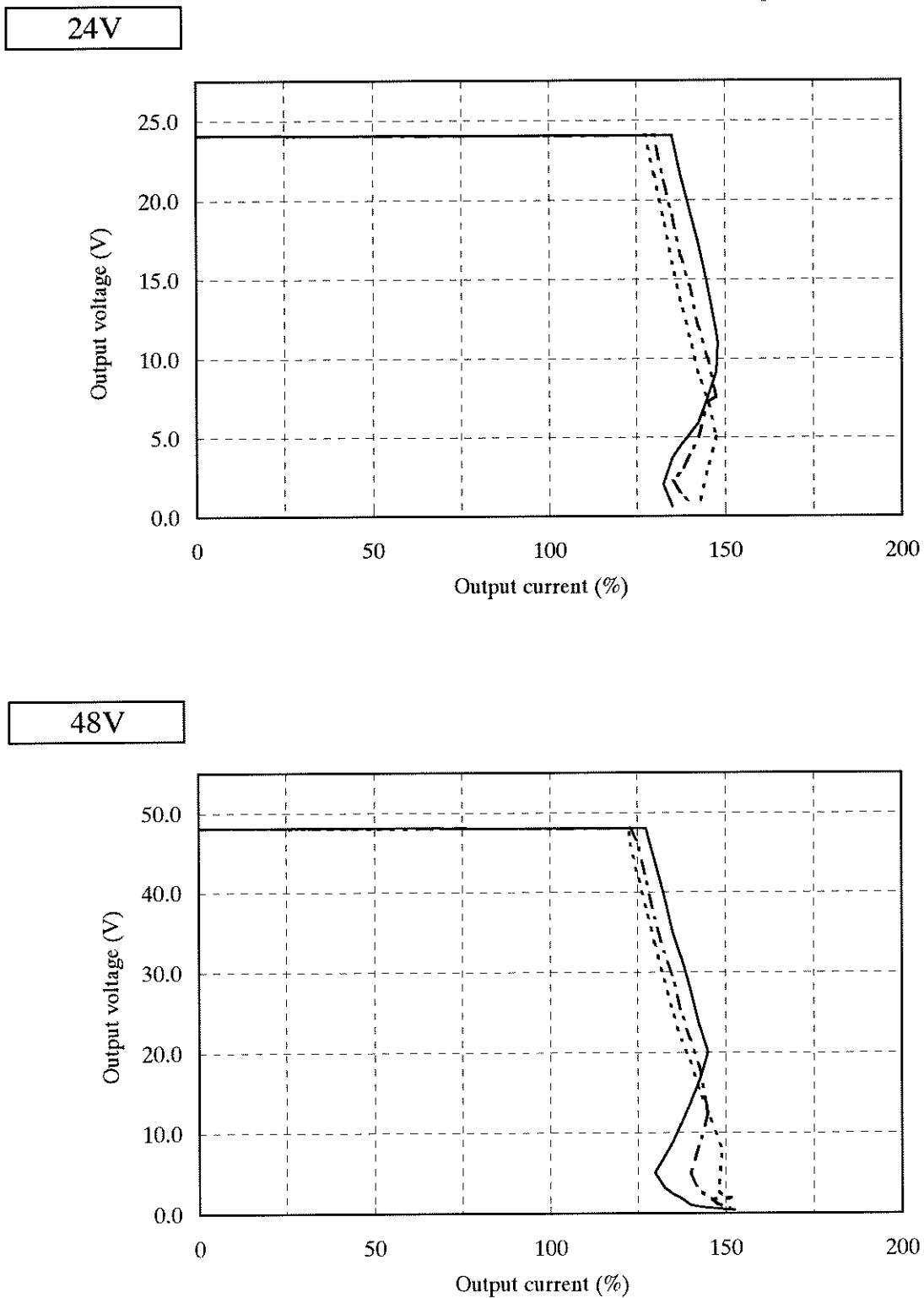
12V



## 2.3 過電流保護特性

Over current protection (OCP) characteristics

Conditions Vin : 200 VDC .....  
 : 280 VDC - - - - -  
 : 400 VDC ——————  
 Tp : 25 °C

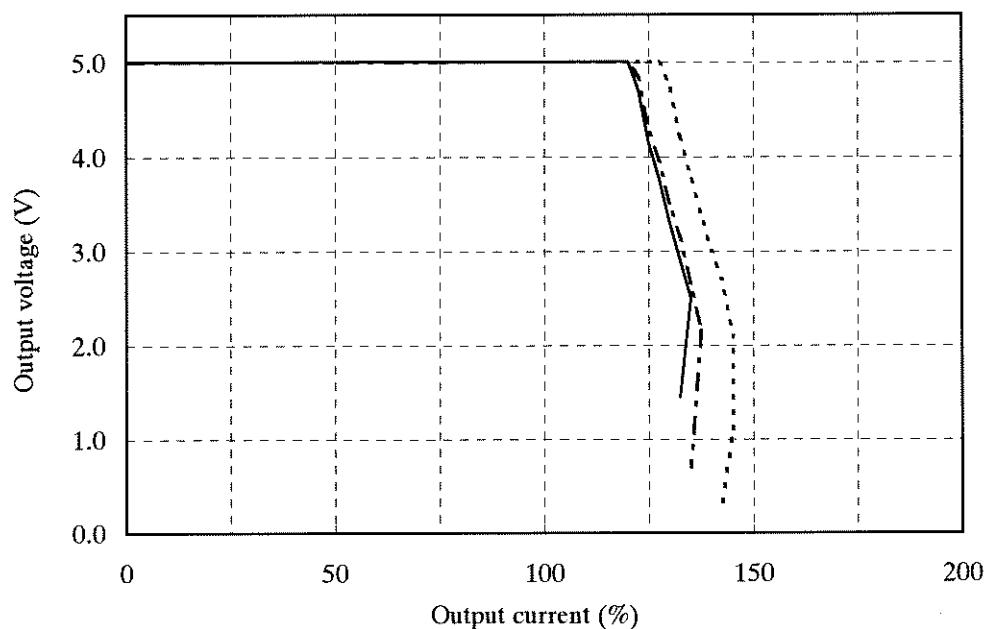


## 2.3 過電流保護特性

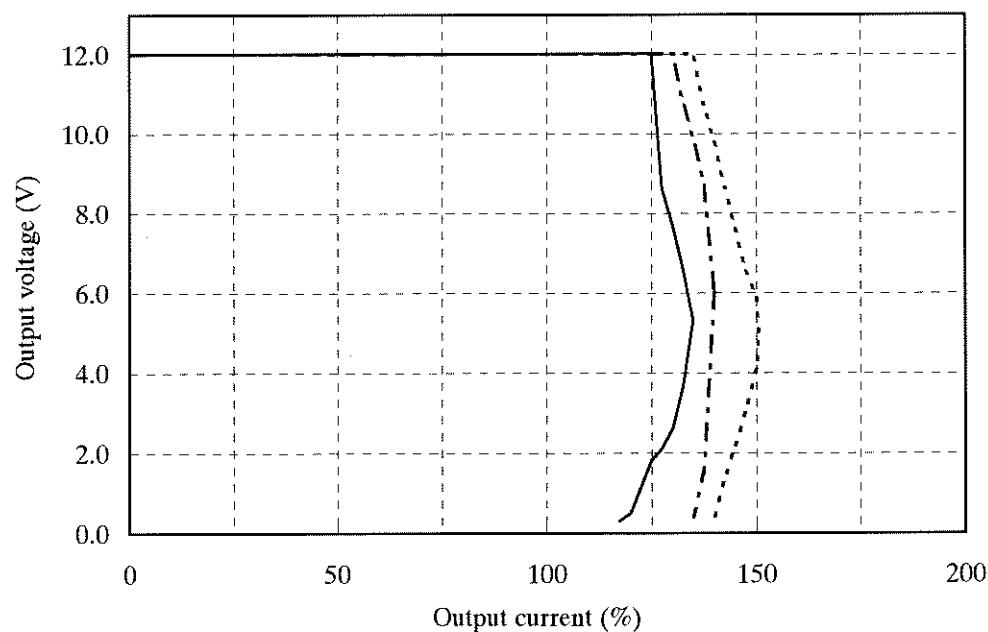
Over current protection (OCP) characteristics

Conditions  $T_p$  : -20 °C .....  
                  : 25 °C .....  
                  : 100 °C .....  
      $V_{in}$  : 280 VDC

5V



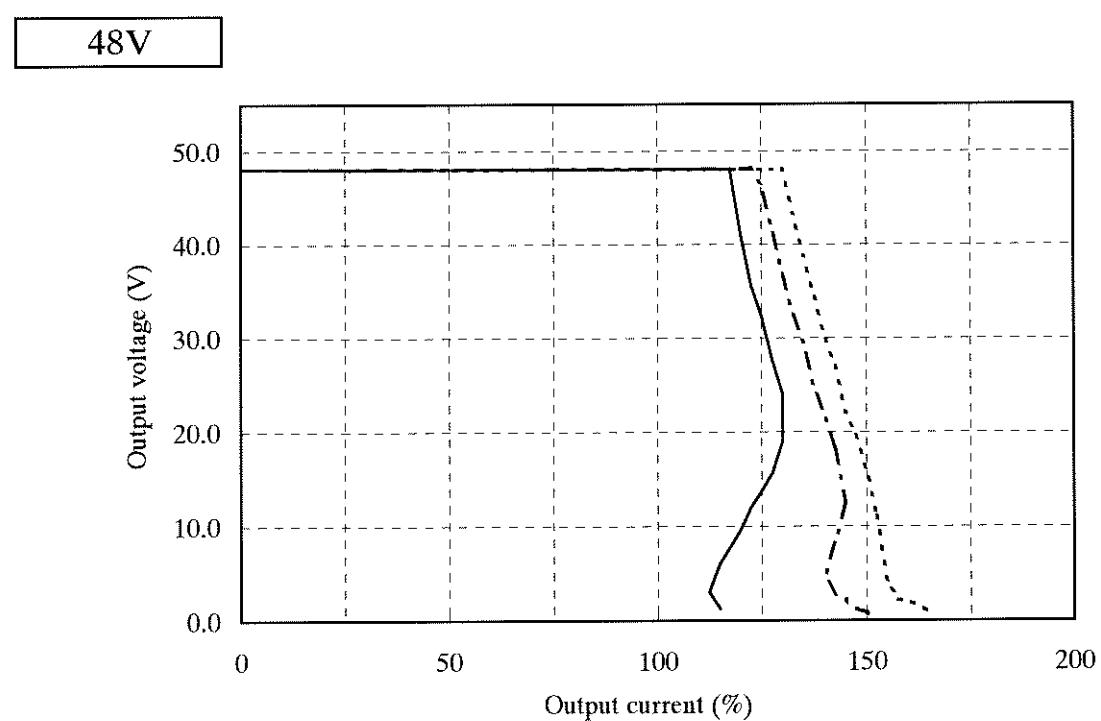
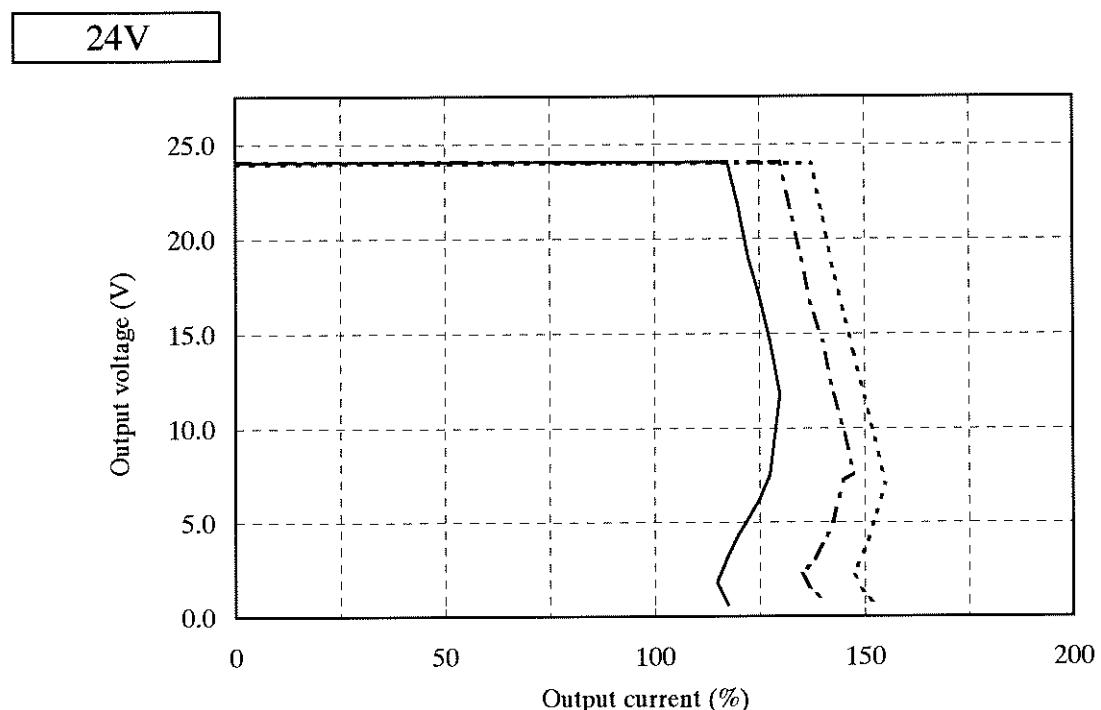
12V



## 2.3 過電流保護特性

Over current protection (OCP) characteristics

Conditions T<sub>p</sub> : -20 °C .....  
 : 25 °C .....  
 : 100 °C ———  
 Vin : 280 VDC



## 2.4 過電圧保護特性

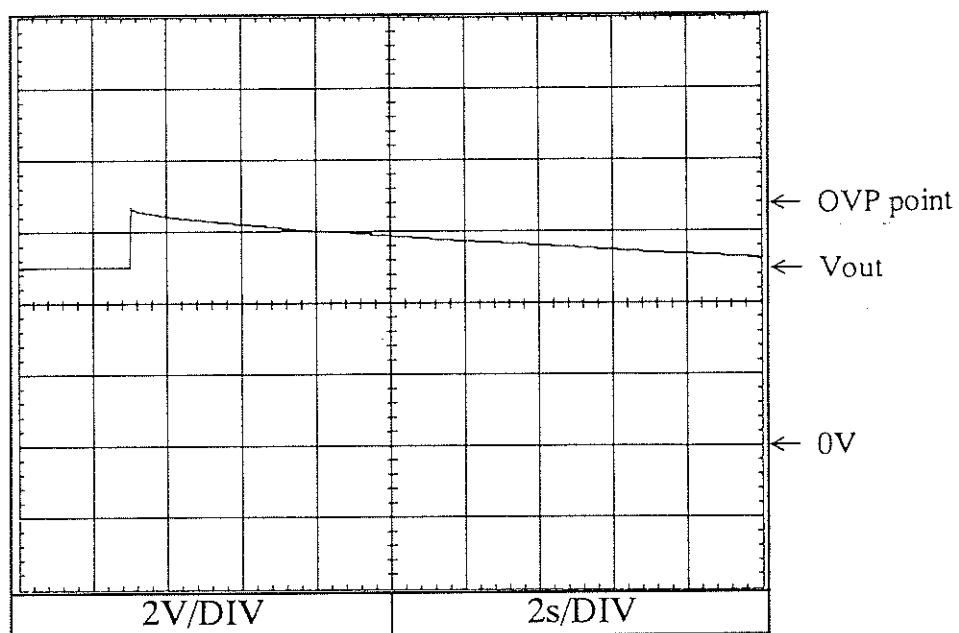
Over voltage protection (OVP) characteristics

Conditions Vin : 280 VDC

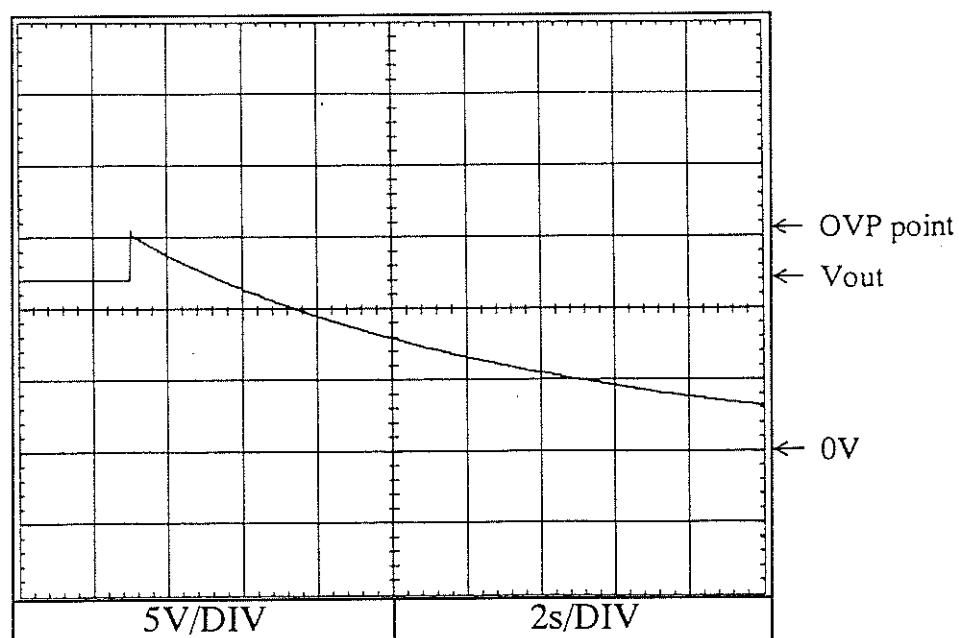
Iout : 0 %

Tp : 25 °C

5V



12V



## 2.4 過電圧保護特性

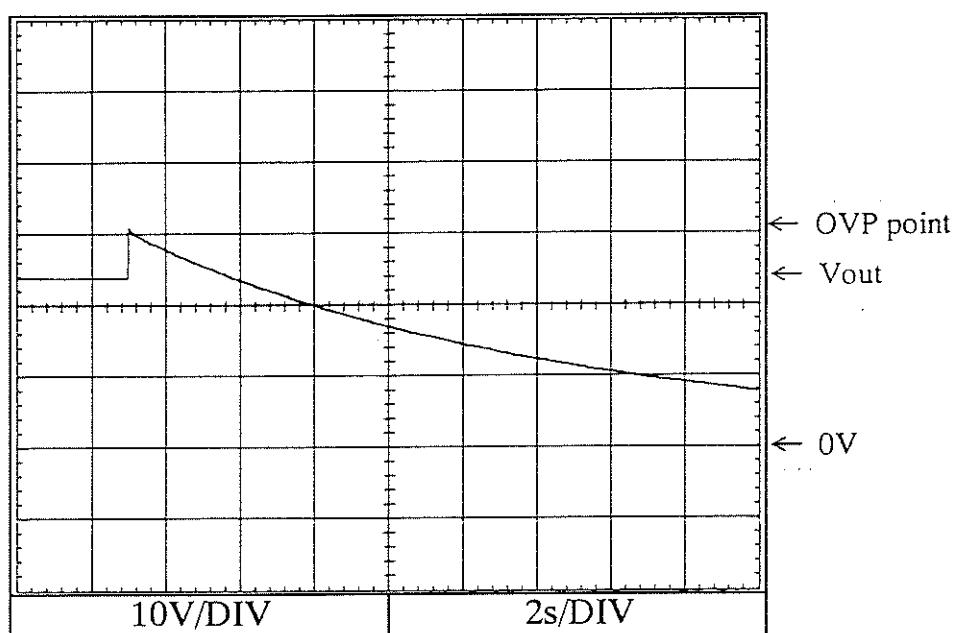
Over voltage protection (OVP) characteristics

Conditions Vin : 280 VDC

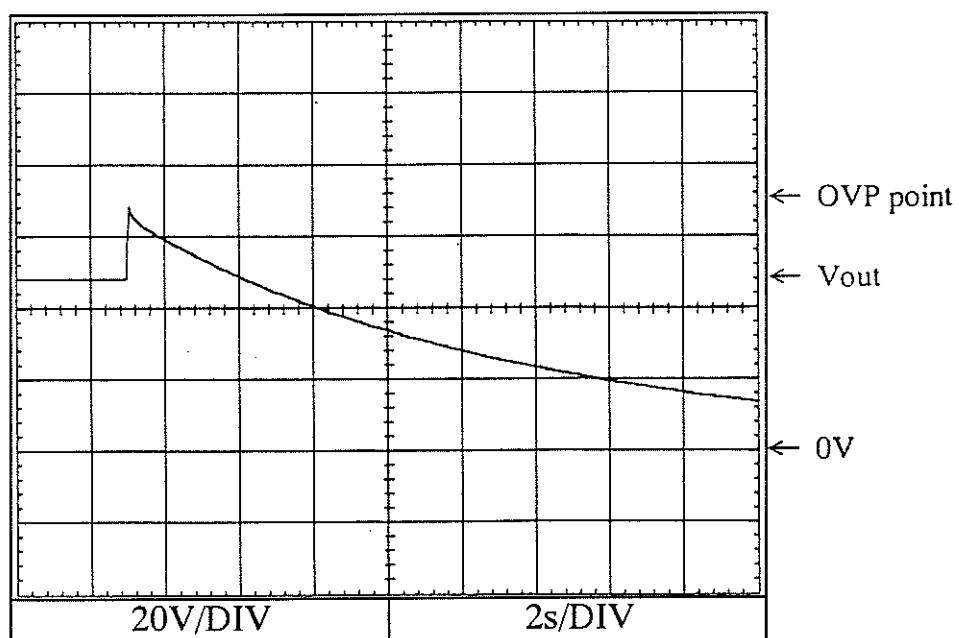
Iout : 0 %

Tp : 25 °C

24V



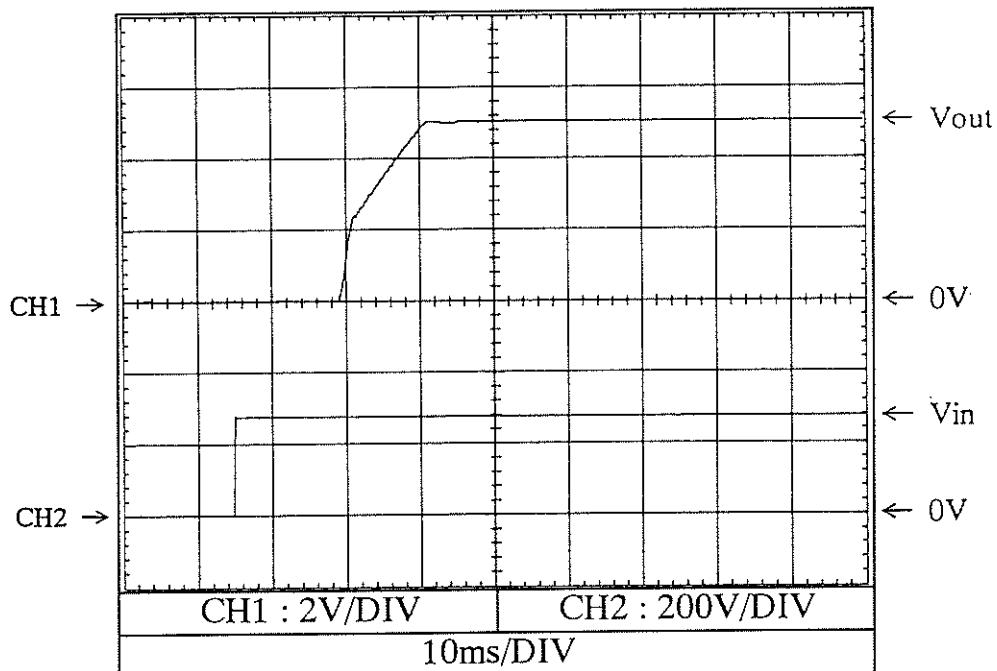
48V



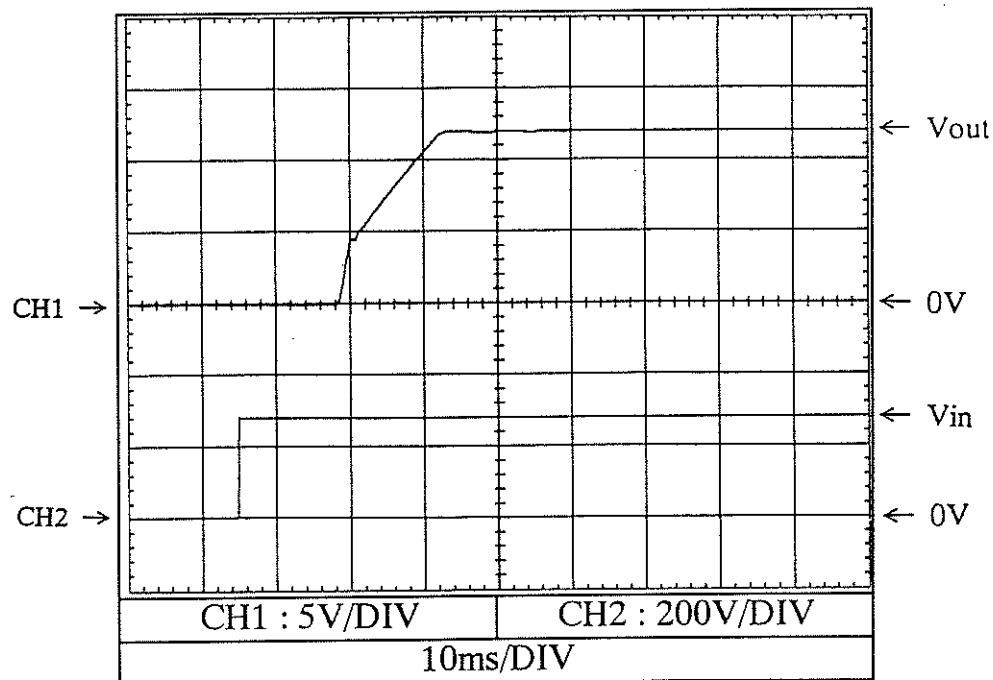
2.5 出力立ち上がり特性  
Output rise characteristics

Conditions Vin : 280 VDC  
Iout : 0 %  
Tp : 25 °C

5V



12V



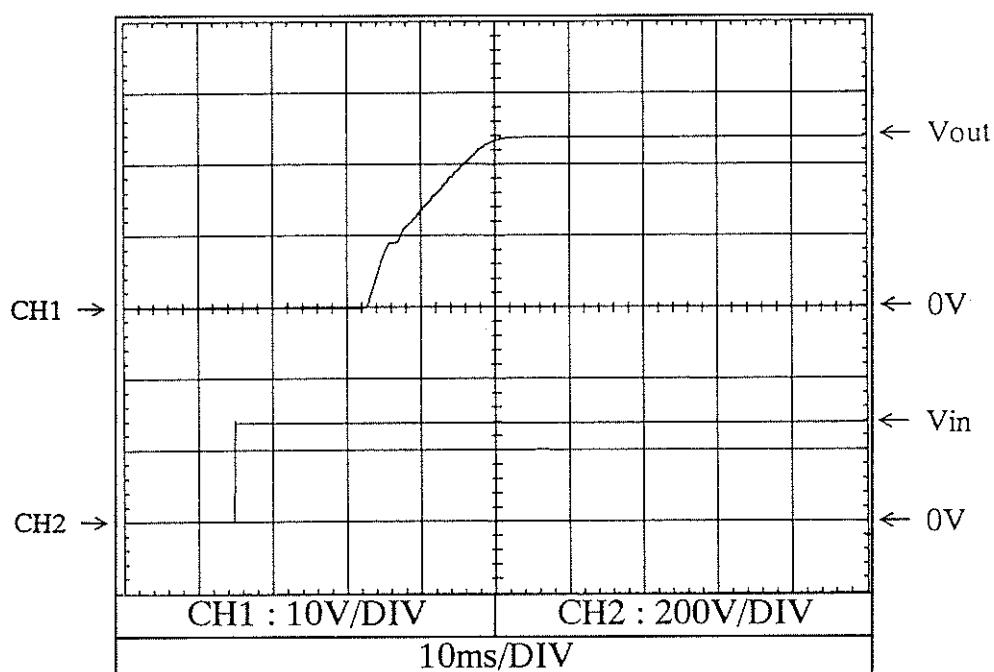
2.5 出力立ち上がり特性  
Output rise characteristics

Conditions Vin : 280 VDC

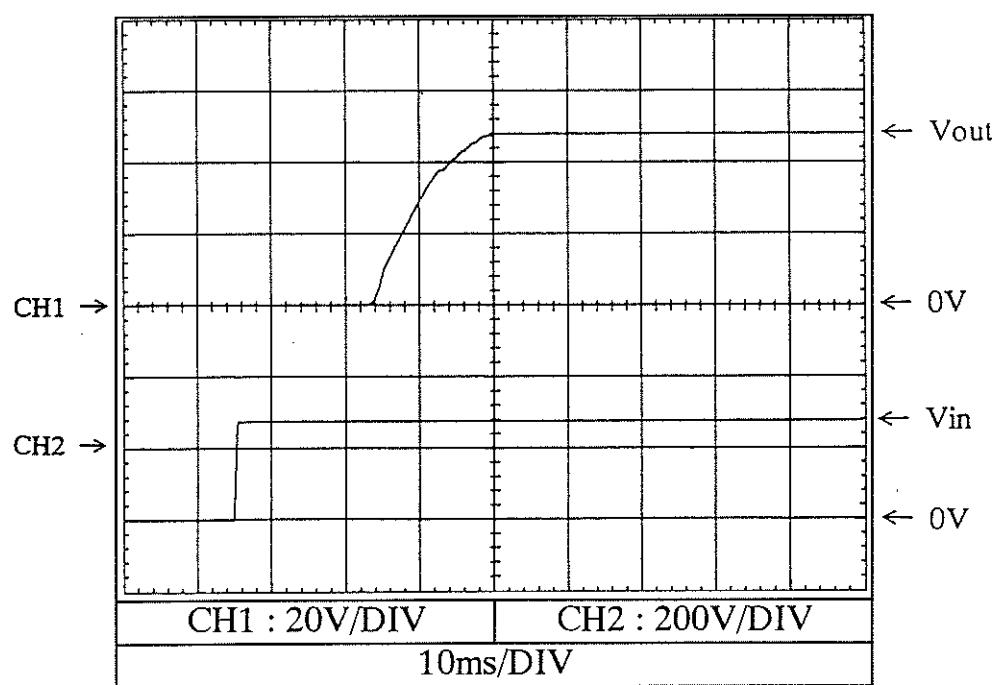
Iout : 0 %

Tp : 25 °C

24V



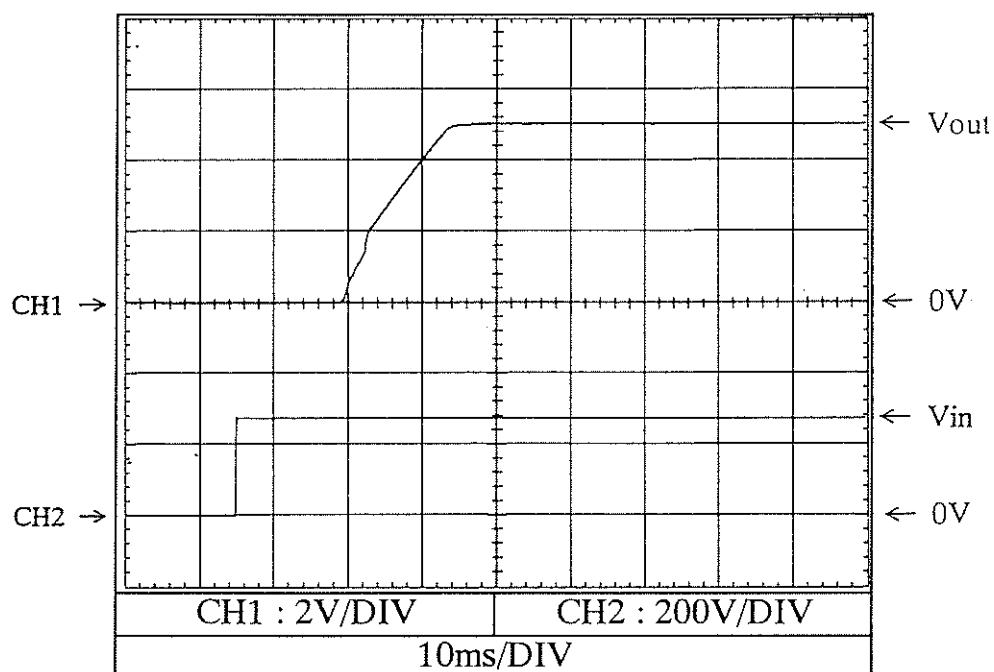
48V



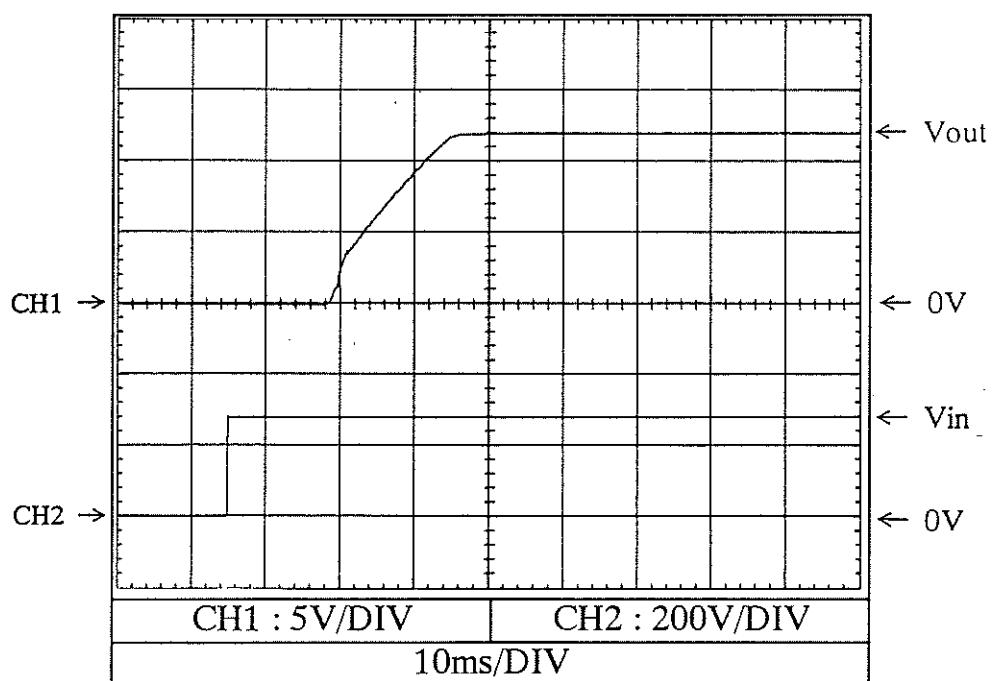
2.5 出力立ち上がり特性  
Output rise characteristics

Conditions Vin : 280 VDC  
Iout : 100 %  
Tp : 25 °C

5V



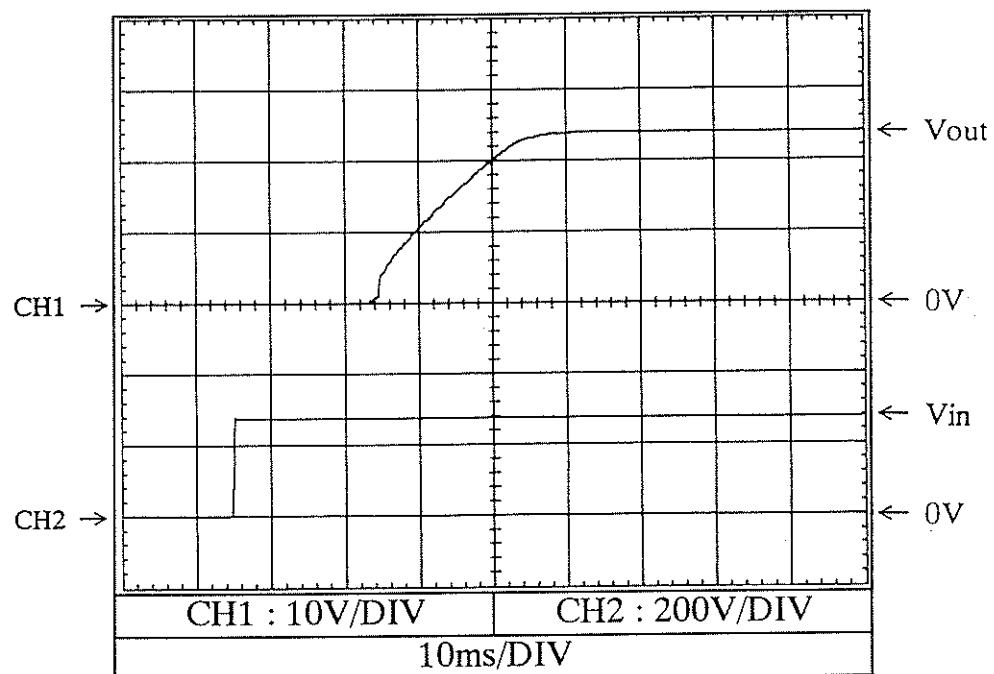
12V



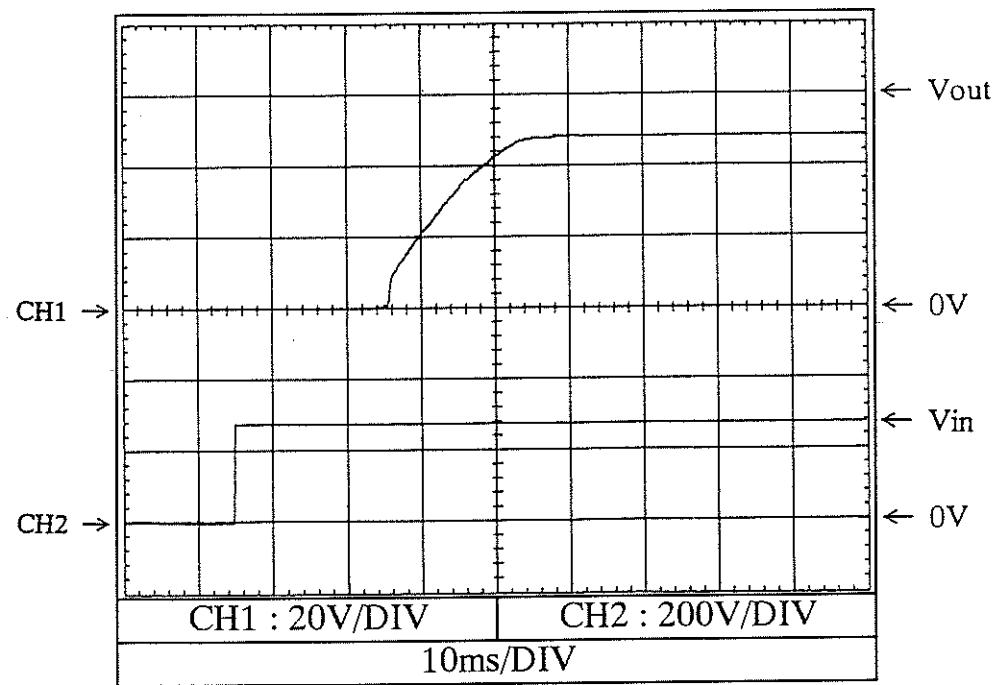
2.5 出力立ち上がり特性  
Output rise characteristics

Conditions Vin : 280 VDC  
Iout : 100 %  
Tp : 25 °C

24V



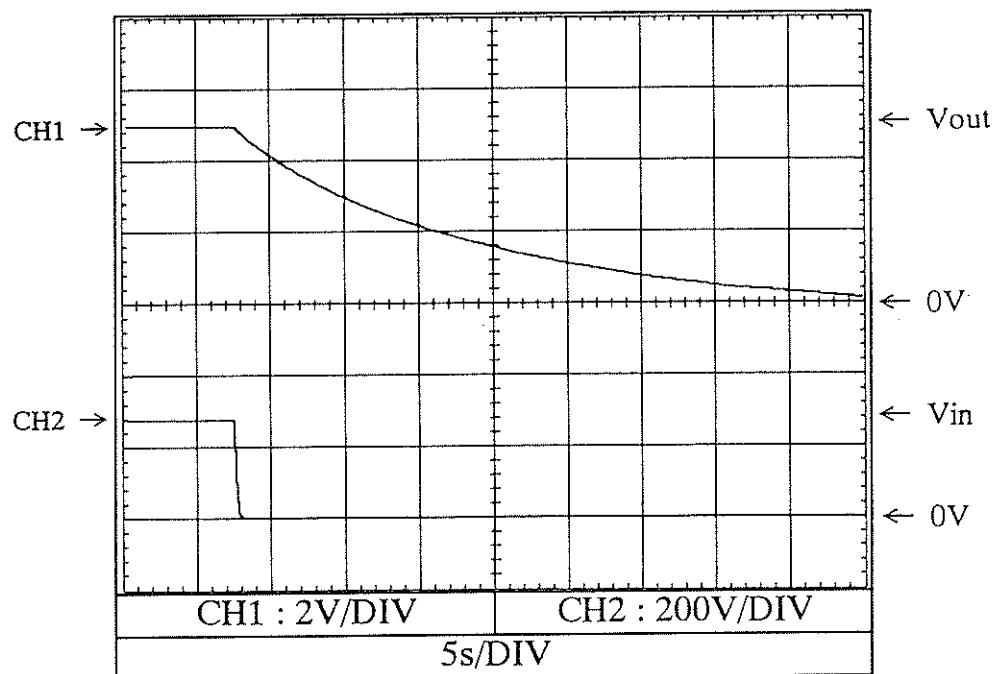
48V



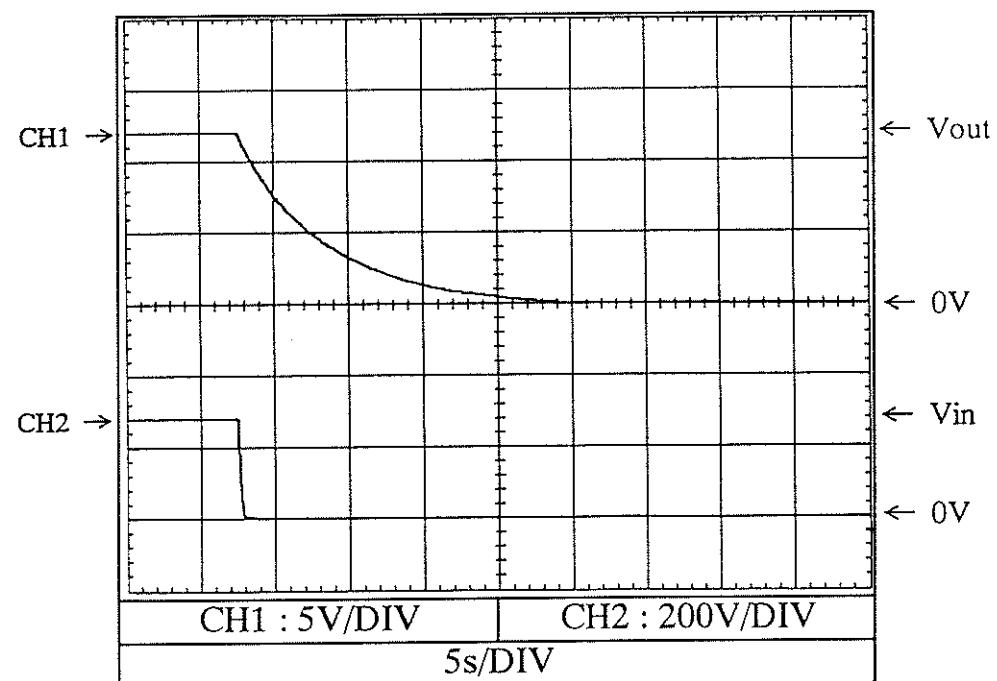
2.6 出力立ち下がり特性  
Output fall characteristics

Conditions Vin : 280 VDC  
Iout : 0 %  
Tp : 25 °C

5V



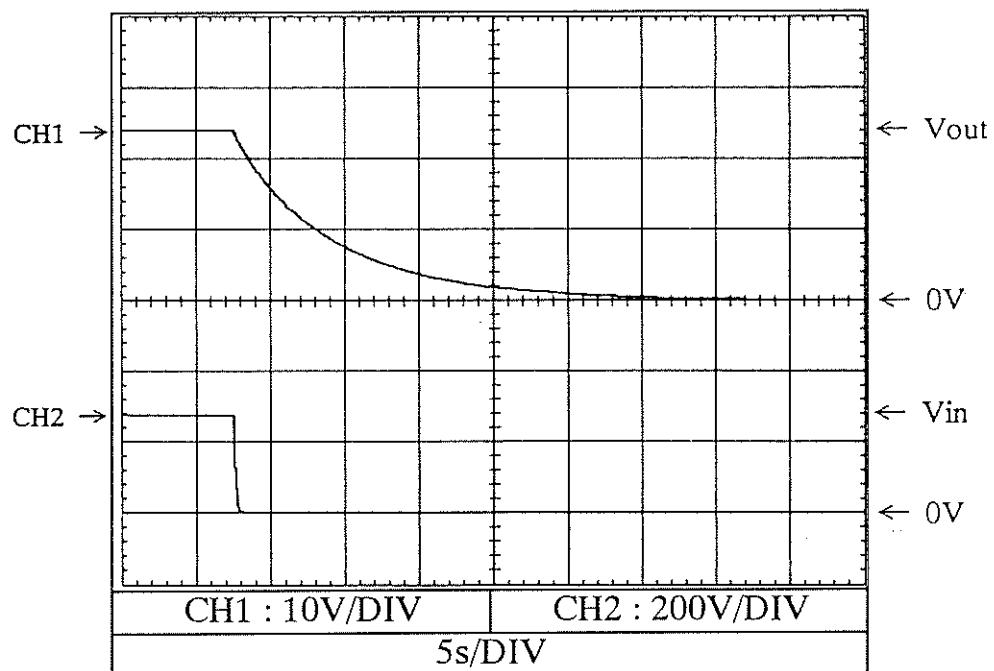
12V



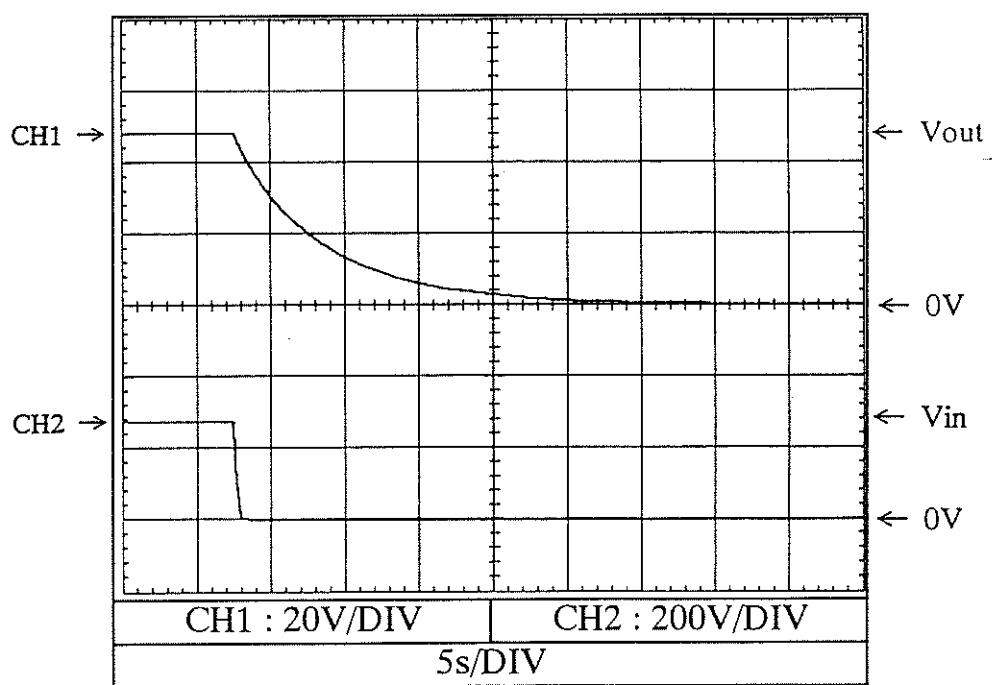
2.6 出力立ち下がり特性  
Output fall characteristics

Conditions Vin : 280 VDC  
Iout : 0 %  
Tp : 25 °C

24V



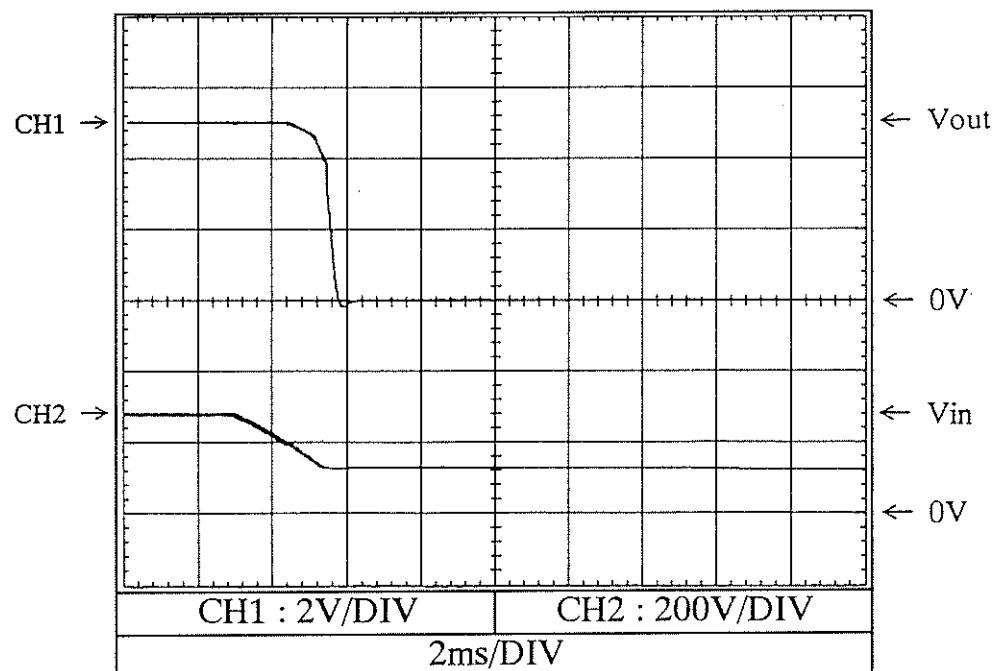
48V



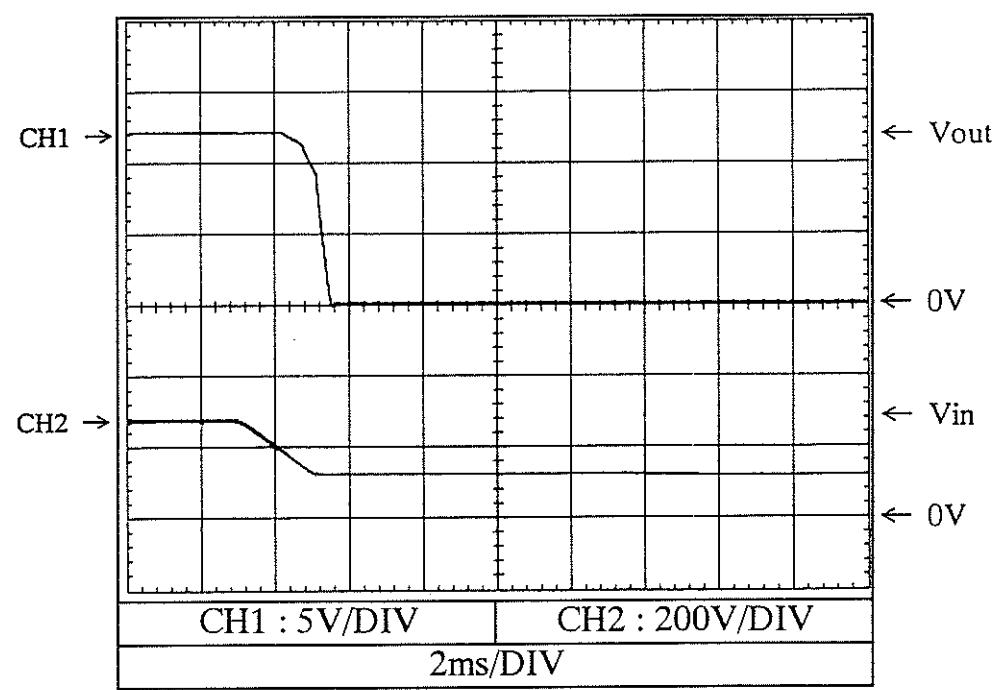
2.6 出力立ち下がり特性  
Output fall characteristics

Conditions Vin : 280 VDC  
Iout : 100 %  
Tp : 25 °C

5V



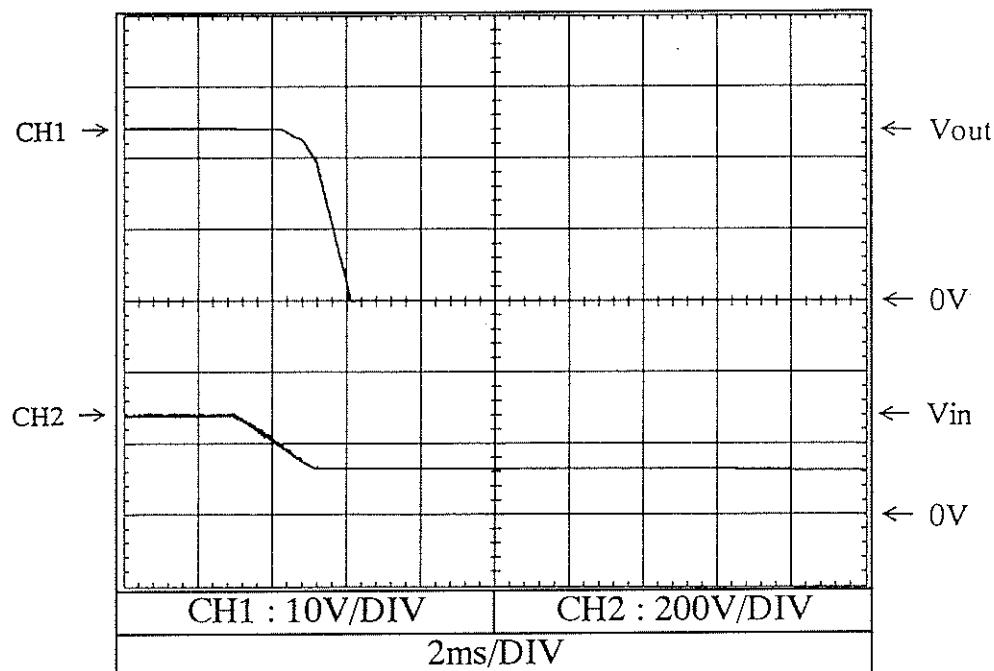
12V



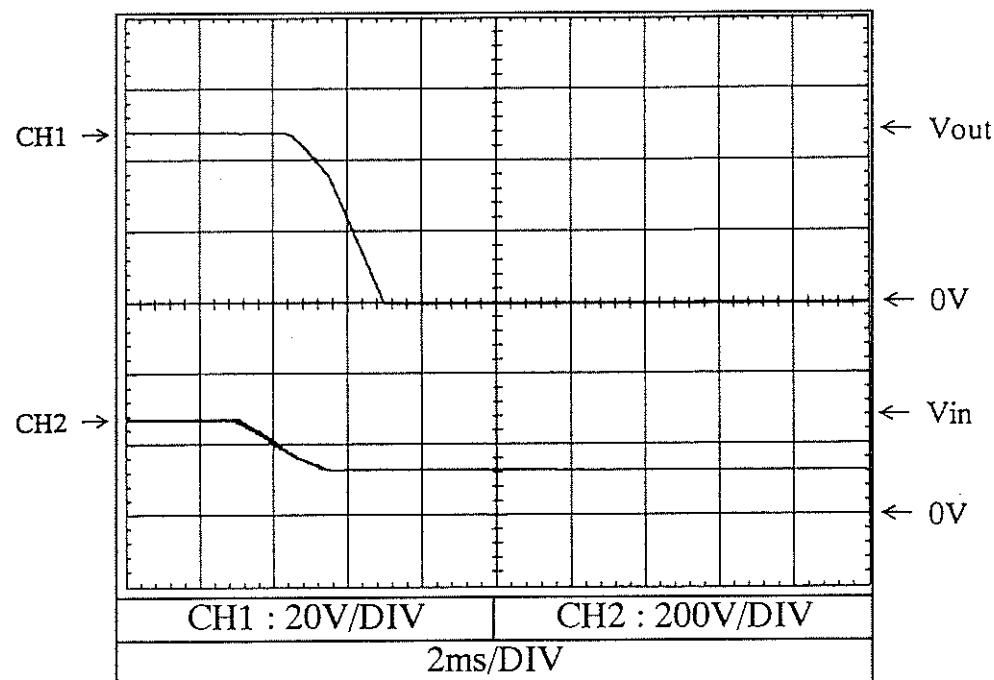
2.6 出力立ち下がり特性  
Output fall characteristics

Conditions Vin : 280 VDC  
Iout : 100 %  
Tp : 25 °C

24V



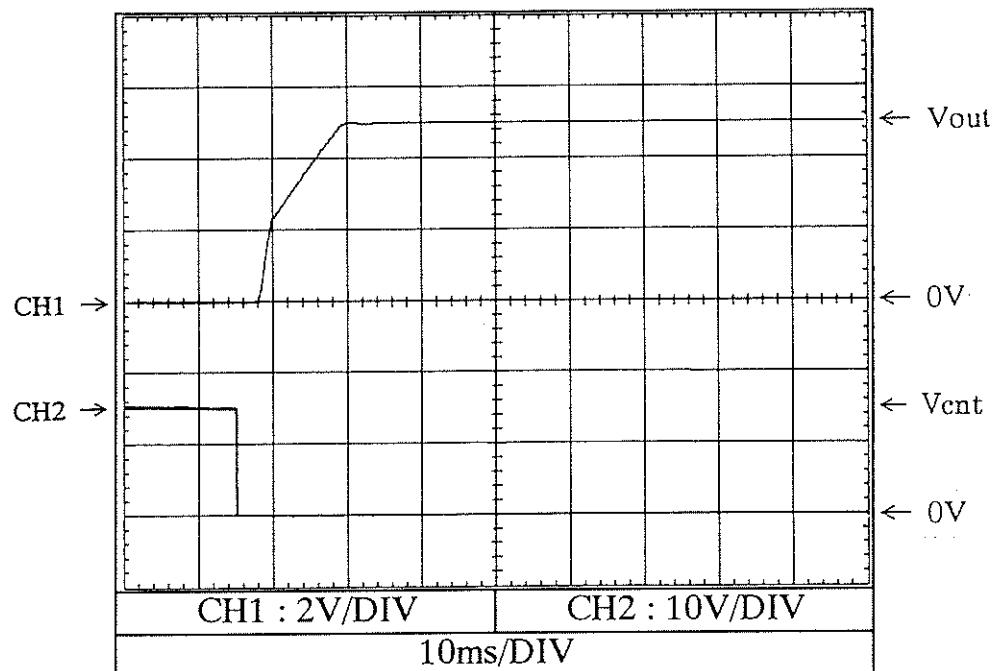
48V



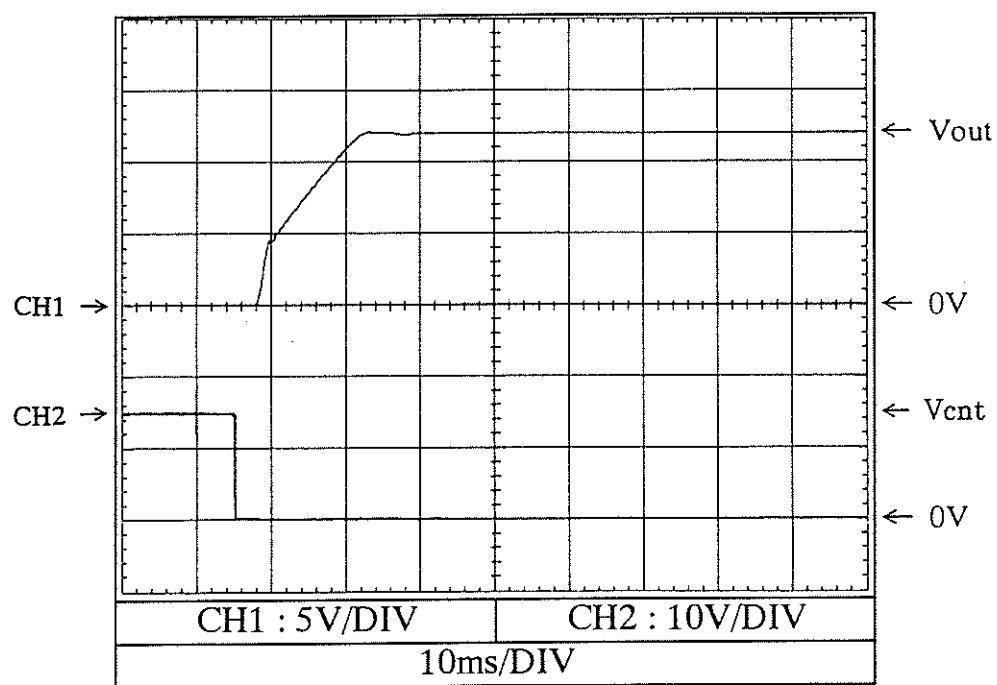
2.7 出力立ち上がり特性 (ON/OFFコントロール時)  
 Output rise characteristics with ON/OFF CONTROL

Conditions Vin : 280 VDC  
 Iout : 0 %  
 Tp : 25 °C

5V



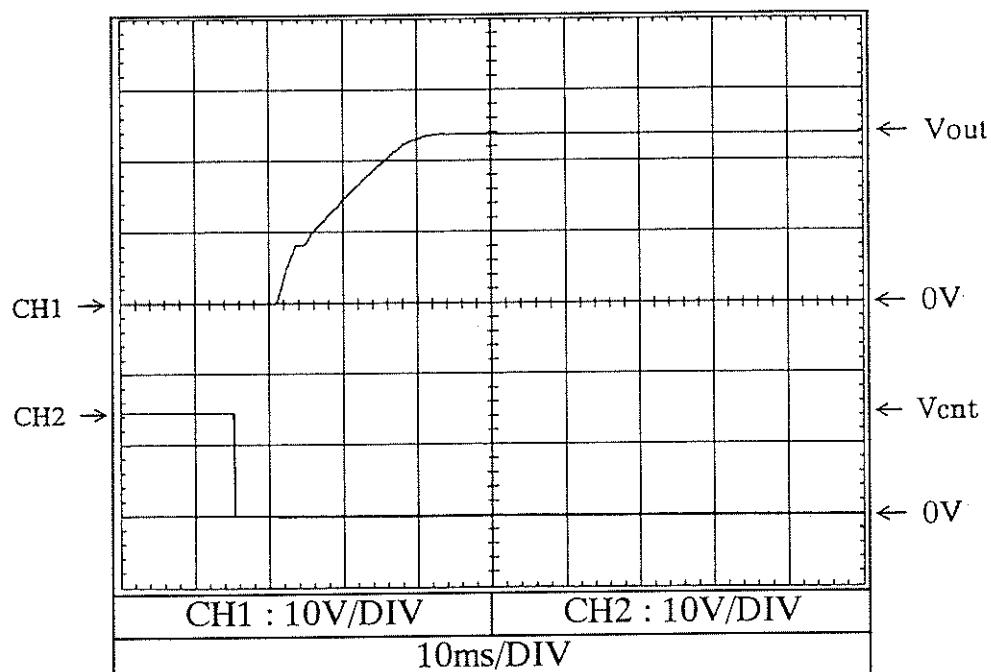
12V



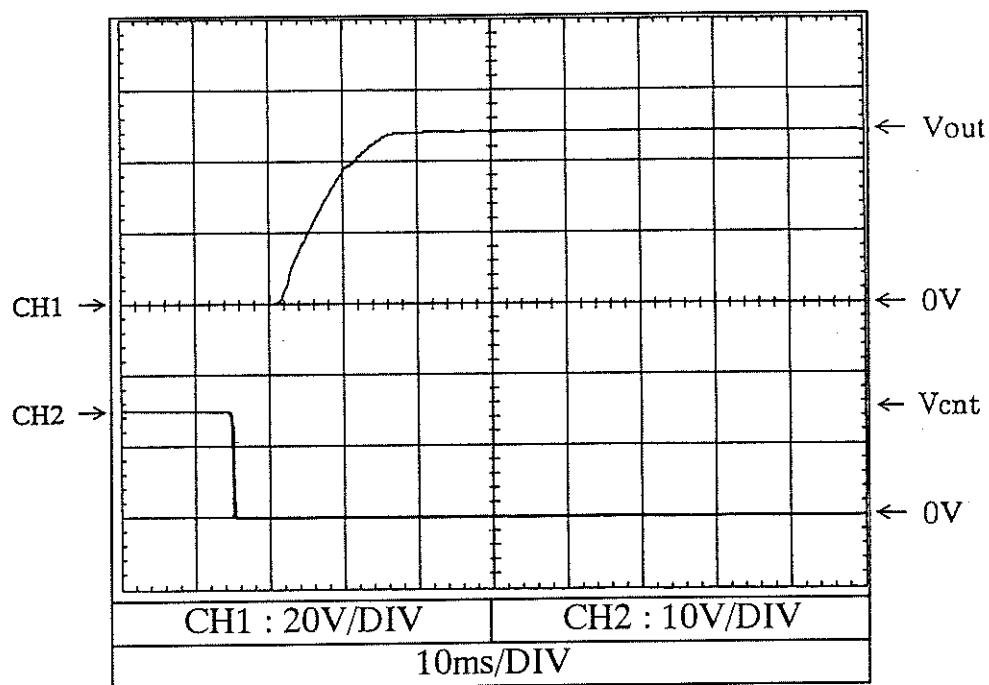
2.7 出力立ち上がり特性 (ON/OFFコントロール時)  
 Output rise characteristics with ON/OFF CONTROL

Conditions Vin : 280 VDC  
 Iout : 0 %  
 Tp : 25 °C

24V



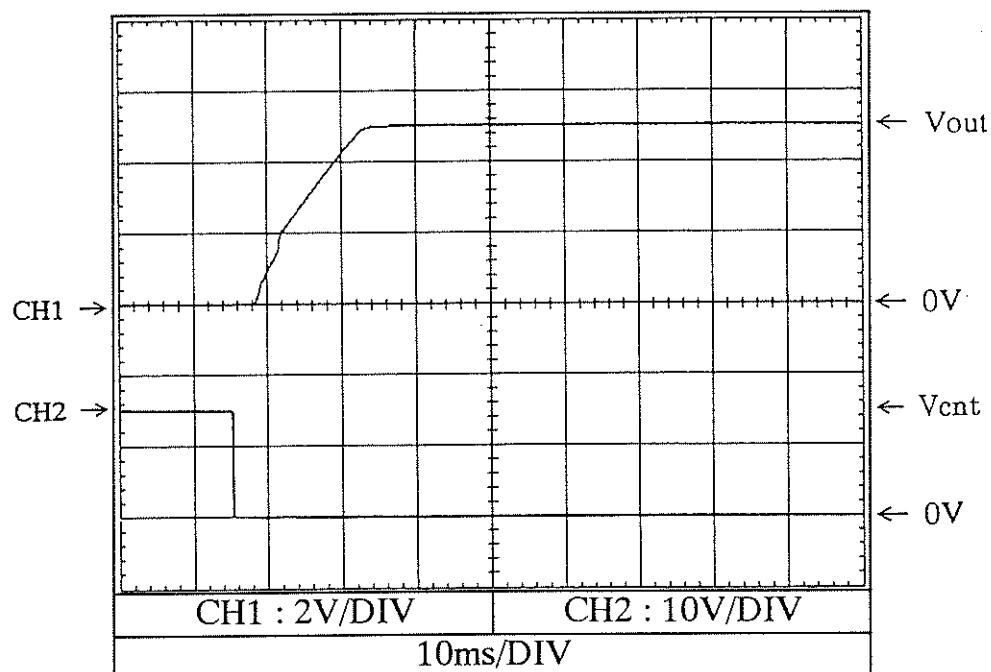
48V



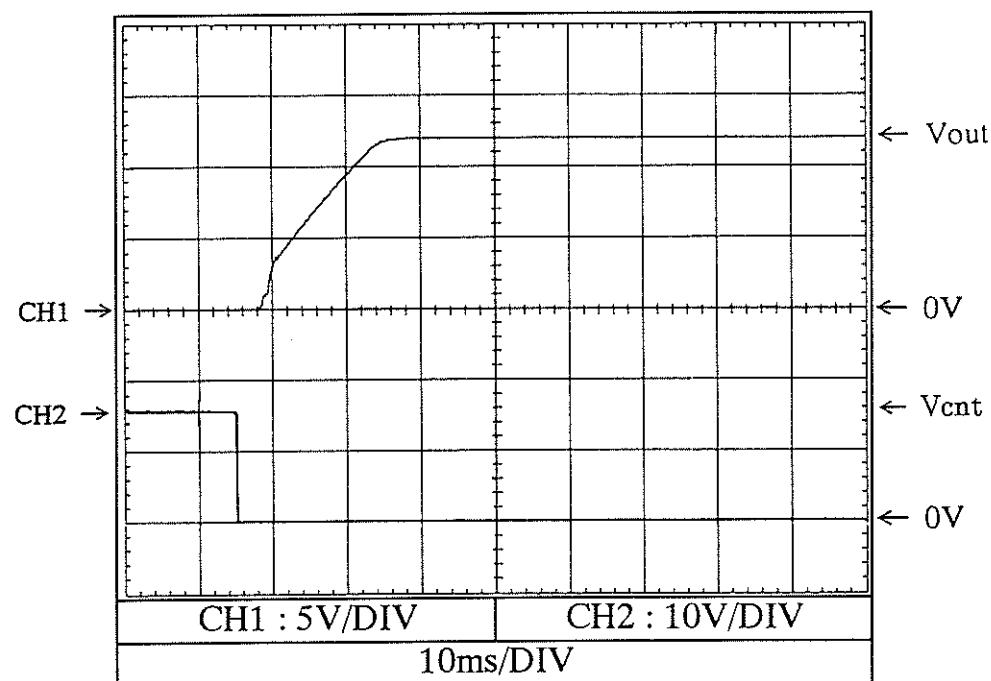
2.7 出力立ち上がり特性 (ON/OFFコントロール時)  
 Output rise characteristics with ON/OFF CONTROL

Conditions Vin : 280 VDC  
 Iout : 100 %  
 Tp : 25 °C

5V



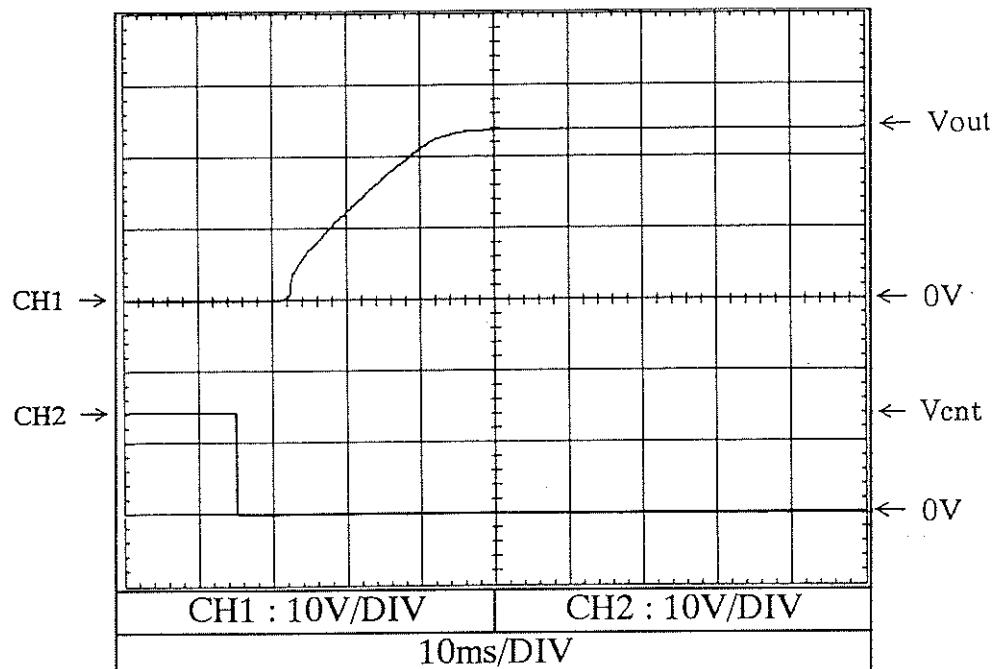
12V



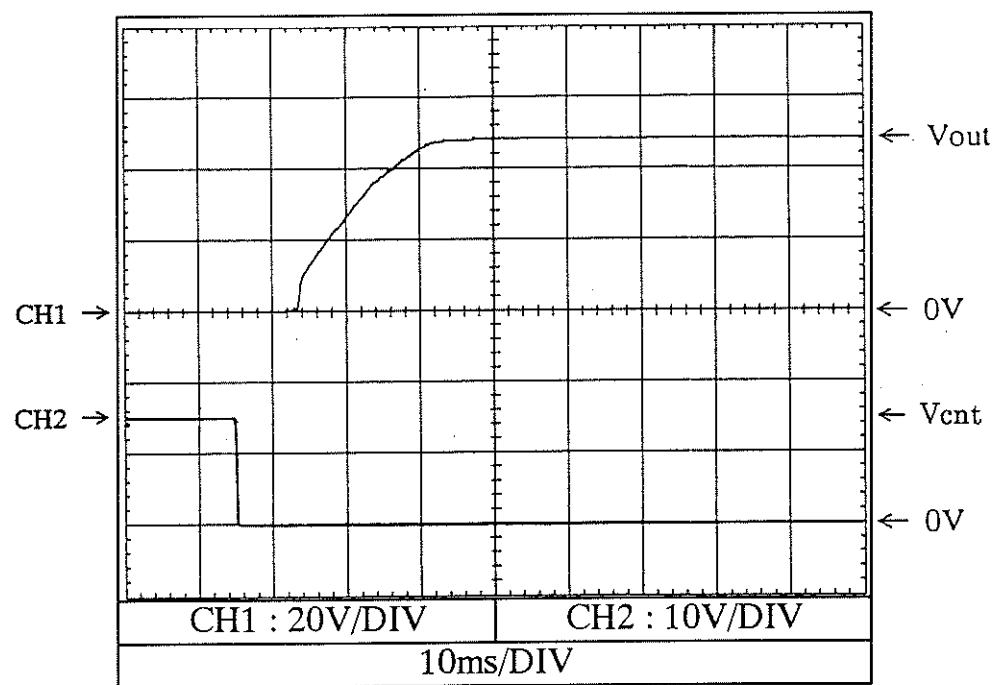
2.7 出力立ち上がり特性 (ON/OFFコントロール時)  
 Output rise characteristics with ON/OFF CONTROL

Conditions Vin : 280 VDC  
 Iout : 100 %  
 Tp : 25 °C

24V



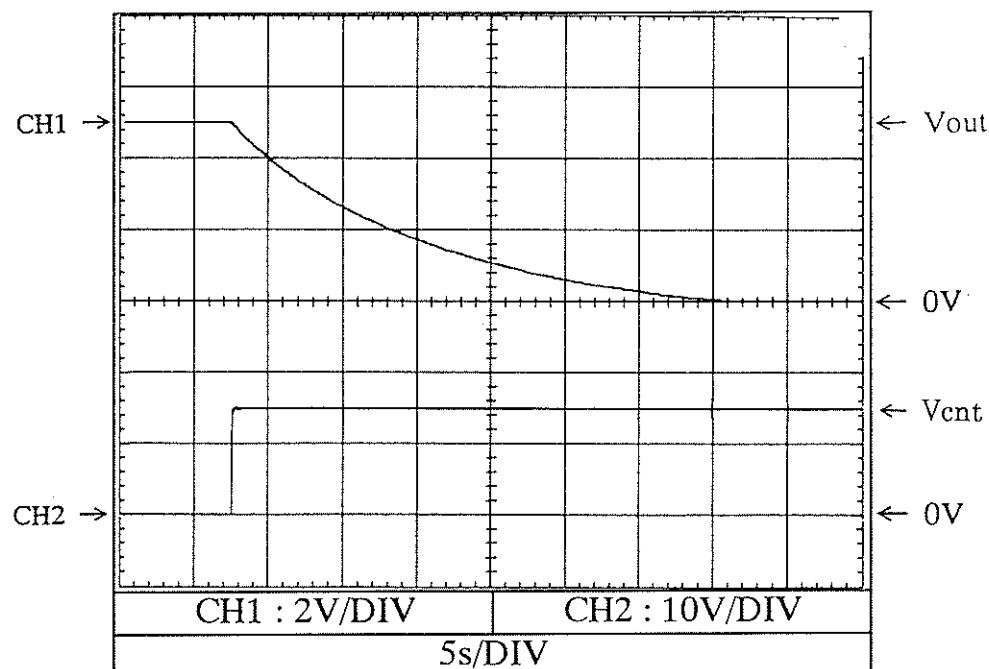
48V



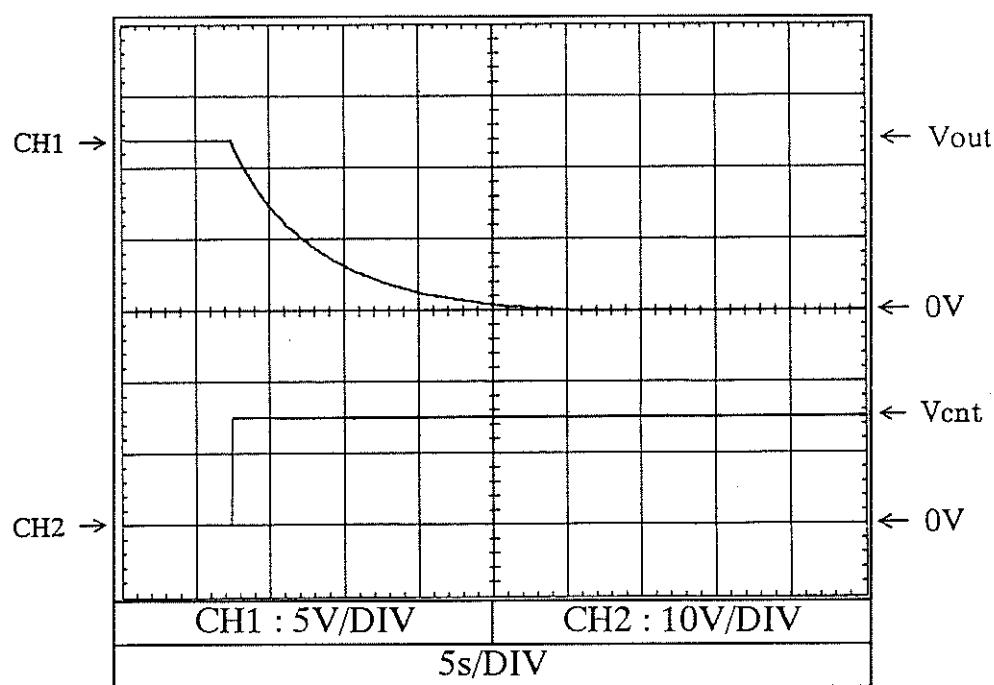
2.8 出力立ち下がり特性 (ON/OFFコントロール時)  
 Output fall characteristics with ON/OFF CONTROL

Conditions Vin : 280 VDC  
 Iout : 0 %  
 Tp : 25 °C

5V



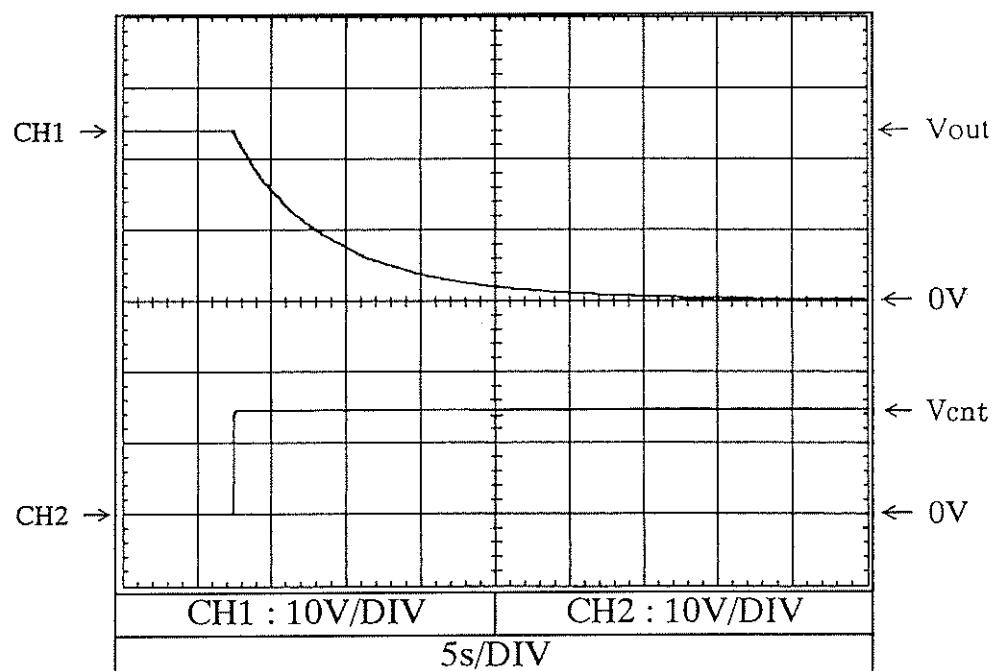
12V



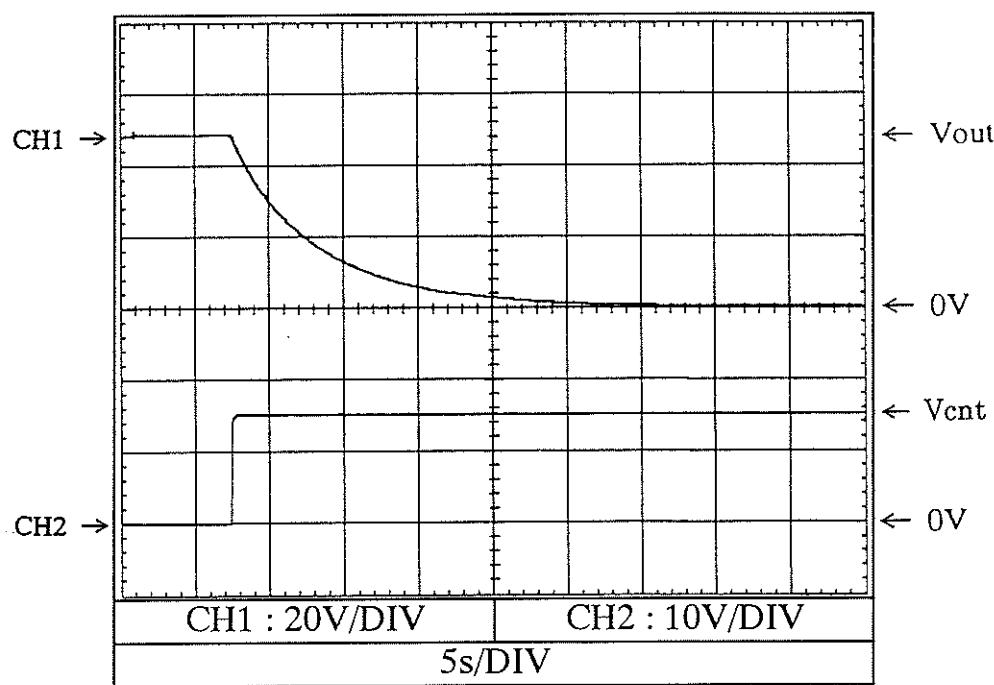
2.8 出力立ち下がり特性 (ON/OFF CONTROL時)  
 Output fall characteristics with ON/OFF CONTROL

Conditions Vin : 280 VDC  
 Iout : 0 %  
 Tp : 25 °C

24V



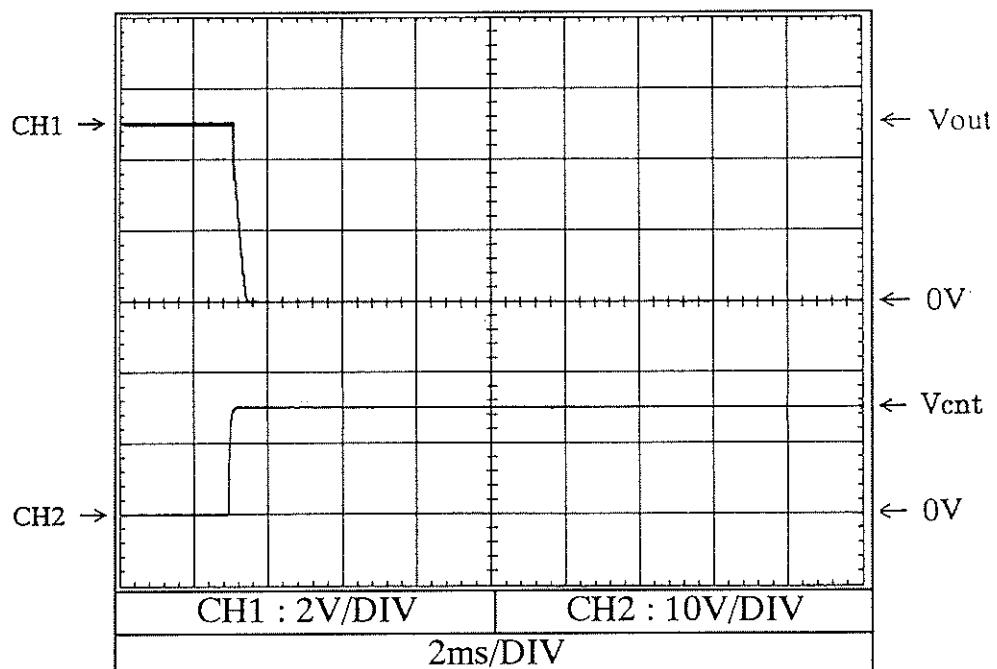
48V



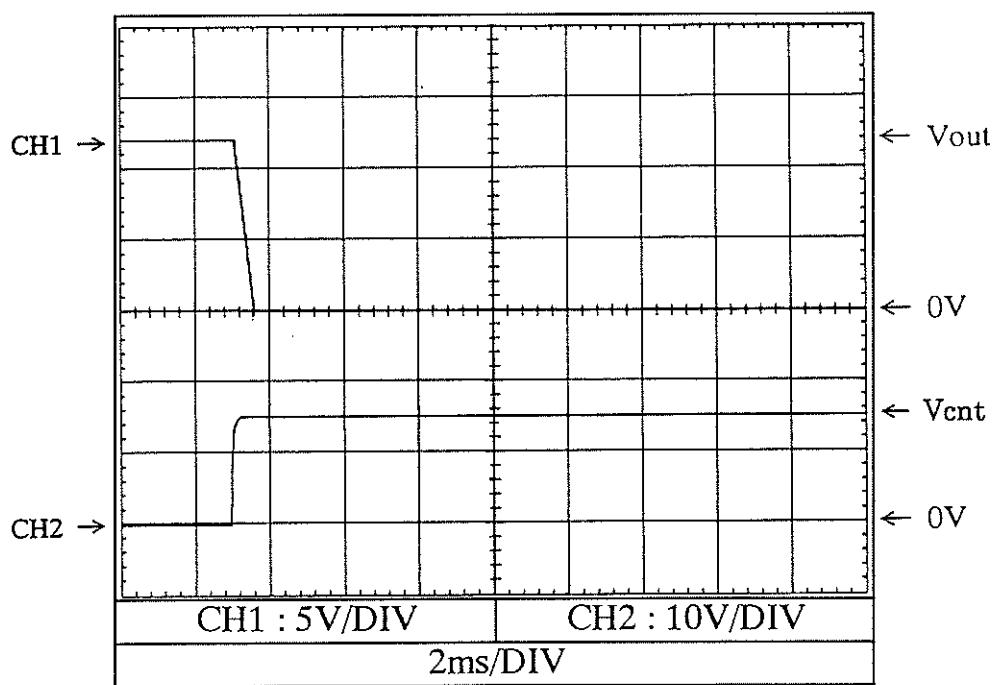
2.8 出力立ち下がり特性 (ON/OFFコントロール時)  
 Output fall characteristics with ON/OFF CONTROL

Conditions Vin : 280 VDC  
 Iout : 100 %  
 Tp : 25 °C

5V



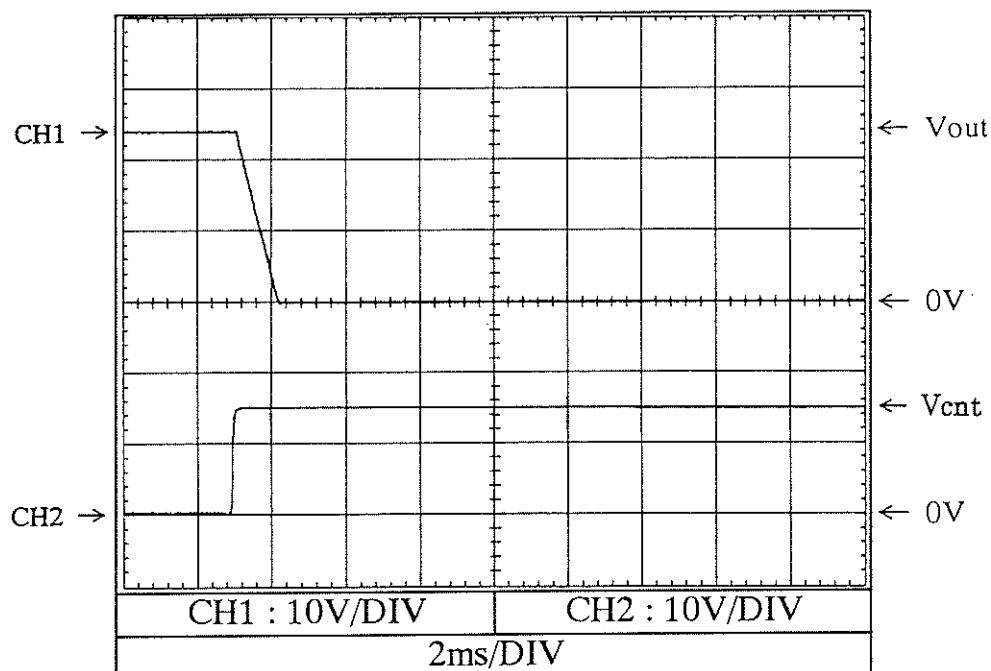
12V



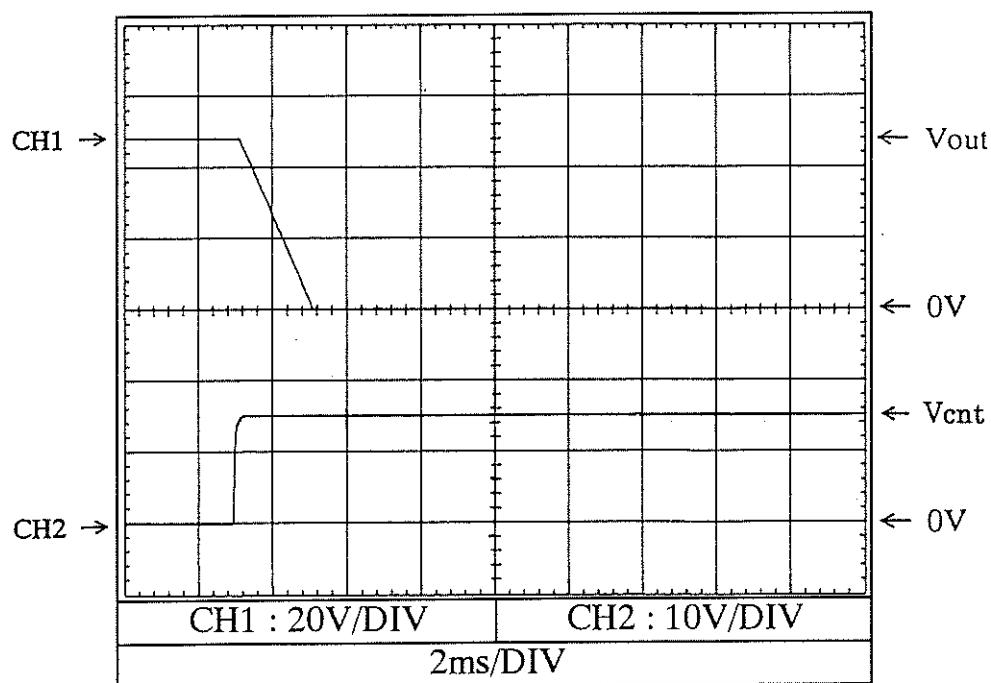
2.8 出力立ち下がり特性 (ON/OFFコントロール時)  
 Output fall characteristics with ON/OFF CONTROL

Conditions Vin : 280 VDC  
 Iout : 100 %  
 Tp : 25 °C

24V

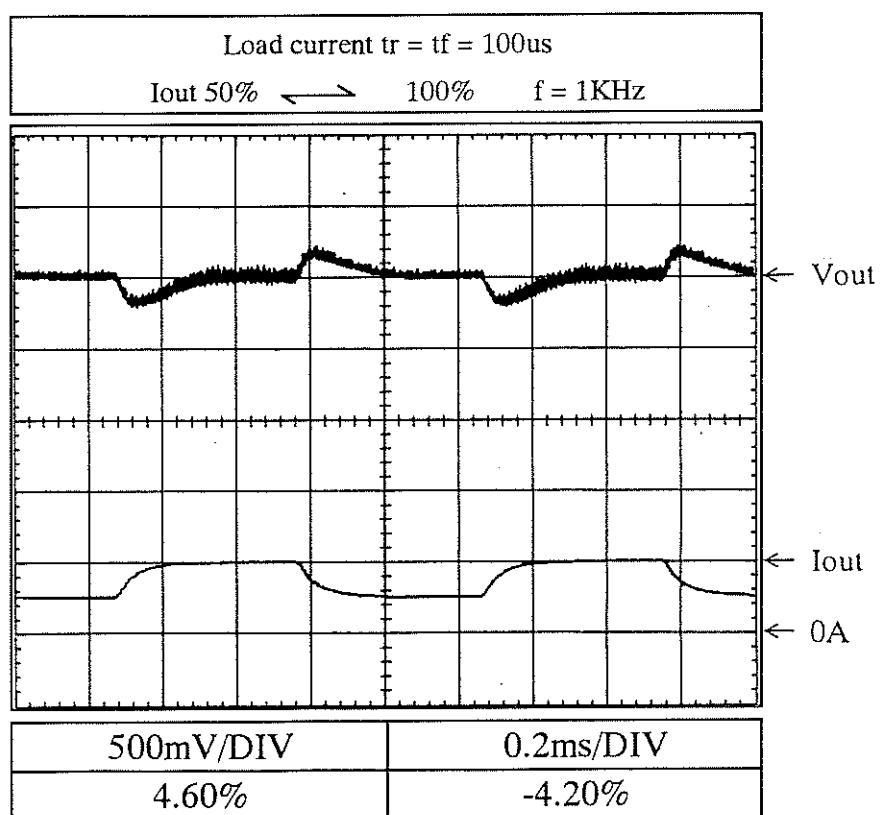
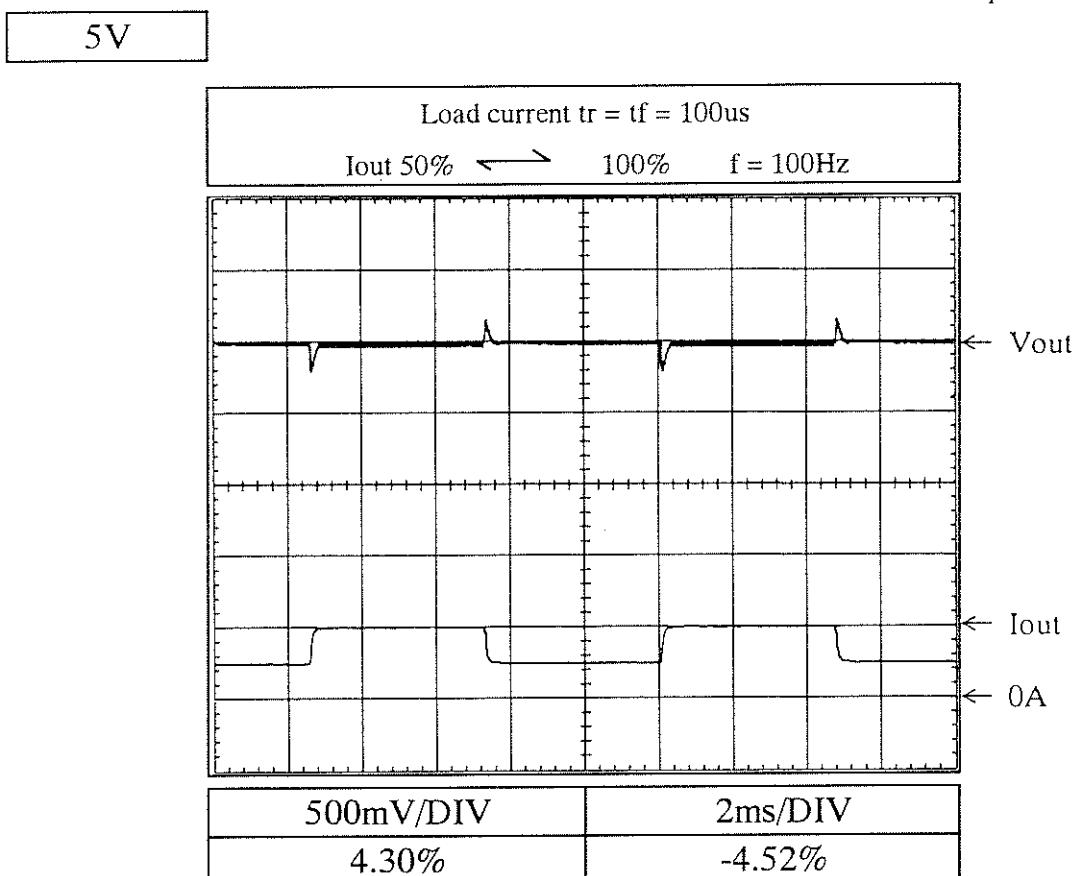


48V



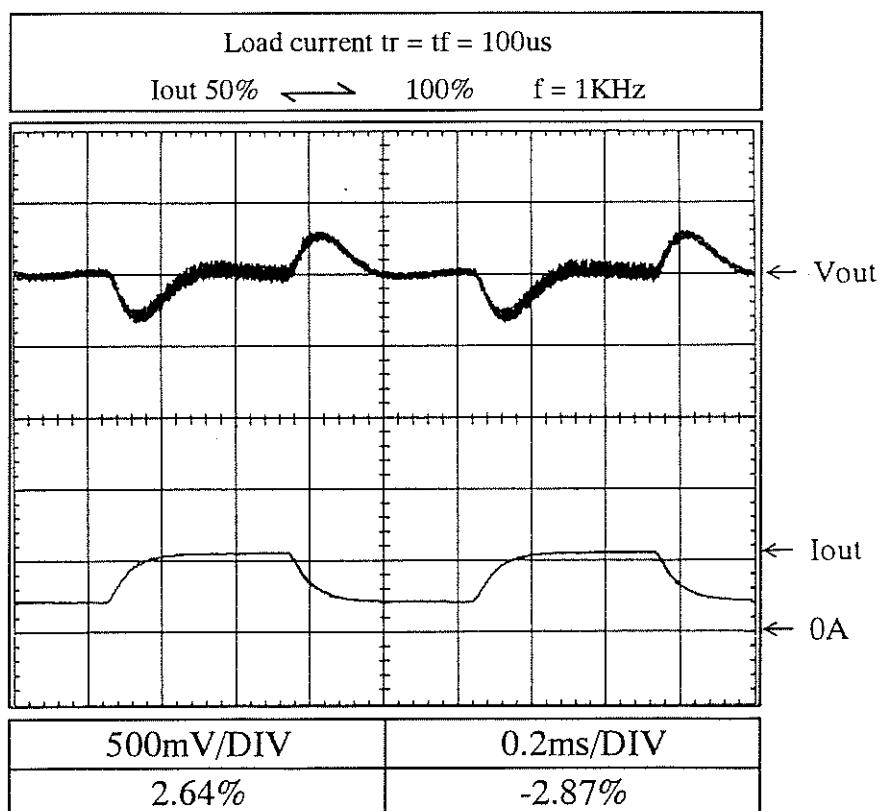
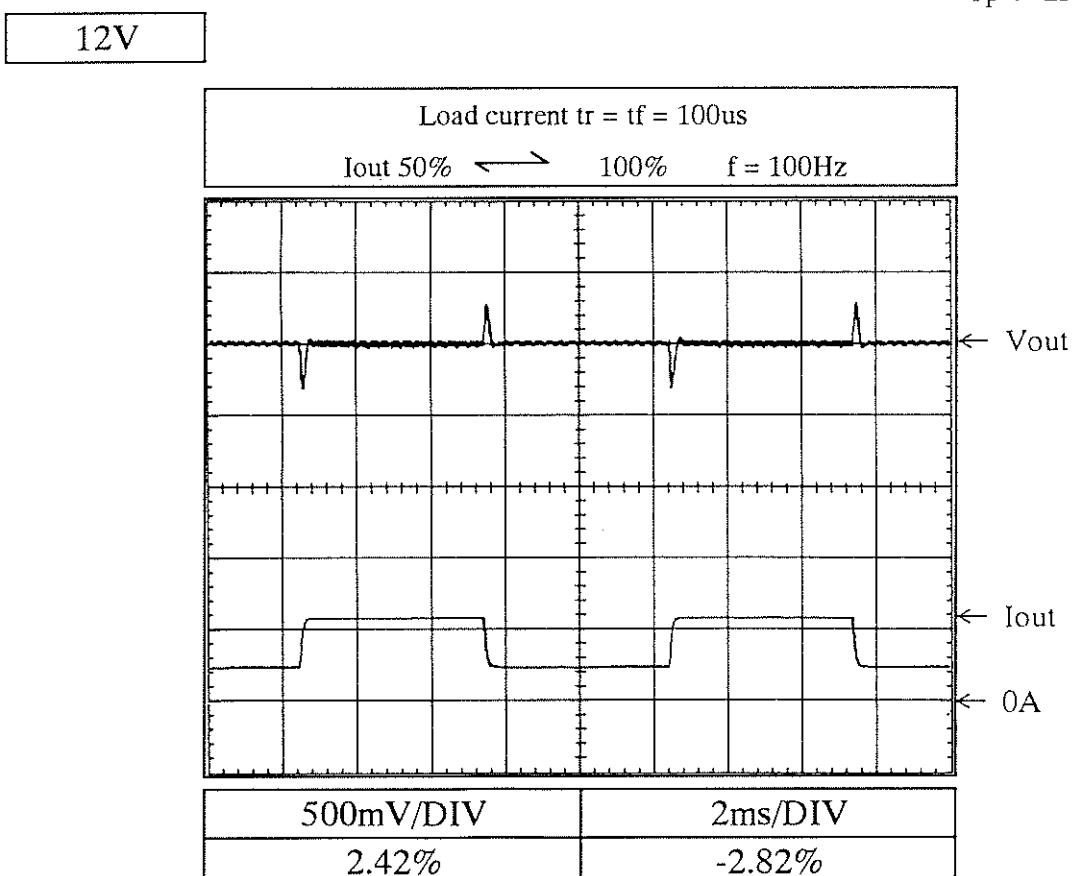
2.9 過渡応答（負荷急変）特性  
Dynamic load response characteristics

Conditions Vin : 280 VDC  
Tp : 25 °C



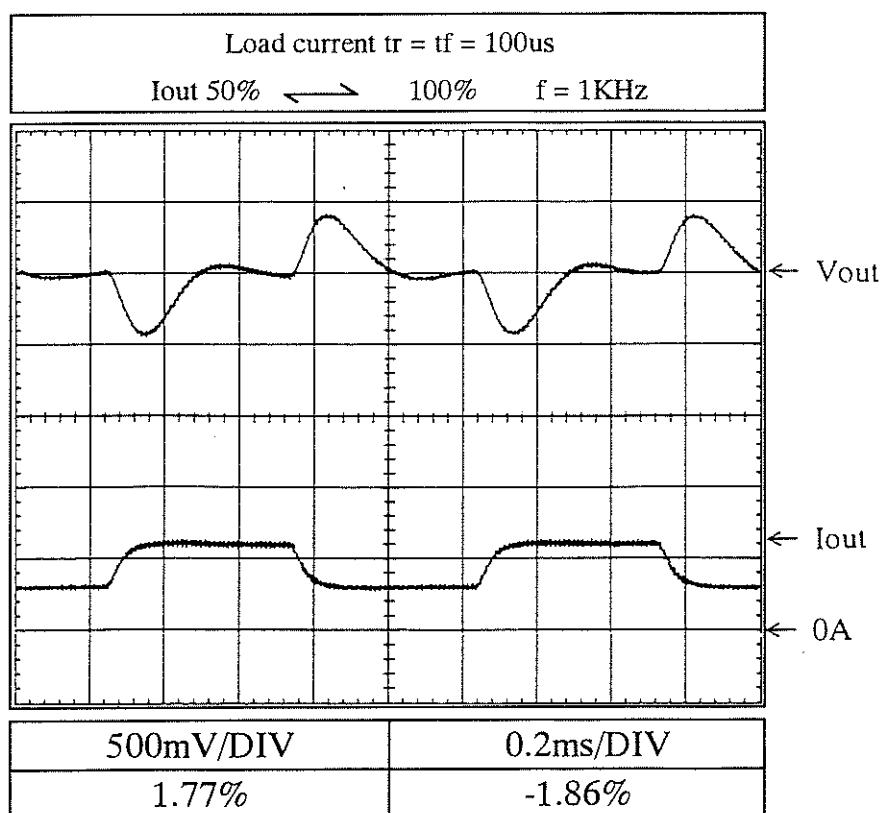
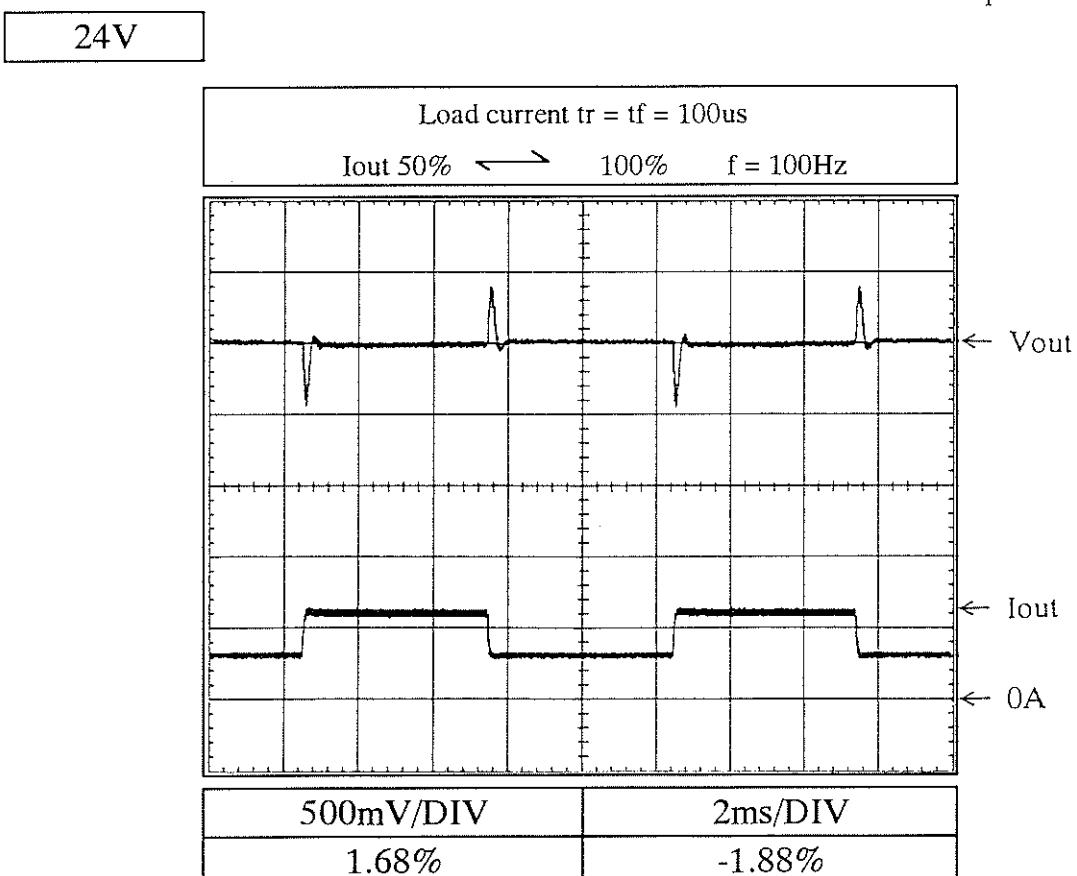
2.9 過渡応答（負荷急変）特性  
Dynamic load response characteristics

Conditions Vin : 280 VDC  
Tp : 25 °C



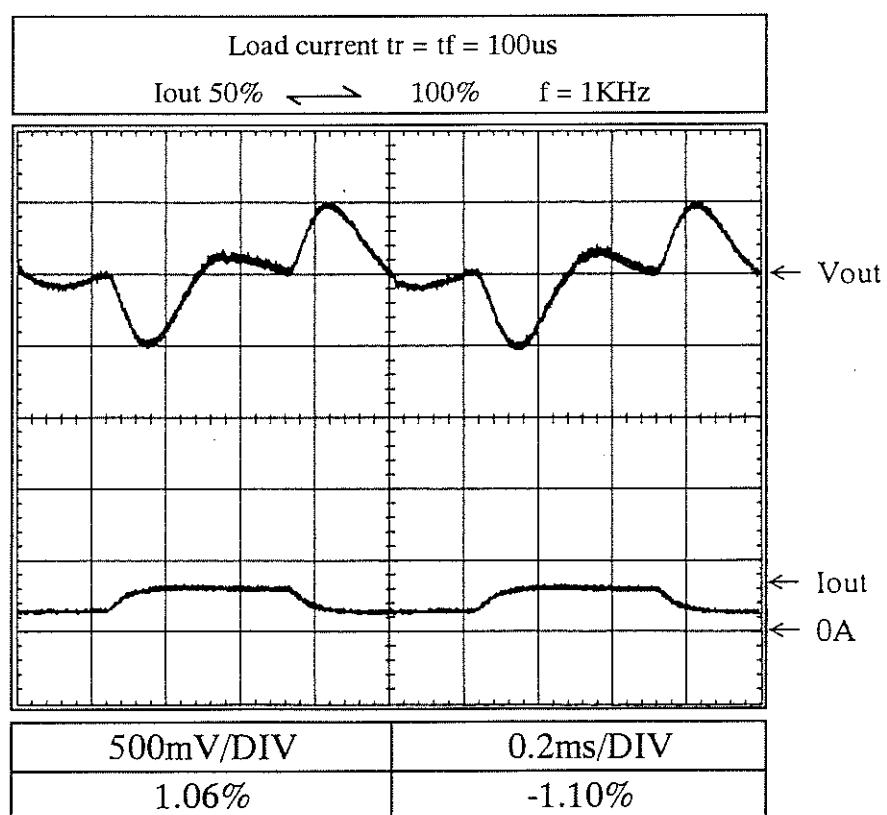
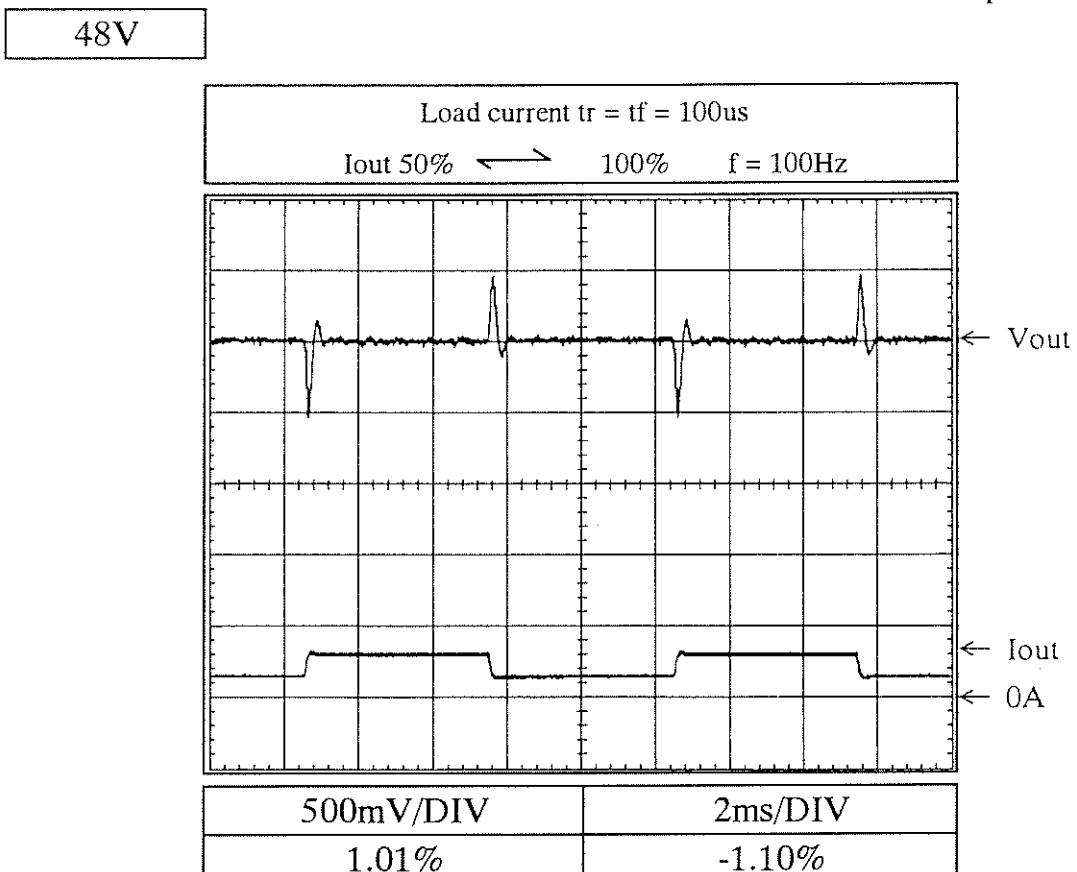
2.9 過渡応答（負荷急変）特性  
Dynamic load response characteristics

Conditions Vin : 280 VDC  
Tp : 25 °C



2.9 過渡応答（負荷急変）特性  
Dynamic load response characteristics

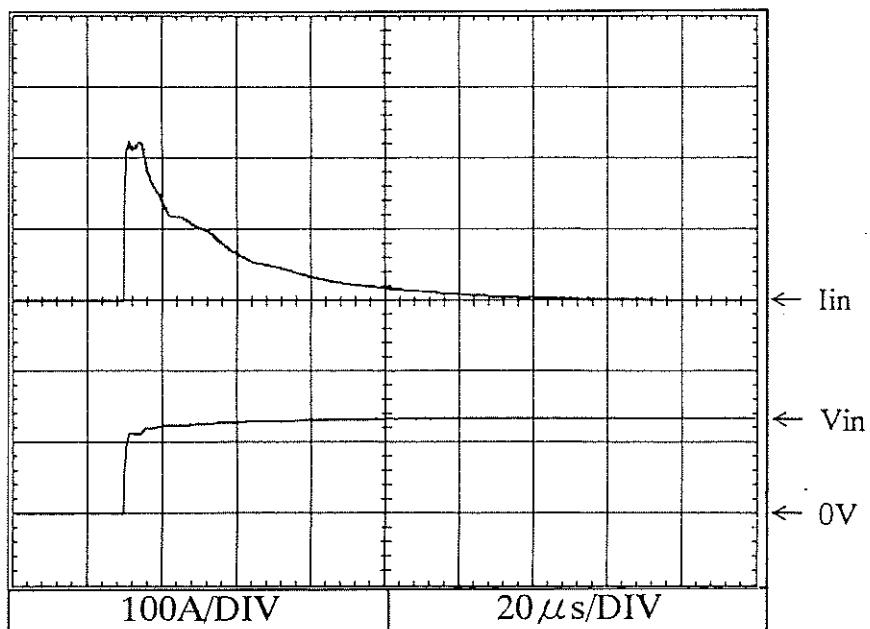
Conditions Vin : 280 VDC  
Tp : 25 °C



2.10 入力サージ電流（突入電流）特性  
Inrush current waveform

Conditions Vin : 280 VDC  
Iout : 100 %  
Tp : 25 °C

5V



2.11 出力リップル、ノイズ波形  
Output ripple and noise waveform

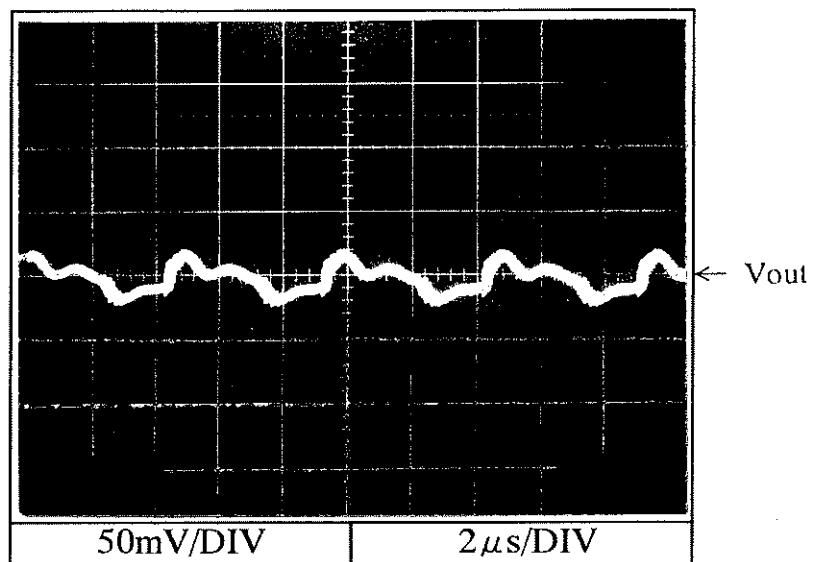
5V

Conditions Vin : 280 VDC

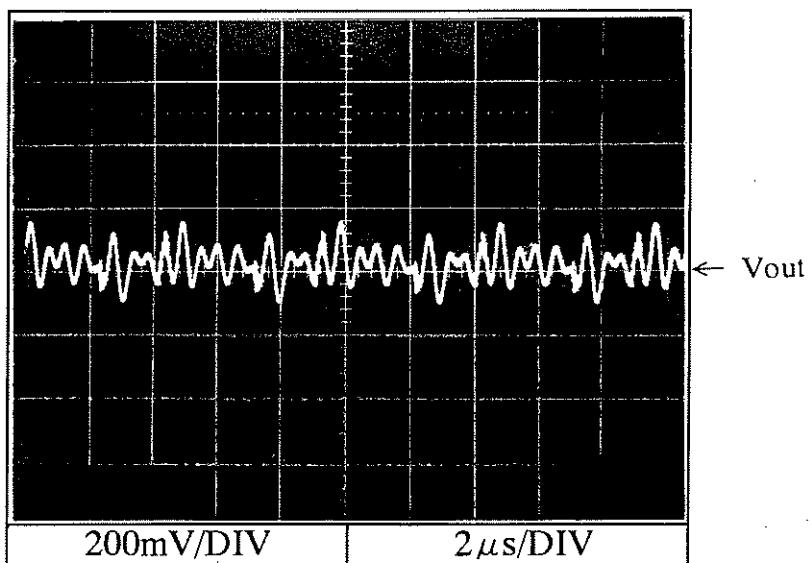
Iout : 100 %

T<sub>p</sub> : 25 °C

NORMAL MODE



NORMAL + COMMON MODE

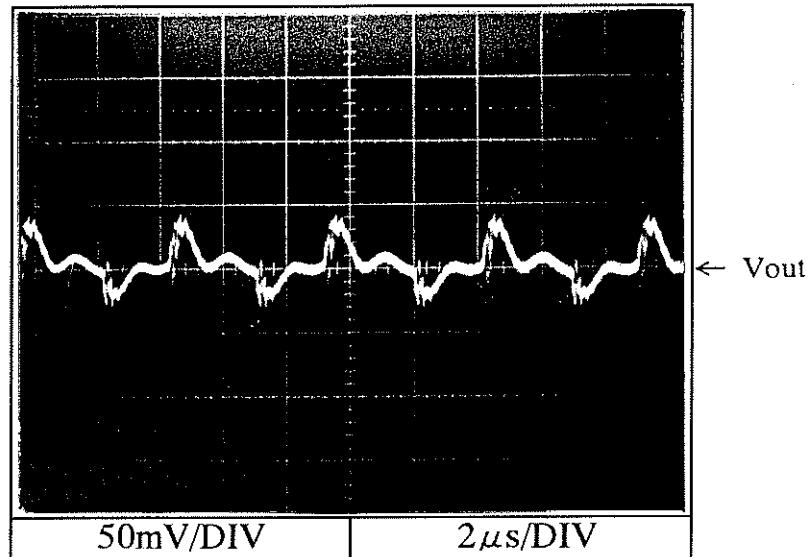


2.11 出力リップル、ノイズ波形  
Output ripple and noise waveform

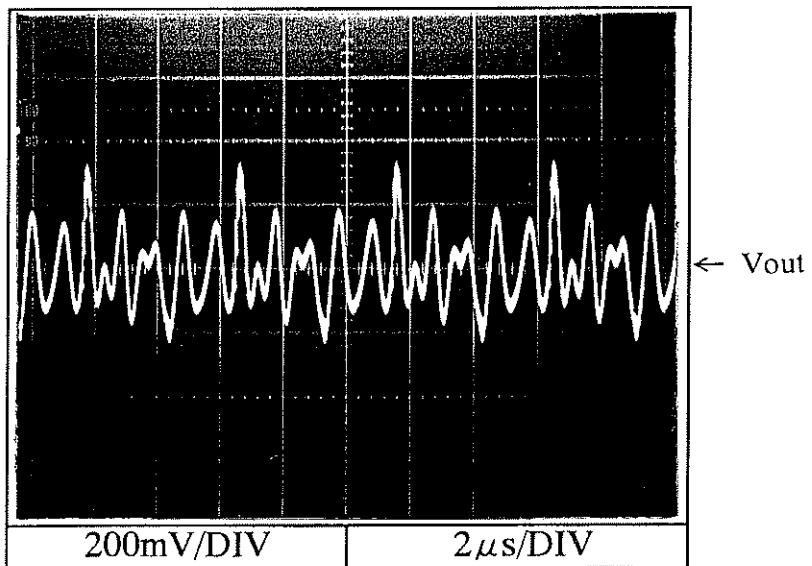
12V

Conditions Vin : 280 VDC  
Iout : 100 %  
Tp : 25 °C

NORMAL MODE



NORMAL + COMMON MODE



2.11 出力リップル、ノイズ波形  
Output ripple and noise waveform

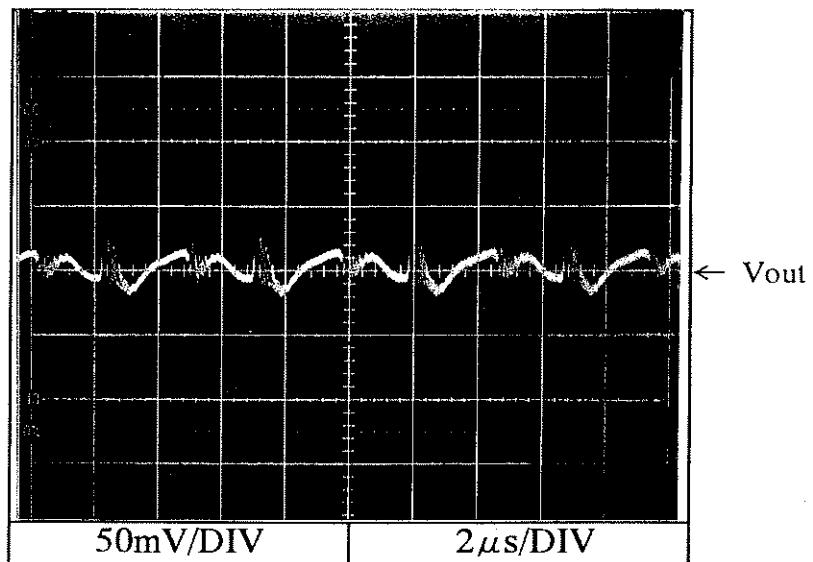
24V

Conditions Vin : 280 VDC

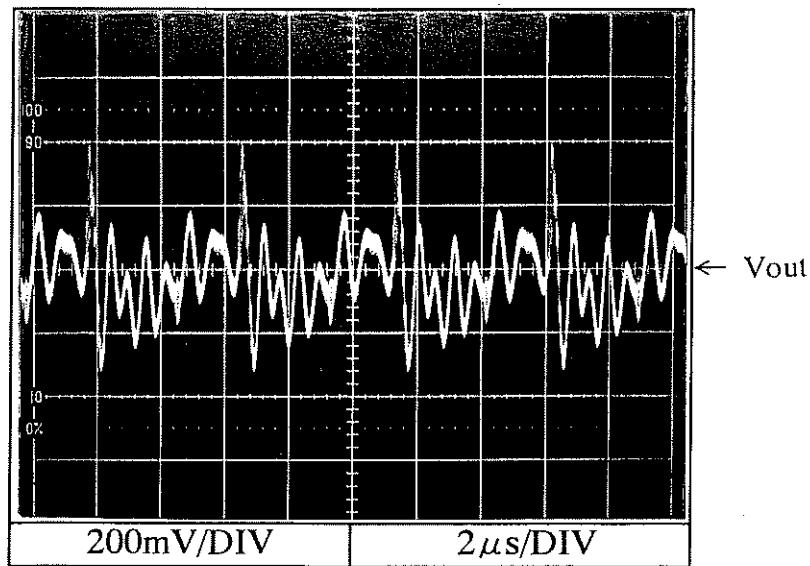
Iout : 100 %

T<sub>p</sub> : 25 °C

NORMAL MODE



NORMAL + COMMON MODE



2.11 出力リップル、ノイズ波形  
Output ripple and noise waveform

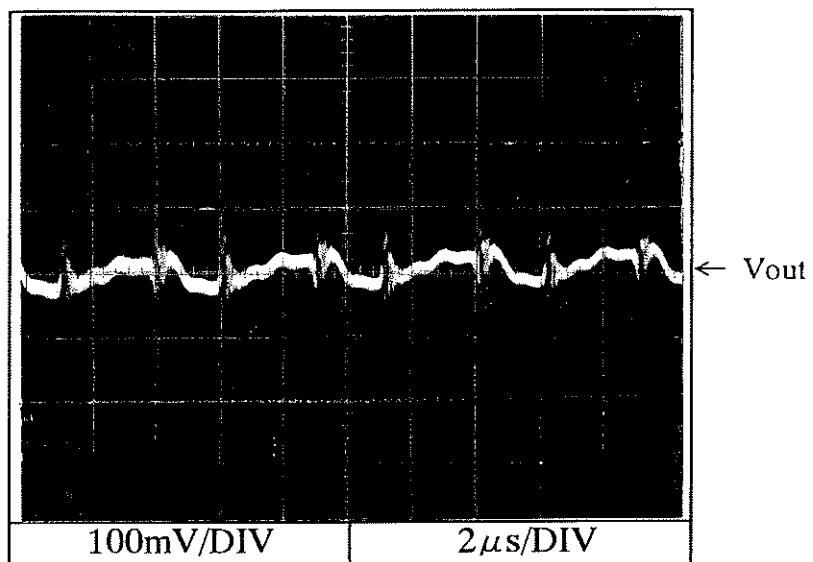
48V

Conditions Vin : 280 VDC

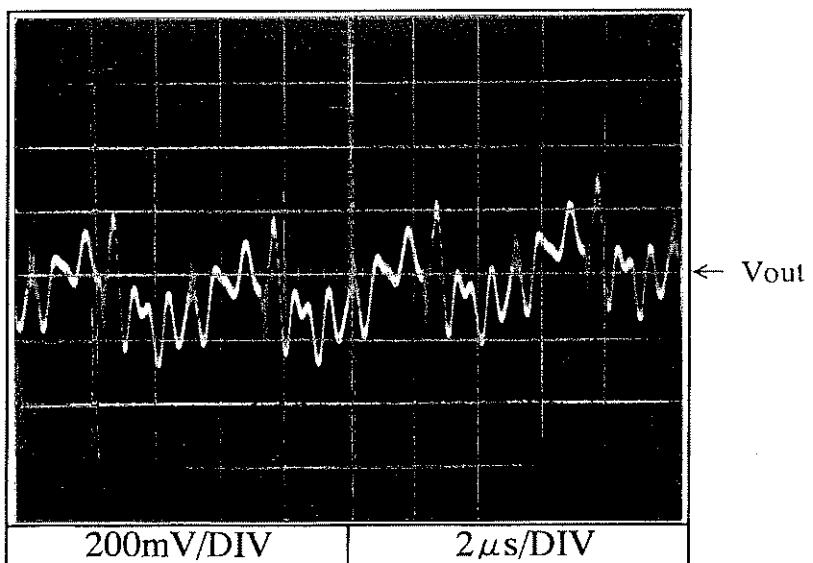
Iout : 100 %

T<sub>p</sub> : 25 °C

NORMAL MODE



NORMAL + COMMON MODE



## 2.12 EMI特性

Electro-Magnetic Interference characteristics

(a) 雜音端子電圧 (帰還ノイズ)

Conditions

Vin : 280 VDC

Conducted Emission Noise

Iout : 100 %

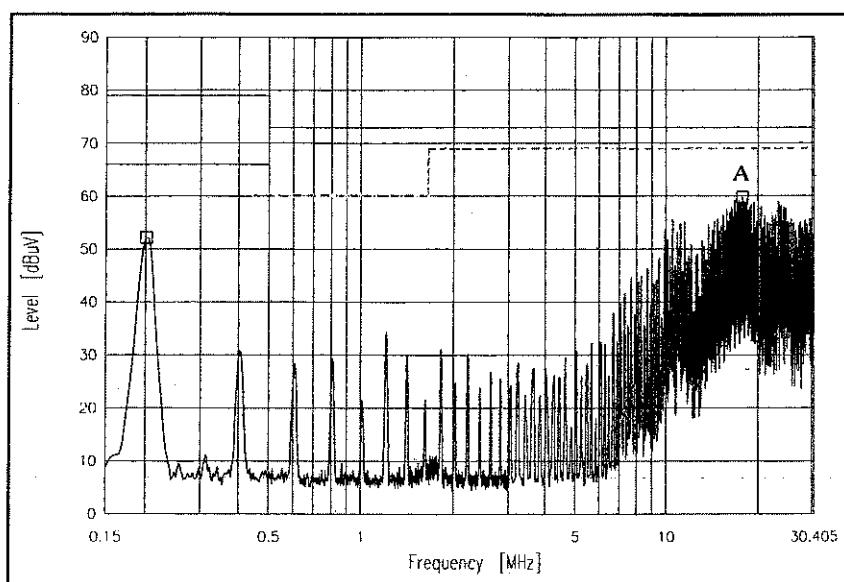
(1) VCCI class A 対応アプリケーションシステム

Tp : 25 °C

VCCI class A application system

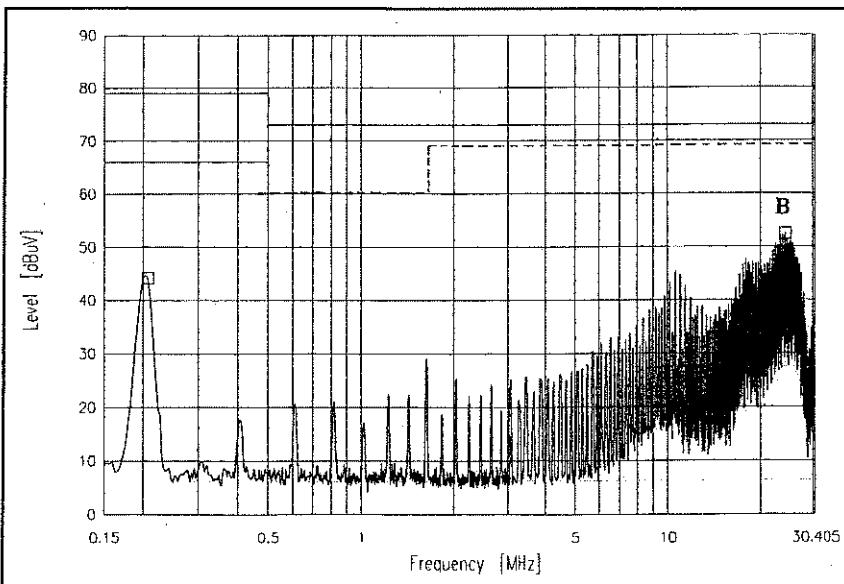
5V

Point A (17.743MHz)		
Ref.	Data	Limit
	(dBuV)	(dBuV)
QP	73.0	58.5
AV	60.0	56.9



12V

Point B (24.182MHz)		
Ref.	Data	Limit
	(dBuV)	(dBuV)
QP	73.0	51.4
AV	60.0	49.9



NEMIC-LAMBDA

## 2.12 EMI特性

Electro-Magnetic Interference characteristics

(a) 雑音端子電圧 (帰還ノイズ)

Conditions Vin : 280 VDC

Conducted Emission Noise

Iout : 100 %

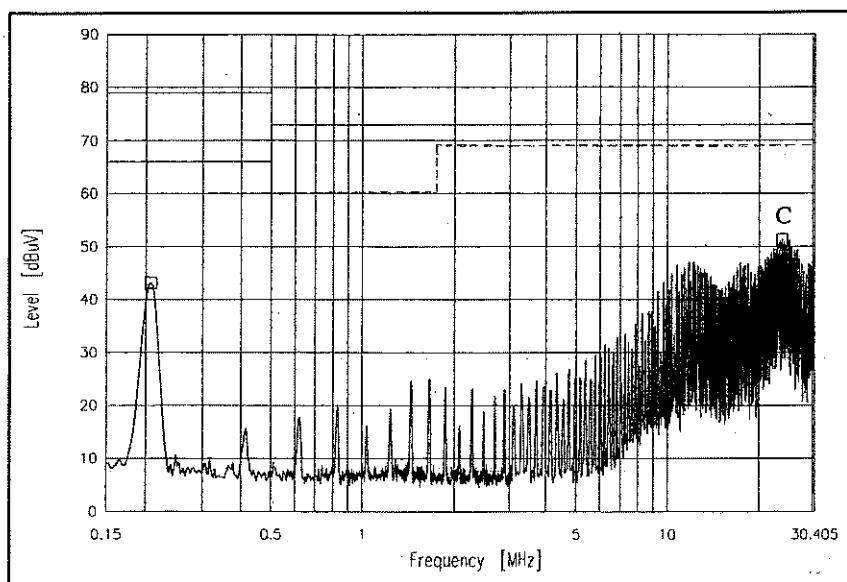
(1) VCCI class A 対応アプリケーションシステム

Tp : 25 °C

VCCI class A application system

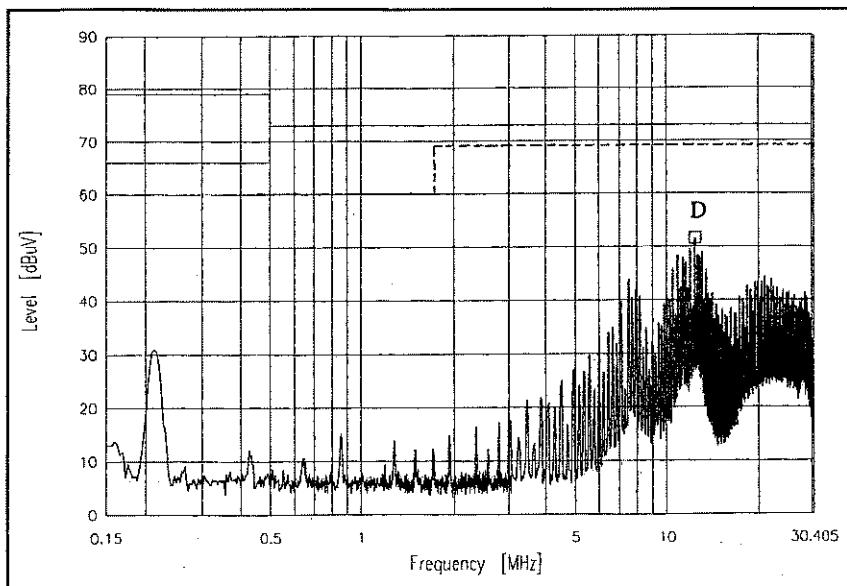
24V

Point C (23.739MHz)			
Ref.	Data	Limit (dBuV)	Measure (dBuV)
QP	73.0	51.1	
AV	60.0	49.8	



48V

Point D (12.367MHz)			
Ref.	Data	Limit (dBuV)	Measure (dBuV)
QP	73.0	50.6	
AV	60.0	50.6	



## 2.12 EMI特性

Electro-Magnetic Interference characteristics

(b) 雜音電界強度（輻射ノイズ）

Conditions Vin : 280 VDC

Radiated Emission Noise

Iout : 100 %

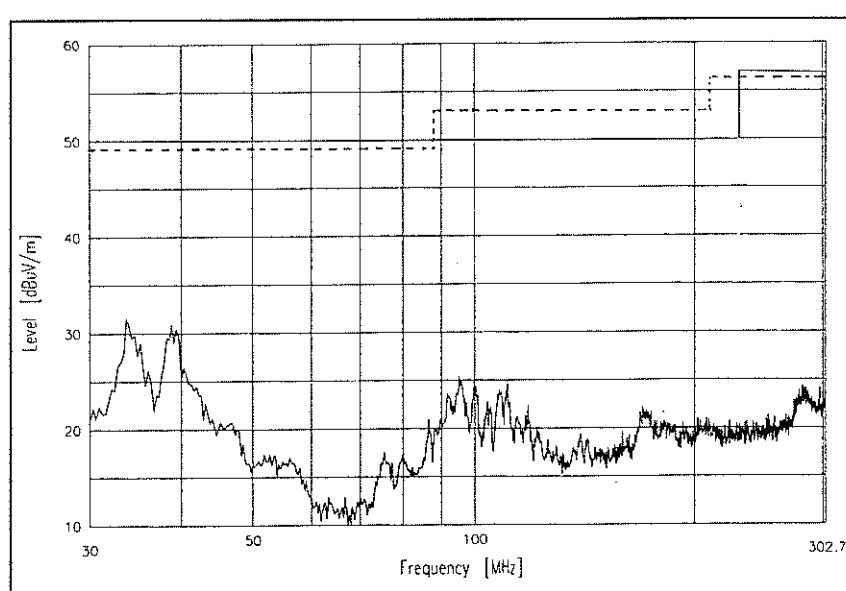
(1) VCCI class A 対応アプリケーションシステム

Tp : 25 °C

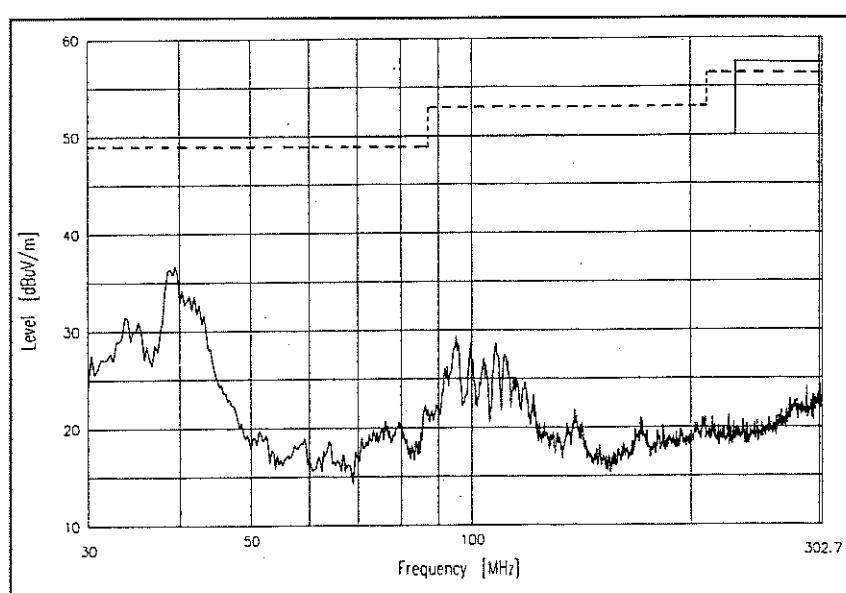
VCCI class A application system

5V

HORIZONTAL:



VERTICAL:



## 2.12 EMI特性

Electro-Magnetic Interference characteristics

(b) 雜音電界強度（輻射ノイズ）

Radiated Emission Noise

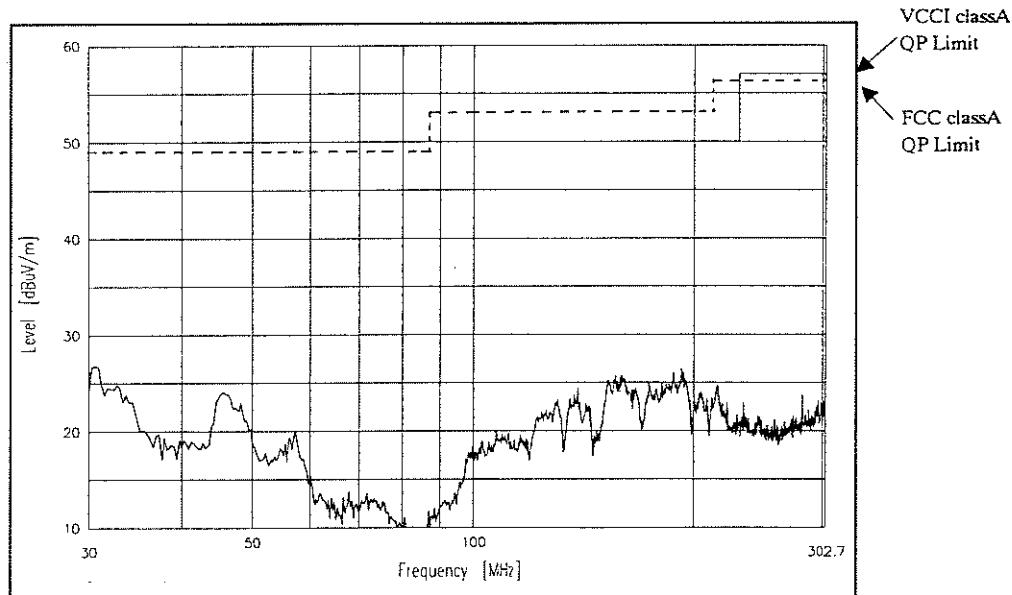
(1) VCCI class A 対応アプリケーションシステム

VCCI class A application system

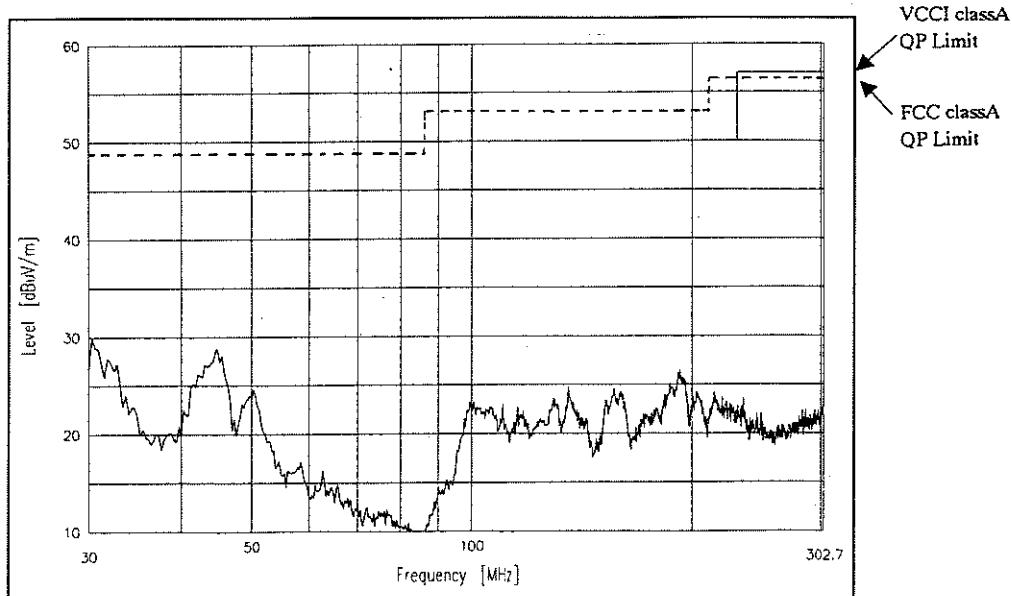
Conditions  
 Vin : 280 VDC  
 Iout : 100 %  
 Tp : 25 °C

12V

HORIZONTAL:



VERTICAL:



NEMIC-LAMBDA

## 2.12 EMI特性

Electro-Magnetic Interference characteristics

(b) 雜音電界強度（輻射ノイズ）

Conditions Vin : 280 VDC

Radiated Emission Noise

Iout : 100 %

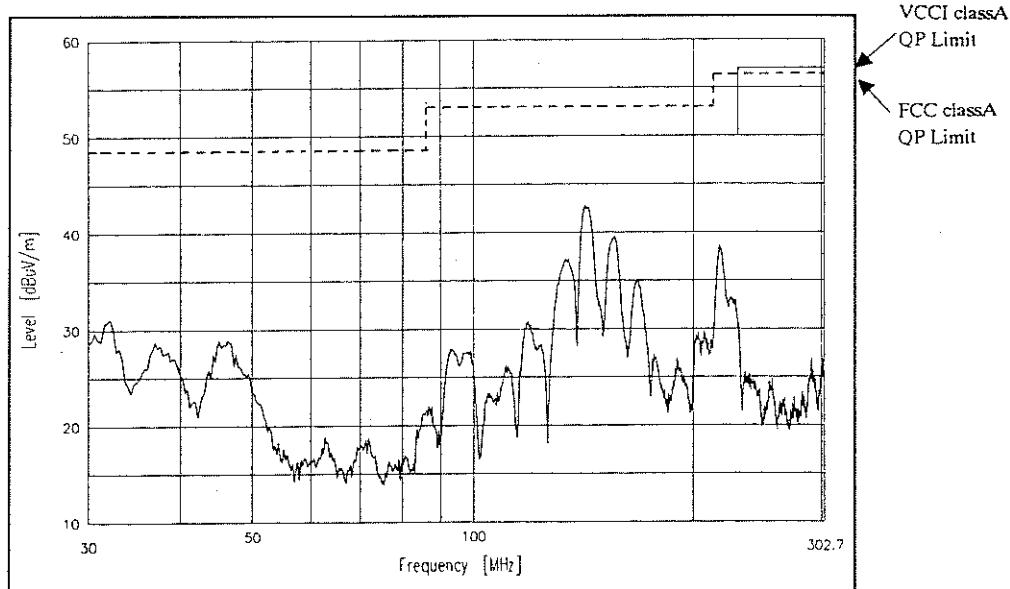
(1) VCCI class A 対応アプリケーションシステム

Tp : 25 °C

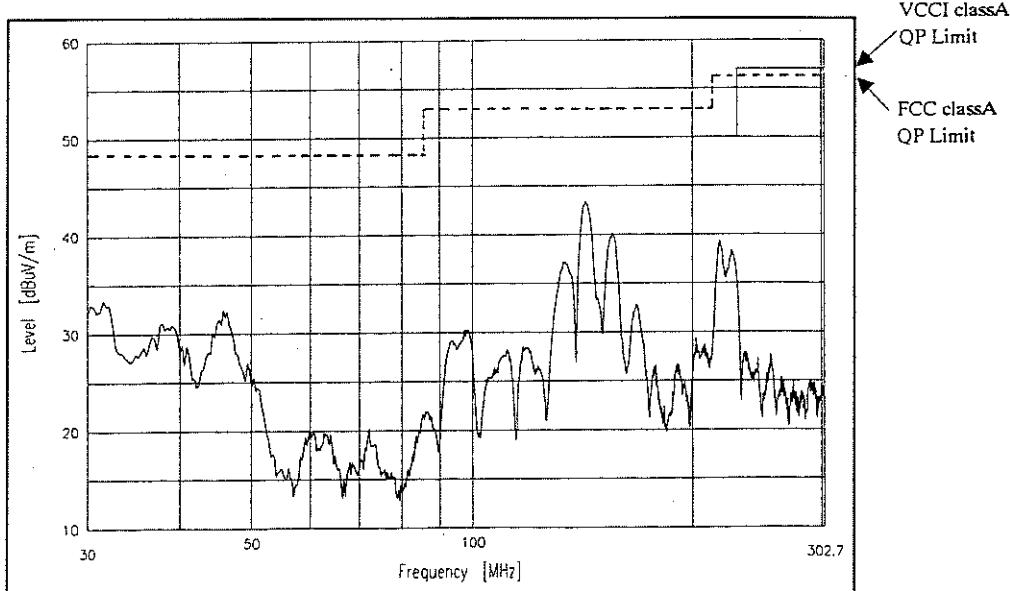
VCCI class A application system

24V

HORIZONTAL:



VERTICAL:



NEMIC-LAMBDA

## 2.12 EMI特性

Electro-Magnetic Interference characteristics

(b) 雜音電界強度（輻射ノイズ）

Radiated Emission Noise

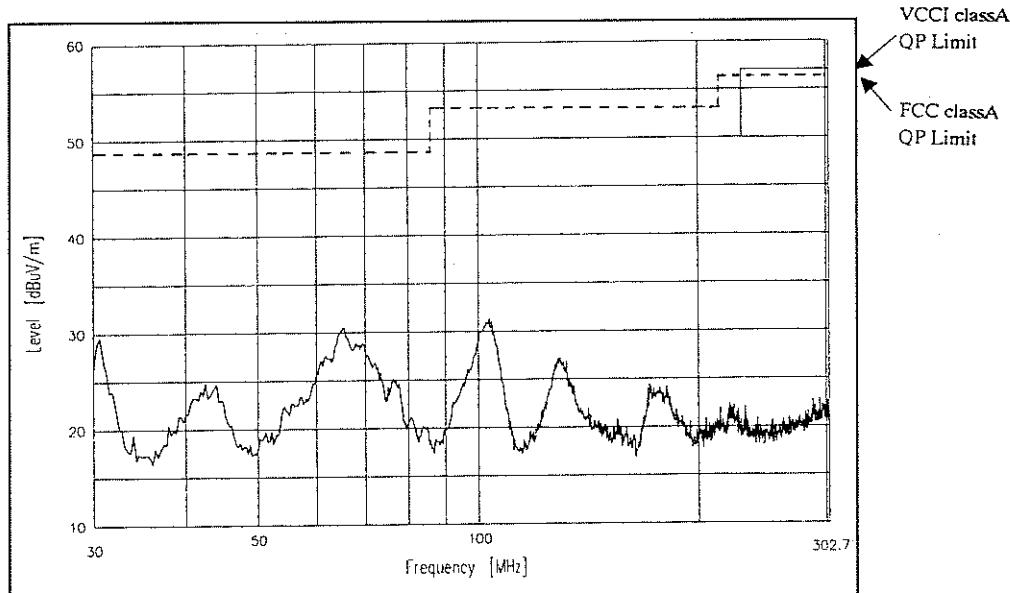
(1) VCCI class A 対応アプリケーションシステム

VCCI class A application system

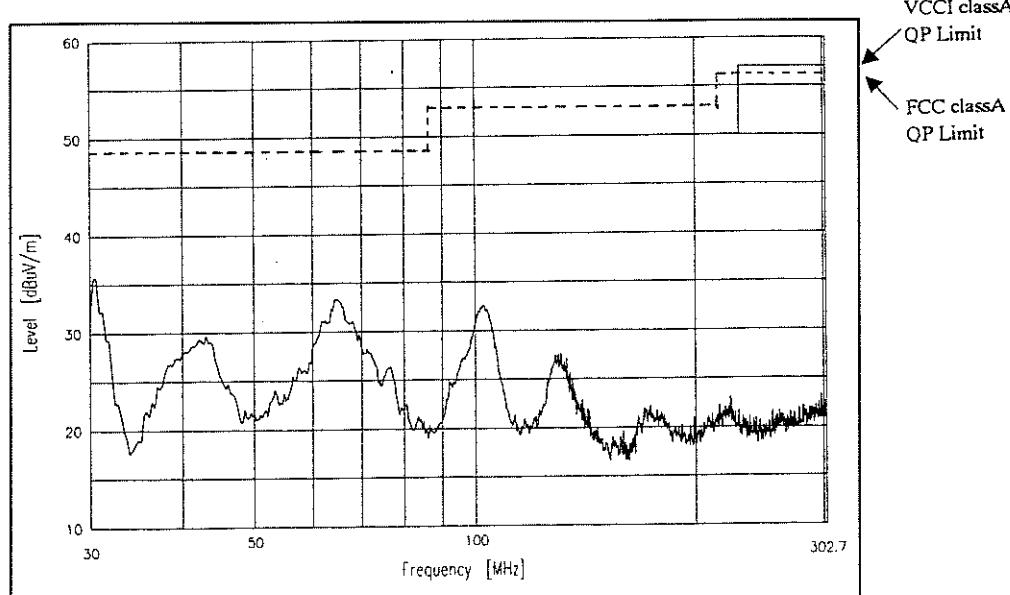
Conditions  
 Vin : 280 VDC  
 Iout : 100 %  
 Tp : 25 °C

48V

HORIZONTAL:



VERTICAL:



NEMIC-LAMBDA

## 2.12 EMI特性

Electro-Magnetic Interference characteristics

(a) 雑音端子電圧 (帰還ノイズ)

Conducted Emission Noise

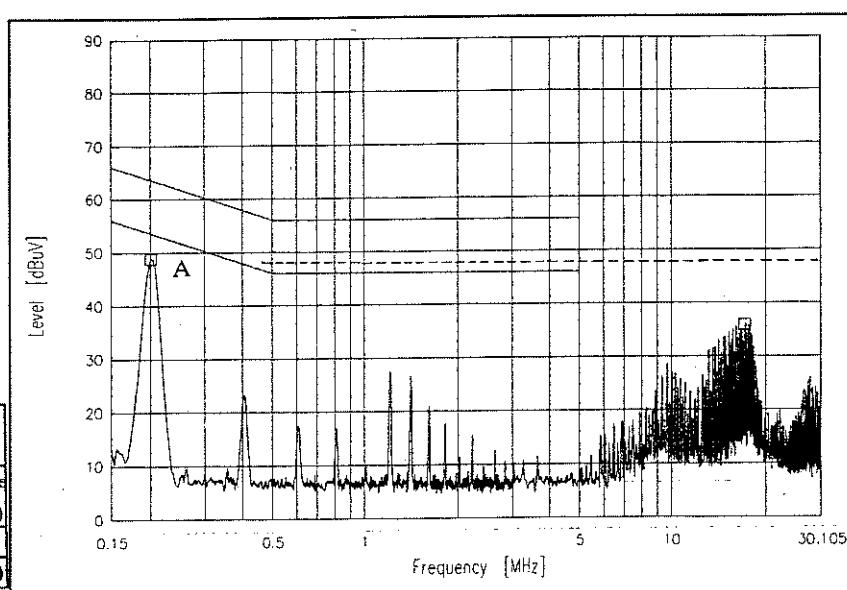
(2) VCCI class B 対応アプリケーションシステム

VCCI class B application system

Conditions  
 Vin : 280 VDC  
 Iout : 100 %  
 Tp : 25 °C

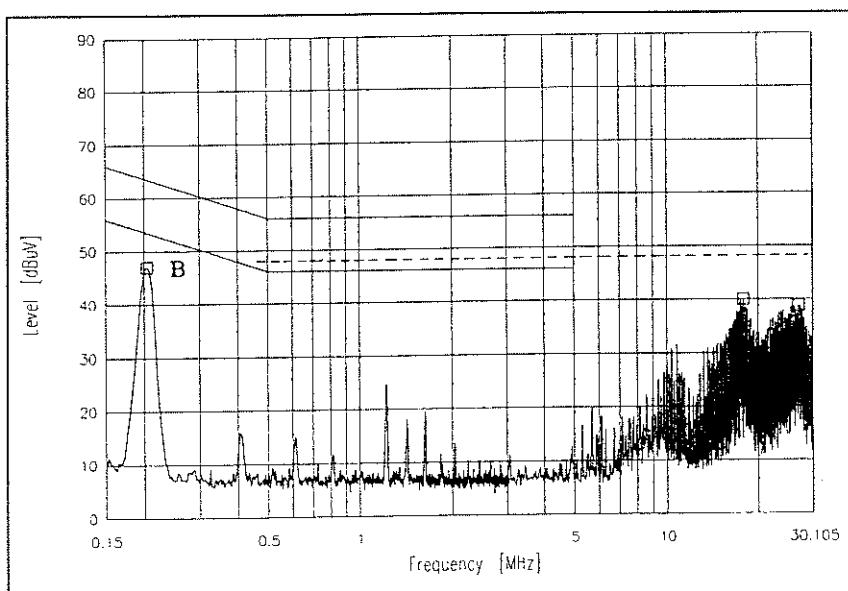
5V

Point A (202kHz)			
Ref.	Data	Limit (dBuV)	Measure (dBuV)
QP	63.5	48.1	
AV	53.5	48.0	



12V

Point B (203kHz)			
Ref.	Data	Limit (dBuV)	Measure (dBuV)
QP	63.5	46.8	
AV	53.5	46.6	



## 2.12 EMI特性

Electro-Magnetic Interference characteristics

(a) 雑音端子電圧 (帰還ノイズ)

Conducted Emission Noise

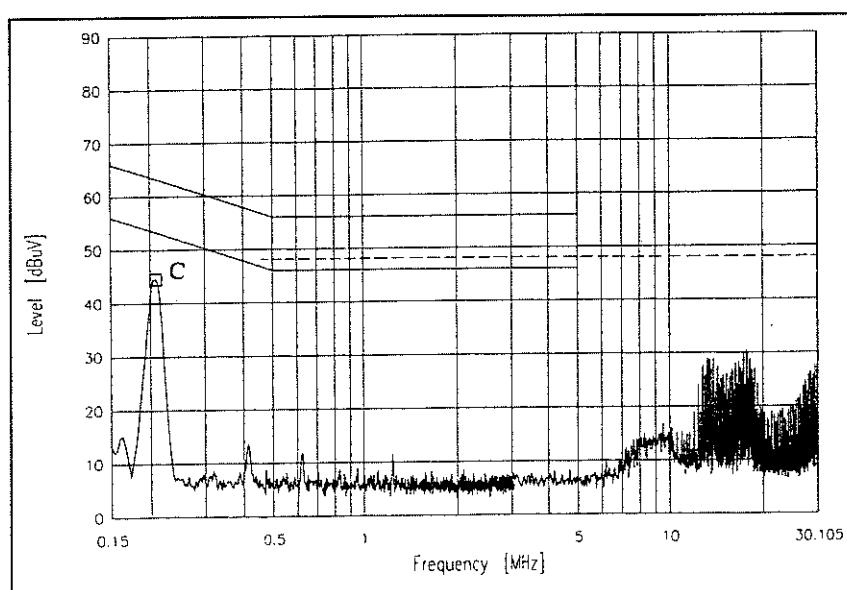
(2) VCCI class B 対応アプリケーションシステム

VCCI class B application system

Conditions  
 Vin : 280 VDC  
 Iout : 100 %  
 Tp : 25 °C

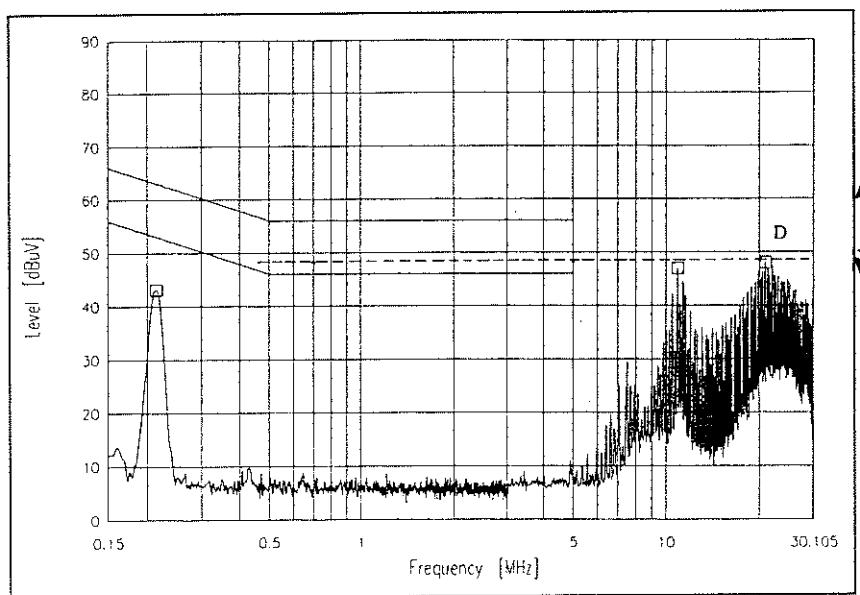
24V

Point C (206kHz)		
Ref.	Data	Limit
	(dBuV)	(dBuV)
QP	63.4	43.9
AV	53.4	43.8



48V

Point D (20.891MHz)		
Ref.	Data	Limit
	(dBuV)	(dBuV)
QP	60.0	46.3
AV	50.0	45.8



## 2.12 EMI特性

Electro-Magnetic Interference characteristics

(b) 雜音電界強度（輻射ノイズ）

Conditions Vin : 280 VDC

Radiated Emission Noise

Iout : 100 %

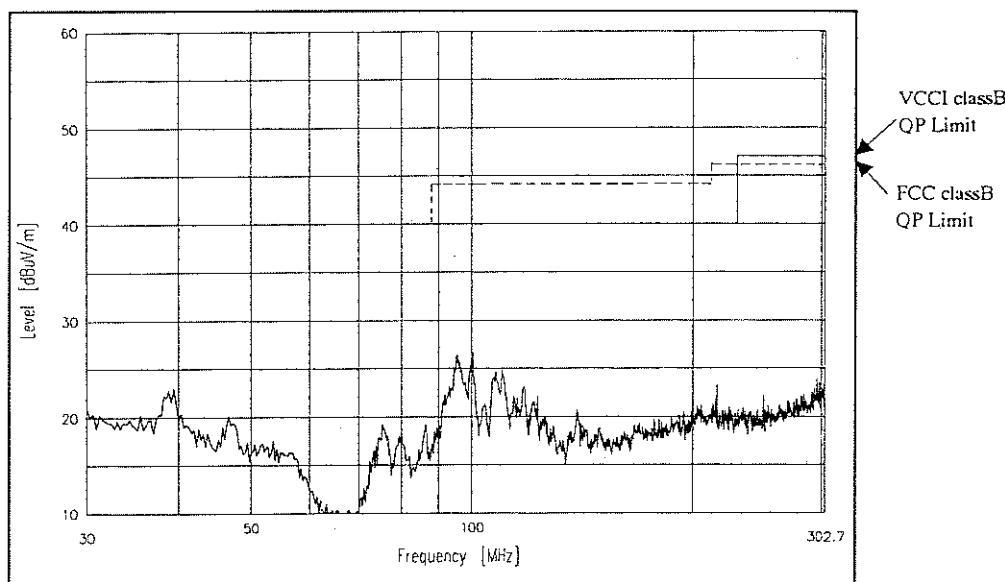
(2) VCCI class B 対応アプリケーションシステム

Tp : 25 °C

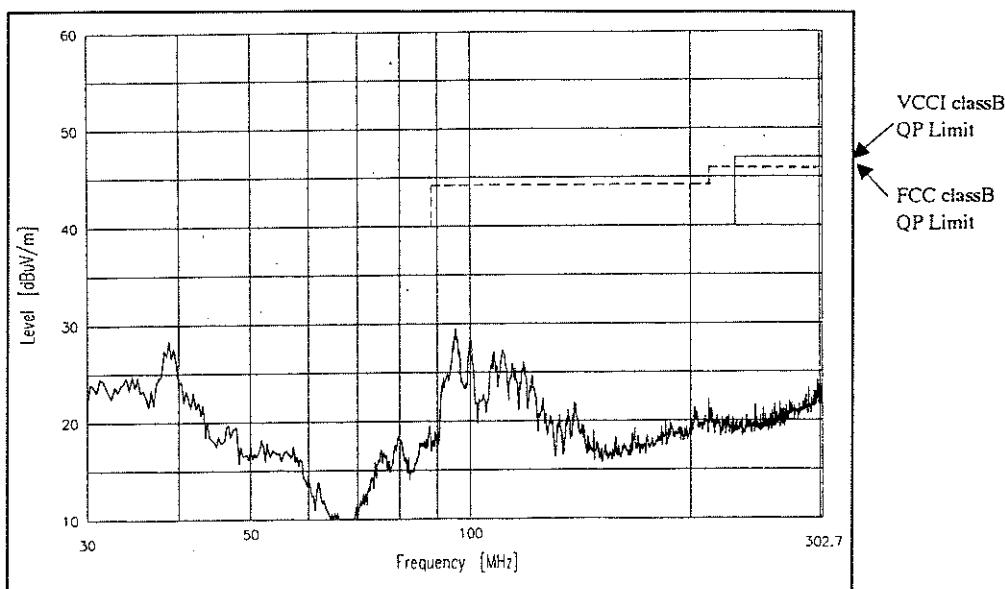
VCCI class B application system

5V

HORIZONTAL:



VERTICAL:



## 2.12 EMI特性

Electro-Magnetic Interference characteristics

(b) 雜音電界強度（輻射ノイズ）

Conditions

Vin : 280 VDC

Radiated Emission Noise

Iout : 100 %

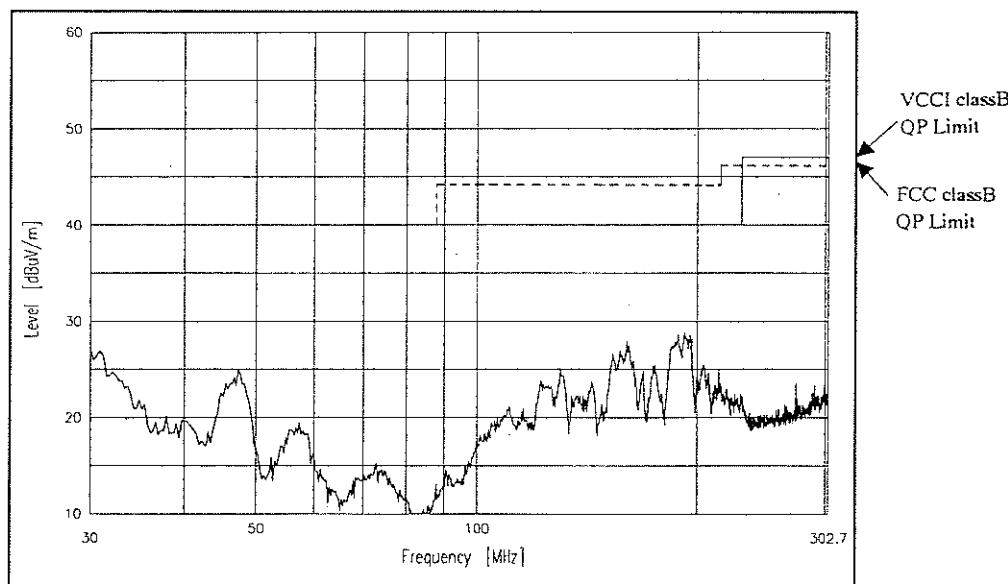
(2) VCCI class B 対応アプリケーションシステム

Tp : 25 °C

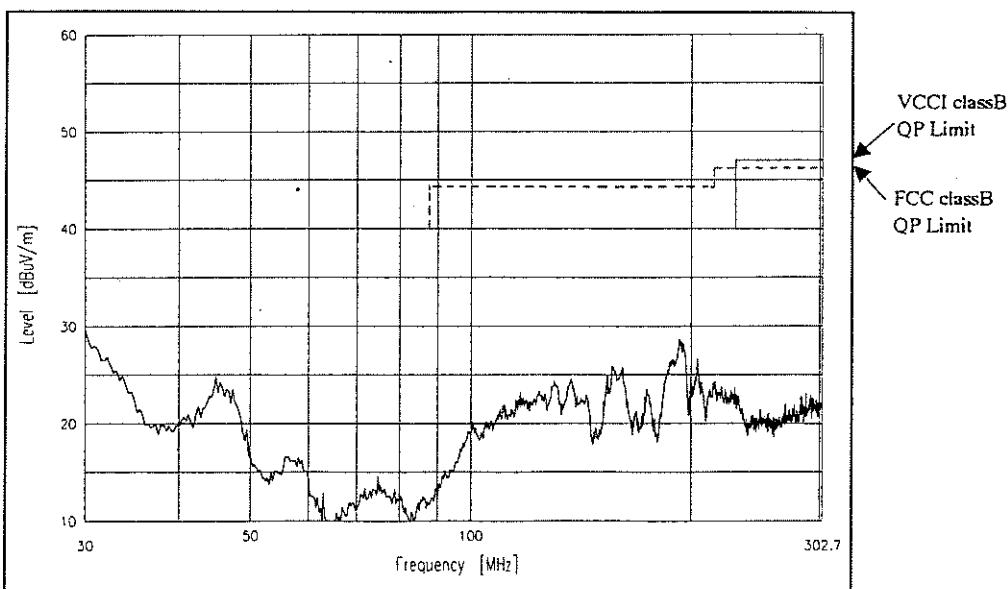
VCCI class B application system

12V

HORIZONTAL:



VERTICAL:



NEMIC-LAMBDA

## 2.12 EMI特性

Electro-Magnetic Interference characteristics

(b) 雜音電界強度（輻射ノイズ）

Conditions Vin : 280 VDC

Radiated Emission Noise

Iout : 100 %

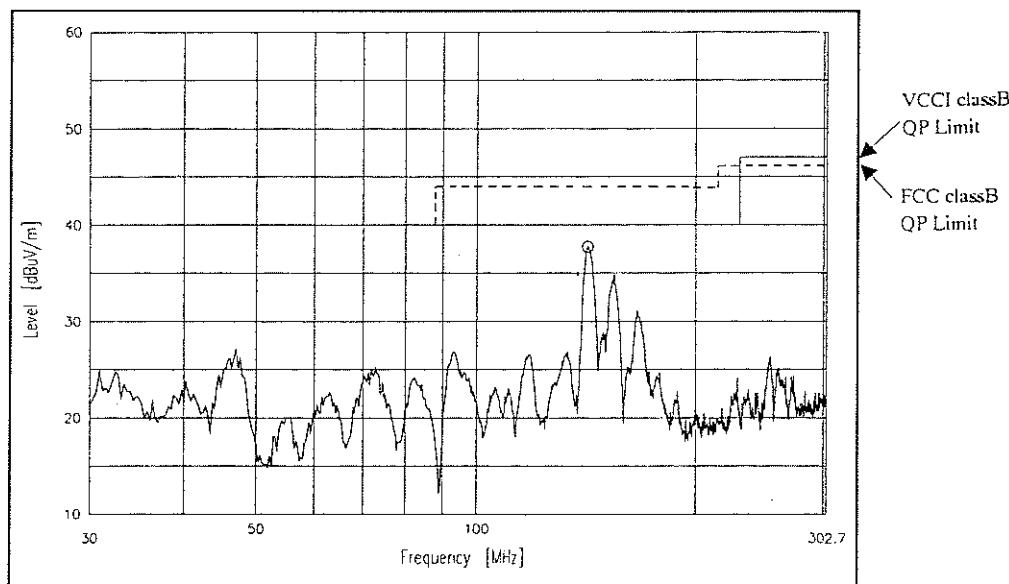
(2) VCCI class B 対応アプリケーションシステム

Tp : 25 °C

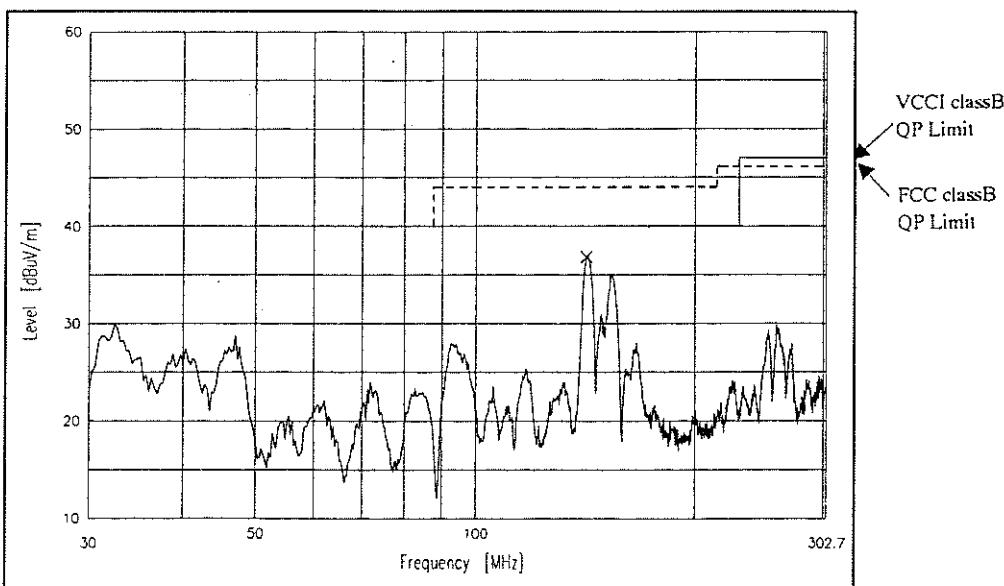
VCCI class B application system

24V

HORIZONTAL:



VERTICAL:



NEMIC-LAMBDA

## 2.12 EMI特性

Electro-Magnetic Interference characteristics

(b) 雜音電界強度（輻射ノイズ）

Radiated Emission Noise

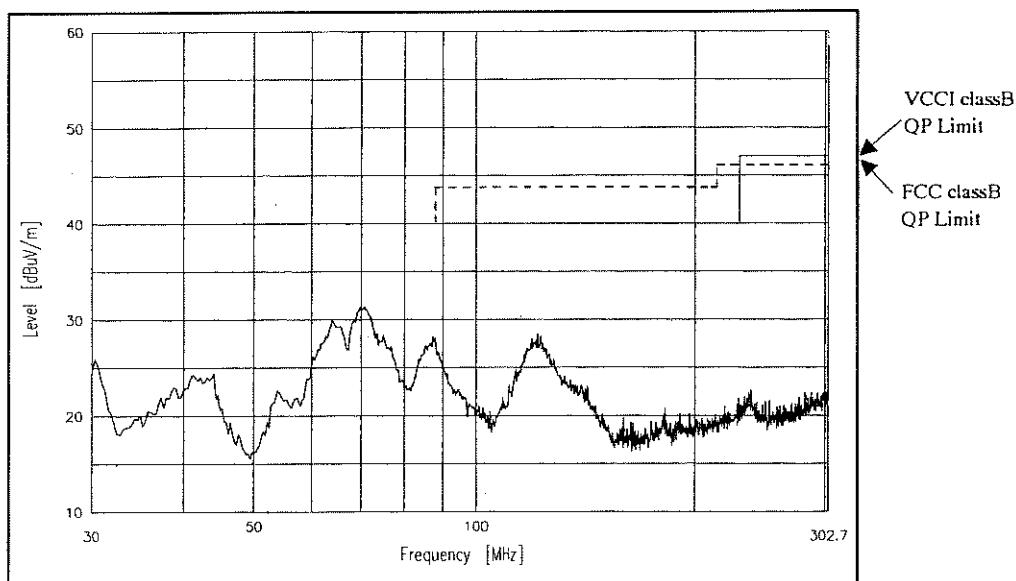
(2) VCCI class B 対応アプリケーションシステム

VCCI class B application system

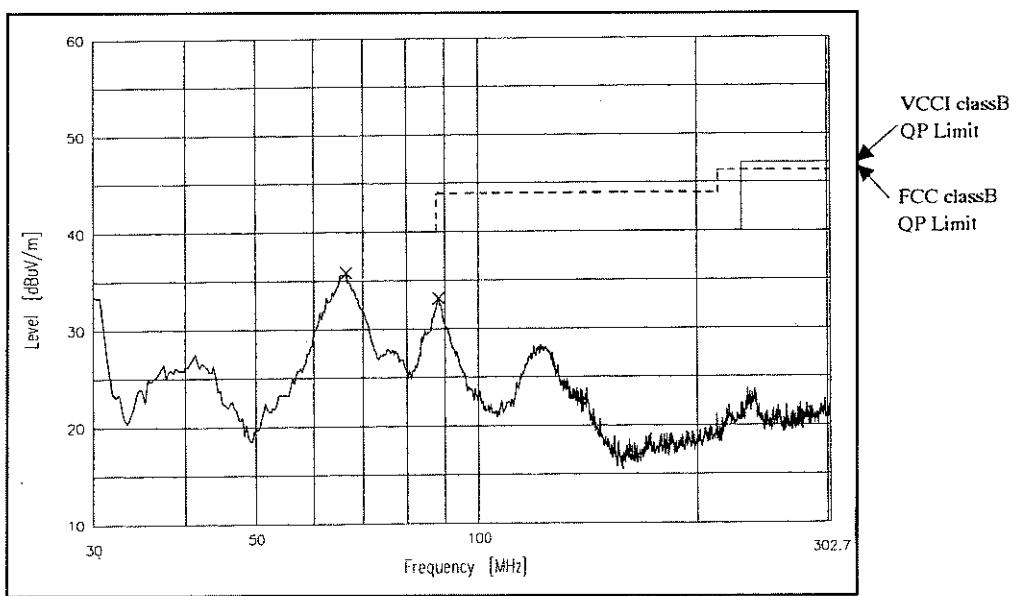
Conditions  
 Vin : 280 VDC  
 Iout : 100 %  
 Tp : 25 °C

48V

HORIZONTAL:



VERTICAL:



NEMIC-LAMBDA